# **AVX Surface Mount Ceramic Capacitor Products**



Version 6.1



# **Ceramic Chip Capacitors**



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Basic Capacitor Formulas



# **How to Order**





#### **Commercial Surface Mount Chips**

## **EXAMPLE: 08055A101JAT2A**

0805	<u>5</u>	<u>A</u>	<u>101</u>	<u>J*</u>	<u>A</u>	<u>T</u>	<u>2</u>	A
Size (L" x W") 0201 0402 0603 0805 1206 1210 1812 1825 2220 2225	Voltage 4 = 4V 6 = 6.3V Z = 10V Y = 16V 3 = 25V D = 35V 5 = 50V 1 = 100V 2 = 200V 7 = 500V	Dielectric A = NPO(COG C = X7R D = X5R F = X8R G = Y5V U = U Series W = X6S Z = X7S	Capacitance  2 Sig. Fig + No. of Zeros Examples: 100 = 10 pF 101 = 100 pF 102 = 1000 pF 223 = 22000 pF 224 = 220000 pF 105 = 1 µF 106 = 10µF 107 = 100µF	Tolerance B = $\pm$ .10 pF C = $\pm$ .25 pF D = $\pm$ .50 pF F = $\pm$ 1% (≥ 10 pF) G = $\pm$ 2% (≥ 10 pF) J = $\pm$ 5% K = $\pm$ 10% M = $\pm$ 20% Z = $\pm$ 80%, $\pm$ 20% P = $\pm$ 100%, $\pm$ 0%	Failure Rate A = N/A 4 = Automotive	Terminations T = Plated Ni and Sn T = Gold Plated U = Conductive Expoxy for Hybrid Applications Z = FLEXITERM <sup>TM</sup> with 5% min lead (X7R &	Packaging Available 2 = 7" Reel 4 = 13" Reel 7 = Bulk Cass. 9 = Bulk  Contact Factory For Multiples	Special Code A = Std.
LLLO	1	Factory for Voltages 9 = 300V X = 350V 8 = 400V	For values below 10 pF, use "R" in place of Decimal point, e.g., 9.1 pF = 9R1.			X8R only)  Contact Factory For 1 = Pd/Ag Term		

<sup>\*</sup> B, C & D tolerance for ≤10 pF values.

Standard Tape and Reel material (Paper/Embossed) depends upon chip size and thickness.

See individual part tables for tape material type for each capacitance value.

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. For Tin/Lead Terminations, please refer to LD Series

## **High Voltage MLC Chips**

## **EXAMPLE: 1808AA271KA11A**

1808	A	<u>A</u>	271	K	<u>A</u>	<u>T</u>	1	<u>A</u>
AVX Style	<b>Voltage</b> C = 600V/630V	Temperature Coefficient	Capacitance Code	Capacitance Tolerance	Failure Rate	Termination 1= Pd/Ag	Packaging/ Marking	Special Code A = Standard
0805 1206 1210 1808 1812	A = 1000V S = 1500V G = 2000V W = 2500V H = 3000V	A = C0G C = X7R	(2 significant digits + no. of zeros) Examples: 10 pF = 100 100 pF = 101	COG: $J = \pm 5\%$ $K = \pm 10\%$ $M = \pm 20\%$ X7R: $K = \pm 10\%$ $M = \pm 20\%$	A=Not Applicable	T = Plated Ni and Sn B = 5% Min Pb Z = FLEXITERM™ X = FLEXITERM™	1 = 7" Reel 3 = 13" Reel 9 = Bulk	A – Standard
1825 2220 2225 3640	J = 4000V K = 5000V	22	0,000  pF = 102 0,000  pF = 223 0,000  pF = 224 0,000  pF = 105	Z = +80%, -20%		with 5% min lead (X7R only)		

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. For Tin/Lead Terminations, please refer to LD Series



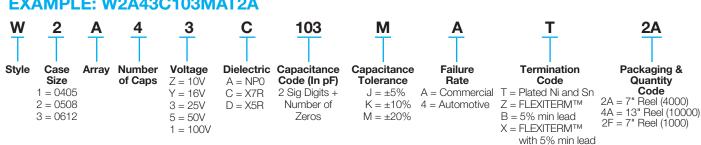
## **How to Order**





#### **Capacitor Array**

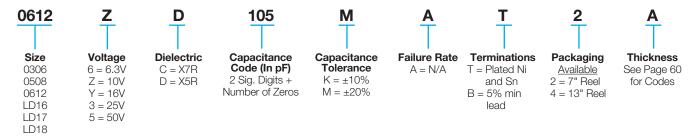
## **EXAMPLE: W2A43C103MAT2A**



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

#### Low Inductance Capacitors (LICC)

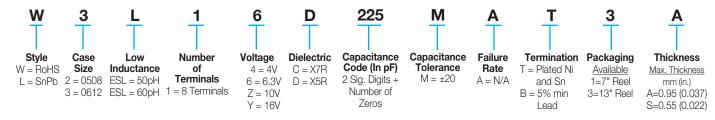
## **EXAMPLE: 0612ZD105MAT2A**



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

#### Interdigitated Capacitors (IDC)

#### **EXAMPLE: W3L16D225MAT3A**



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

#### **Low Inductance Decoupling Capacitor Arrays (LICA)**

#### **EXAMPLE: LICA3T183M3FC4AA**



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

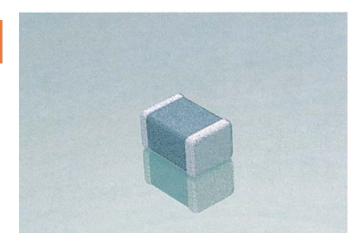


w/ clear lid

# COG (NP0) Dielectric

## **General Specifications**

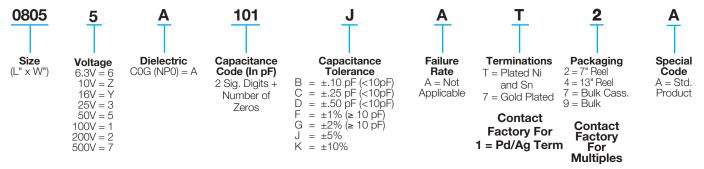




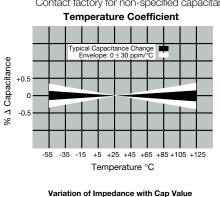
COG (NP0) is the most popular formulation of the "temperature-compensating," EIA Class I ceramic materials. Modern COG (NP0) formulations contain neodymium, samarium and other rare earth oxides.

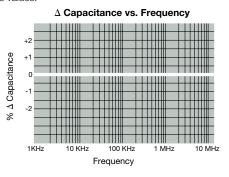
COG (NP0) ceramics offer one of the most stable capacitor dielectrics available. Capacitance change with temperature is 0  $\pm 30 ppm/^{\circ}C$  which is less than  $\pm 0.3\%$   $\Delta$  C from -55°C to +125°C. Capacitance drift or hysteresis for COG (NP0) ceramics is negligible at less than  $\pm 0.05\%$  versus up to  $\pm 2\%$  for films. Typical capacitance change with life is less than  $\pm 0.1\%$  for COG (NP0), one-fifth that shown by most other dielectrics. COG (NP0) formulations show no aging characteristics.

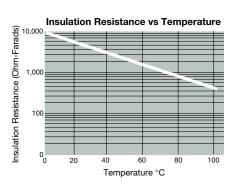
## PART NUMBER (see page 2 for complete part number explanation)



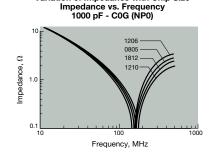
NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.



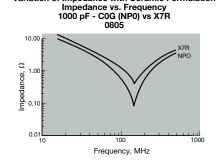




Impedance vs. Frequency 0805 - COG (NPO) 10 pF vs. 100 pF vs. 1000 pF vs. 1000



Variation of Impedance with Chip Size



Variation of Impedance with Ceramic Formulation



# C0G (NP0) Dielectric



# **Specifications and Test Methods**

Parame	ter/Test	NP0 Specification Limits	Measuring	Conditions			
Operating Tem		-55°C to +125°C	Temperature C	Cycle Chamber			
Capac	itance	Within specified tolerance	Freq.: 1.0 MHz ± 10				
	,	<30 pF: Q≥ 400+20 x Cap Value		% for cap > 1000 pF			
	×	≥30 pF: Q≥ 1000	Voltage: 1.0				
Insulation	Registance	100,000M $\Omega$ or 1000M $\Omega$ - μF,	Charge device with				
IIISUIAUOII	i lesistance	whichever is less	60 ± 5 secs @ roc				
Dielectric	Strength	No breakdown or visual defects	Charge device with 300 1-5 seconds, w/charge limited to 50 Note: Charge device voltage for 50	and discharge current O mA (max) with 150% of rated 00V devices.			
	Appearance	No defects	Deflection				
Resistance to	Capacitance Variation	±5% or ±.5 pF, whichever is greater	Test Time: 3	30 seconds 7 1mm/sec			
Flexure Stresses	Q	Meets Initial Values (As Above)					
	Insulation Resistance	≥ Initial Value x 0.3	90 mm ——————————————————————————————————				
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.				
	Appearance	No defects, <25% leaching of either end terminal	_				
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Dip device in eutectic	solder at 260°C for 60			
Resistance to Solder Heat	Q	Meets Initial Values (As Above)	seconds. Store at room temperature for 24 hours before measuring electrical proper				
	Insulation Resistance	Meets Initial Values (As Above)		9			
	Dielectric Strength	Meets Initial Values (As Above)					
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes			
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp ≤ 3 minutes				
Thermal Shock	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2° 30 ± 3 minutes				
o.i.ook	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes			
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles ar 24 hours at room tem				
	Appearance	No visual defects	_				
	Capacitance Variation	≤ ±3.0% or ± .3 pF, whichever is greater	Charge device with t				
Load Life	Q (C=Nominal Cap)	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	test chamber set for 1000 hou	ırs (+48, -0).			
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test cha room temperatu	ire for 24 hours			
	Dielectric Strength	Meets Initial Values (As Above)	before me	easuring.			
	Appearance	No visual defects	_				
	Capacitance Variation	≤ ±5.0% or ± .5 pF, whichever is greater	Store in a test chamb				
Load Humidity	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	85% ± 5% relative hu (+48, -0) with rate	d voltage applied.			
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from cham room temperature	e for $24 \pm 2$ hours			
	Dielectric Strength	Meets Initial Values (As Above)	before me	easuring.			



# C0G (NP0) Dielectric





									a	<b>.</b>										⊐		
SIZI	E		0201			0402			06	603				0805					12	206		
Solder		Re	eflow Or	nlv	R	leflow O			Reflow Only				Re	flow/Wa	ve					v/Wave		
Packaç		,	All Pape	r		All Pape	er		All F	aper			Pap	er/Embo	ssed			P	aper/E	mbosse		
(L) Length	MM (in.)		0.60 ± 0.0 024 ± 0.0			1.00 ± 0.1 .040 ± 0.0				± 0.15 ± 0.006)				2.01 ± 0.20 079 ± 0.00								
(W) Width	MM (in.)		0.30 ± 0.0		- (	0.50 ± 0.1	10		0.81	± 0.15 ± 0.006)				1.25 ± 0.20 049 ± 0.00	)				1.60 :	± 0.20 ± 0.008)		
(t) Terminal	MM	C	0.15 ± 0.0	15	ì	0.25 ± 0.1	15		0.35	± 0.15			, (	0.50 ± 0.25	5				0.50	± 0.25		
(i) FORTIFICAL	(in.) WVDC	10	006 ± 0.0	25	16	.010 ± 0.0	50	6.3	(0.014	± 0.006) 50	100	16	25	$\frac{020 \pm 0.0^{\circ}}{50}$	10)	200	16	25	(0.020 :	± 0.010) 100	200	500
Cap	0.5	10	10	А	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
(pF)	1.0 1.2			A A	C	C	C	G G	G G	G G	G G	J J	J	J	J J	J J	J	J	J	J J	J J	J
	1.5	Α	Α	А	С	С	C	G	G	G	G	J	J	J	J	J	Ĵ	J	J	J	J	J
	1.8 2.2	A A	A A	A A	C	C	C	G G	G G	G G	G G	J J	J	J	J	J J	J	J	J	J	J J	J
	2.7	Α	Α	A	C	C	C	G	G	G	G	J	J	J	J	J	Ĵ	J	J	Ĵ	J	J
	3.3 3.9	A A	A A	A A	CC	C	C	G G	G G	G G	G G	J J	J	J	J J	J J	J J	J	J	J J	J J	J J
	4.7	A	A	A	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	5.6 6.8	A A	A A	A A	C	C	C	G G	G G	G G	G G	J J	J	J	J J	J	J J	J	J	J	J J	J
	8.2 10	A A	A A	A	C	C	C	G G	G G	G G	G	J J	J	J	J	J	J J	J	J	J	J	J
	12	Α	Α	Α	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	15 18	A A	A A	A	C	C	C	G G	G G	G G	G G	J J	J	J	J	J	J	J	J	J	J	J
	22	Α	Α	Α	С	С	С	G	G	G	G	J	J	J	J	J	Ĵ	J	J	J	J	J
	27 33	A	A	A	C	C	C	G G	G G	G G	G	J	J	J	J	J	J	J	J	J	J	J
	39	Α	Α	Α	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
-	47 56	A	A	A	C	C	C	G G	G G	G G	G	J	J	J	J	J	J	J	J	J	J	J
	68	A	A	A	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	82 100	A	A	A	C	C	C	G G	G G	G G	G	J	J	J	J	J	J	J	J	J	J	J
	120 150				C	C	C	G G	G G	G G	G G	J J	J	J	J J	J J	J J	J	J J	J J	J J	J
	180				С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	220 270				С	С	С	G G	G	G G	G G	J J	J	J	J	J M	J J	J	J	J	J J	M M
	330							G	G	G	G	J	J	J	J	М	J	J	J	J	J	М
	390 470							G G	G G	G G		J J	J	J	J	M M	J	J	J	J	J J	M M
	560 680							G G	G G	G G		J J	J J	J	J J	М	J	J	J	J J	J	M P
	820							G	G	G		J	J	J	J		J	J	J	J	J M	Г
	1000 1200							G	G	G		J J	J	J	J		J	J	J	J J	QQ	
	1500											Ĵ	J	J			Ĵ	J	J	М	Q	
	1800 2200											J J	J	J M			J J	J	M M	M P		
	2700											J	J	М			J	J	M	P P		
	3300 3900			I	I	l	I										J	J	M M	Р		
	4700 5600			<del>حر</del> ا.	<u> </u>		•	<u> </u>					-				J	J	M	Р		
	6800				_	$\int \int_{\mathbb{R}}$	ÎT										М	М				
Cap	8200 0.010					السل	<u> </u>	<u> </u>					-				M M	M				
(µF)	0.012			_	مر ا																	
	0.015 0.018				τı																	
	0.022 0.027																					
	0.033																					
	0.039 0.047																					
	0.068																					
	0.082 0.1	L			L					L			L	L			L	L				
	WVDC	10	16	25	16	25	50	6.3	25	50	100	16	25	50	100	200	16	25	50	100	200	500
	SIZE		0201	_		0402			06			<u> </u>		0805	.,		<u> </u>	_		.06		
Letter Max.	<b>A</b> 0.33	0.5		<b>E</b> 0.71	<b>G</b>		<b>J</b>	1.02		<b>M</b> .27	<b>N</b>	1.5		<b>Q</b> 1.78	<b>X</b> 2.29		<b>Y</b>	<b>Z</b>				
Thickness	(0.013)	(0.0)	)22)	(0.028)	(0.03		0.037)	(0.040		050)	(0.055)	(0.0)	60) (	0.070)	(0.090		.100)	(0.11				
			F	PAPER								El	MBOSS	SED								



# C0G (NP0) Dielectric



# **Capacitance Range**

SIZ	Έ			1210					1812				1825			2220			2225	
Solde	ring			Reflow Or					eflow On				Reflow On			Reflow Or			eflow On	
Packa	ging MM			er/Embo 3.20 ± 0.2					Emboss 4.50 ± 0.3				I Emboss 4.50 ± 0.30			Emboss   5.70 ± 0.4			Emboss 5.72 ± 0.25	
(L) Length	(in.) MM			$0.126 \pm 0.0$ $2.50 \pm 0.2$					$3.20 \pm 0.0$				.177 ± 0.01 6.40 ± 0.40			.225 ± 0.0 5.00 ± 0.4			225 ± 0.0° 6.35 ± 0.25	
(W) Width	(in.) MM		(0	$0.098 \pm 0.0$ $0.50 \pm 0.2$	08)			(0	.126 ± 0.00	08)		(0.	.252 ± 0.01 0.61 ± 0.36	6)	(0	.197 ± 0.0 0.64 ± 0.3	16)	(0	250 ± 0.0°	10)
(t) Terminal	(in.)	0.5	(0	$0.020 \pm 0.0$	10)	500	0.5	(0	$.024 \pm 0.0$	14)	T 500	(0.	.024 ± 0.01	4)	(0	.025 ± 0.0	15)	(0	025 ± 0.0	15)
Cap	WVDC 0.5	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200	50	100	200
(pF)	1.0 1.2																			
	1.5 1.8															_				
	2.2																	<b>~</b> _	W	
	2.7 3.3															+ -	< <u>_</u>	<	يك	₹ T
	3.9 4.7																	J )_	سلر	1
	5.6																7	المبيدا		
	6.8 8.2																	[ [ ]		
	10 12					J														
	15 18					J														
	22					J														
	27 33					J														
	39 47					J														
	56 68					J														
	82					J														
	100 120					J														
	150 180					J														
	220 270					J														
	330					J														
	390 470					M M														
	560 680	J J	J	J	J	M M														
	820 1000	J J	J	J	J	M M	K	K	K	K	M	M	М	М				M	М	Р
	1200	J	J	J	М	141	K	K	K	K	M	М	М	М				М	М	Р
	1500 1800	J	J	J	M M		K K	K	K	K	M	M M	M M	M M				M M	M M	P P
	2200 2700	J J	J	J	Q		K K	K K	K K	K P	P Q	M M	M M	M M				M M	M M	P P
	3300 3900	J	J	J M			K K	K K	K K	P P	Q Q	M M	M M	M M			X X	M M	M M	P P
	4700	J	J	M			K	K	K	Р	Q	М	М	М	X	X	Х	М	М	P
	5600 6800						K K	K K	M M	P X	Х	M M	M M	M M	X	X	X	M M	M M	P P
Cap	8200 0.010						K K	M	M M			M M	M M		X	X	X	M M	M M	P P
(µF)	0.012 0.015						K M	M M				M M	M M		X X	X	X X	M M	M M	P Y
-	0.018						М	М				P P	M		Х	Х	X	М	М	Υ
	0.022 0.027						М	М				7			X	X		M P	Y Y	Y
	0.033 0.039														Х	X				
	0.047																			
	0.068 0.082																			
	0.1 WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200	50	100	200
	SIZE			1210					1812				1825			2200			2225	
Letter Max.	<b>A</b> 0.33	0.5		<b>E</b> 0.71	<b>G</b> 0.86	0.9		<b>K</b>	<b>M</b> 1.27	1.4		<b>P</b> 1.52	<b>Q</b> 1.78	2.:		<b>Y</b> 2.54	<b>Z</b> 2.79			
Thickness	(0.013)	(0.0)	22) (	0.028)	(0.034)			(0.040)	(0.050)			(0.060)	(0.070)			(0.100)	(0.110)	)		
		PAPER EMBOSSED																		

# RF/Microwave C0G (NP0) Capacitors

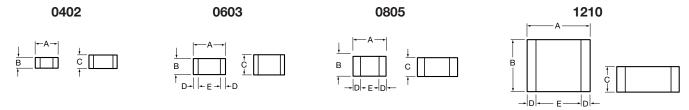


## Ultra Low ESR, "U" Series, C0G (NP0) Chip Capacitors

#### **GENERAL INFORMATION**

"U" Series capacitors are COG (NPO) chip capacitors specially designed for "Ultra" low ESR for applications in the communications market. Max ESR and effective capacitance are met on each value producing lot to lot uniformity. Sizes available are EIA chip sizes 0603, 0805, and 1210.

## **DIMENSIONS:** inches (millimeters)



inches (mm) Size B C D Ε 0402  $0.039\pm0.004$  (1.00±0.1) 0.020±0.004 (0.50±0.1) 0.024 (0.6) max N/A N/A 0603 0.060±0.010 (1.52±0.25) 0.030±0.010 (0.76±0.25) 0.036 (0.91) max 0.010±0.005 (0.25±0.13) 0.030 (0.76) min 0805 0.079±0.008 (2.01±0.2) 0.049±0.008 (1.25±0.2) 0.040±0.005 (1.02±0.127) 0.020±0.010 (0.51±0.255) 0.020 (0.51) min 1210 0.126±0.008 (3.2±0.2) 0.098±0.008 (2.49±0.2) 0.050±0.005 (1.27±0.127) 0.025±0.015 (0.635±0.381) 0.040 (1.02) min

#### **HOW TO ORDER** 0805 U 100 Т 2 Case Size Dielectric = Capacitance **Termination Special** Ultra Low Tolerance Code 0402 T= Plated Ni Code A = Standard 0603 and Sn 0805 $B = \pm 0.1pF$ 1210 $C = \pm 0.25 pF$ $D = \pm 0.5pF$ $F = \pm 1\%$ $G = \pm 2\%$

 $J = \pm 5\%$ 

 $K = \pm 10\%$ 

 $M = \pm 20\%$ 

Voltage Code 3 = 25V5 = 50V1 = 100V2 = 200V

Capacitance EIA Capacitance Code in pF. First two digits = significant figures

or "R" for decimal place.

Third digit = number of zeros or after "R" significant figures.

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

**Packaging** 

Code

2 = 7" Reel

4 = 13" Reel

9 = Bulk

#### **ELECTRICAL CHARACTERISTICS**

#### Capacitance Values and Tolerances:

Size 0402 - 0.2 pF to 22 pF @ 1 MHz Size 0603 - 1.0 pF to 100 pF @ 1 MHz Size 0805 - 1.6 pF to 160 pF @ 1 MHz Size 1210 - 2.4 pF to 1000 pF @ 1 MHz

## Temperature Coefficient of Capacitance (TC):

0±30 ppm/°C (-55° to +125°C)

#### Insulation Resistance (IR):

 $10^{12} \Omega$  min. @  $25^{\circ}$ C and rated WVDC  $10^{11} \Omega$  min. @  $125^{\circ}$ C and rated WVDC

#### Working Voltage (WVDC):

Working Voltage Size 0402 50, 25 WVDC 0603 -200, 100, 50 WVDC 0805 -200, 100 WVDC 200, 100 WVDC 1210 -

## **Dielectric Working Voltage (DWV):**

250% of rated WVDC

**Failure Rate** 

Code

A = Not

Applicable

#### **Equivalent Series Resistance Typical (ESR):**

See Performance Curve, page 9 0402 -0603 See Performance Curve, page 9 0805 See Performance Curve, page 9 1210 See Performance Curve, page 9

Marking: Laser marking EIA J marking standard (except 0603) (capacitance code and tolerance upon request).

#### **MILITARY SPECIFICATIONS**

Meets or exceeds the requirements of MIL-C-55681



# RF/Microwave C0G (NP0) Capacitors



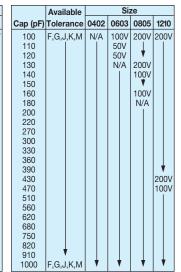
Ultra Low ESR, "U" Series, C0G (NP0) Chip Capacitors

## **CAPACITANCE RANGE**

	Available				
Cap (pF)	Tolerance	0402	0603	0805	1210
0.2	B,C	50V	N/A	N/A	N/A
0.3	Ì				
0.4	\ \				
0.5	B,C				
0.6	B,C,D				
0.7					
0.8	*				
0.9	B,C,D	•	- ▼	- ▼	<b>V</b>

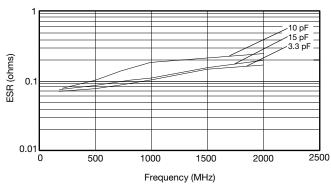
	Available		Size								
Cap (pF)	Tolerance	0402	0603	0805	1210						
1.0	B,C,D	50V	200V	200V	200V						
1.1											
1.2 1.3											
1.4											
1.5											
1.6											
1.7 1.8											
1.9											
2.0											
2.1											
2.2 2.4											
2.7											
3.0											
3.3											
3.6 3.9											
4.3											
4.7											
5.1											
5.6 6.2	B C D										
6.8	B,C,D B,C,J,K,M	<b>V</b>	•	•	₩						
2.0	_, _, _, , , , , , , , , , , , , , , ,										

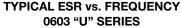
	Available				Siz	ze			
Cap (pF)	Tolerance		02	06	03	08	05	12	10
7.5	B,C,J,K,N	$\overline{}$	0V 200		0V	200V		20	0V
8.2	▼								
9.1	B,C,J,K,N								
10	F,G,J,K,N								
11									
12									
13									
15				1	7				
18					0V				
20				10	0V				
22									
24		Ι,							
27			•						
30			V						
33		l N	/A						
36									
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56									
68									
75									
82									

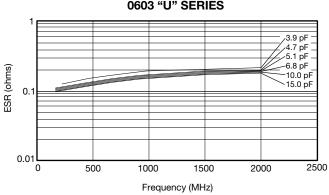


## **ULTRA LOW ESR, "U" SERIES**

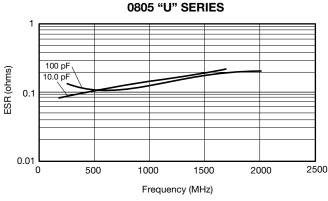
**TYPICAL ESR vs. FREQUENCY** 0402 "U" SERIES



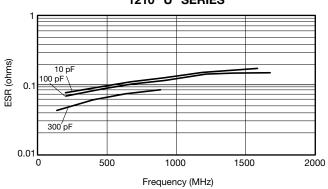




TYPICAL ESR vs. FREQUENCY



TYPICAL ESR vs. FREQUENCY 1210 "U" SERIES



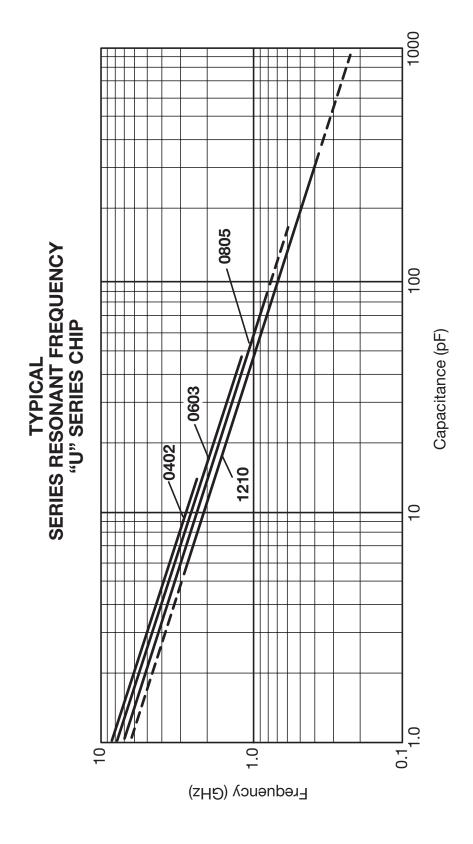
ESR Measured on the Boonton 34A



# RF/Microwave C0G (NP0) Capacitors



Ultra Low ESR, "U" Series, C0G (NP0) Chip Capacitors



# **Designer Kits**





## **"U" SERIES KITS**

Solder Plated, Nickel Barrier

## 0402

Kit 5000 UZ*											
Cap. Value pF	Tol.†	Cap. Value pF	Tol.†								
0.5	В	4.7	В								
1.0	В	5.6	В								
1.5	В	6.8	В								
1.8	В	8.2	В								
2.2	В	10.0	J								
2.4	В	12.0	J								
3.0	В	15.0	J								
3.6	В										

<sup>\* 150</sup> Capacitors 10 each of 15 values.

## 0603

	Kit 400	0 UZ**			
Cap. Value pF	Tol.†	Tol.† Cap. Value pF			
1.0	±.25pF	6.8	±.25pF		
1.2	±.25pF	7.5	±.25pF		
1.5	±.25pF	8.2	±.25pF		
1.8	±.25pF	10.0	±5%		
2.0	±.25pF	12.0	±5%		
2.4	±.25pF	15.0	±5%		
2.7	±.25pF	18.0	±5%		
3.0	±.25pF	22.0	±5%		
3.3	±.25pF	27.0	±5%		
3.9	±.25pF	33.0	±5%		
4.7	±.25pF	39.0	±5%		
5.6	±.25pF	47.0	±5%		

<sup>\*\* 240</sup> Capacitors 10 each of 24 values.

## 0805

Kit 3000 UZ***											
Cap. Value pF	Tol.†	Cap. Value pF	Tol.†	Cap. Value pF	Tol.†						
1.0 1.5 2.2 2.4 2.7 3.0 3.3 3.9 4.7 5.6	0000000000	7.5 8.2 9.1 10.0 12.0 15.0 18.0 22.0 24.0	C C C J J J C C C C C C C C C C C C C C	33 36 39 47 56 68 82 100 130	7 7 7 7 7 7 7						

## 1210

	ı	Kit 3500	UZ**	٠	
Cap. Value pF	Tol.†	Cap. Value pF	Tol.†	Cap. Value pF	Tol.†
2.2	С	18	J	68	J
2.7	С	20	J	82	J
4.7	С	24	J	100	J
5.1	С	27	J	120	J
6.8	С	30	J	130	J
8.2	С	36	J	240	J
9.1	С	39	J	300	J
10	J	47	J	390	J
13	J	51	J	470	J
15	J	56	J	680	J

<sup>\*\*\* 300</sup> Capacitors 10 each of 30 values.

†Tolerance – B =  $\pm 0.1$ pF C =  $\pm 0.25$ pF J =  $\pm 5\%$ 









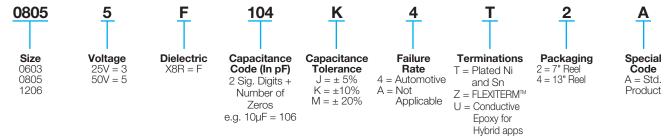
AVX have developed a range of multilayer ceramic capacitors designed for use in applications up to  $150^{\circ}$ C. These capacitors are manufactured with an X8R dielectric material which has a capacitance variation of  $\pm 15\%$  between -55°C and  $\pm 150^{\circ}$ C.

The need for X8R performance has been driven by customer requirements for parts that operate at elevated temperatures. They provide a highly reliable capacitor with low loss and stable capacitance over temperature.

They are ideal for automotive under the hood sensors, measure while drilling and log while drilling. Typical applications include wire line logging tools such as gamma ray receivers, acoustic transceivers and micro-resistivity tools. They can also be used as bulk capacitors for high temperature camera modules.

X8R capacitors are available as standard and Automotive AEC-Q200 qualified parts. Optional termination systems, tin, FLEXITERM™ and conductive epoxy for hybrid applications are available. Providing this series with our FLEXITERM™ termination system provides further advantage to customers by way of enhanced resistance to both, temperature cycling and mechanical damage.

## PART NUMBER (see page 2 for complete part number explanation)



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers

	SIZE	0	603		805		1206
	WVDC	25V	50V	25V	50V	25V	50V
271	Cap 270	G	G				
331	(pF) 330	G	G	J	J		+
471	470	G	G	J	J		
681	680	G	G	J	J		_
102	1000	G	G	J	J	J	J
152	1500	G	G	J	J	J	J
182	1800	G	G	J	J	J	J
222	2200	G	G	J	J	J	J
272	2700	G	G	J	J	J	J
332	3300	G	G	J	J	J	J
392	3900	G	G	J	J	J	J
472	4700	G	G	J	J	J	J
562	5600	G	G	J	J	J	J
682	6800	G	G	J	J	J	J
822	8200	G	G	J	J	J	J
103	Cap 0.01	G	G	J	J	J	J
123	(μF) 0.012	G	G	J	J	J	J
153	0.015	G	G	J	J	J	J
183	0.018	G	G	J	J	J	J
223	0.022	G	G	J	J	J	J
273	0.027	G	G	J	J	J	J
333	0.033	G	G	J	J	J	J
393	0.039	G	G	J	J	J	J
473	0.047	G	G	J	J	J	J
563	0.056	G		N	N	М	M
683	0.068	G		N	N	M	M
823	0.082	G		N	N	M	M
104	0.1	G		N	N	M	M
124	0.12	G		N	N	М	M
154	0.15			N	N	М	M
184	0.18			N		M	M
224	0.22			N		M	M
274	0.27			N		M	M
334	0.33			N		M	M
394	0.39			N		М	
474	0.47			N		M	
684	0.68					M	
824	0.82						
105	1						
	WVDC	25V	50V	25V	50V	25V	50V
	SIZE	0	603		0805	1	206
_etter	A C E	G		M N	P	Q X	Υ
Max.	0.33 0.56 0.71	0.86 0.	94 1.02	1.27 1.40	1.52	.78 2.29	2.54

Letter	Α	С	E	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.86	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.034)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBC	SSED			

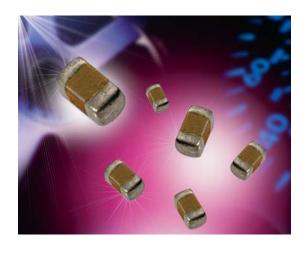
## **General Specifications**



#### **APPLICATIONS FOR X8R CAPACITORS**

- All market sectors with a 150°C requirement
- Automotive on engine applications
- Oil exploration applications
- Hybrid automotive applications
  - Battery control
  - Inverter / converter circuits
  - Motor control applications
  - Water pump
- Hybrid commercial applications
  - Emergency circuits
  - Sensors
  - Temperature regulation



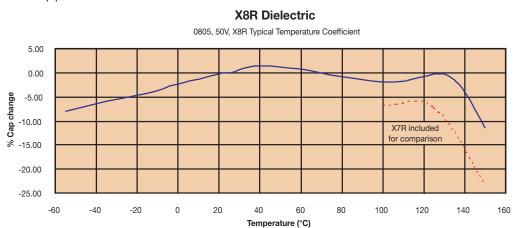


#### **ADVANTAGES OF X8R MLC CAPACITORS**

- Capacitance variation of ±15% between –55°C and +150°C
- Qualified to the highest automotive AEC-Q200 standards
- Excellent reliability compared to other capacitor technologies
- RoHS compliant
- Low ESR / ESL compared to other technologies
- Tin solder finish
- FLEXITERM™ available
- Hybrid available
- 50V range available

## **ENGINEERING TOOLS FOR HIGH VOLTAGE MLC CAPACITORS**

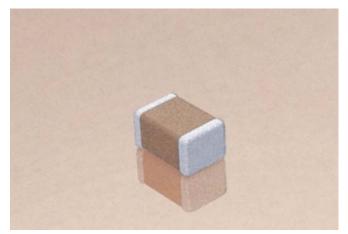
- Samples
- Technical Articles
- Application Engineering
- Application Support











X7R formulations are called "temperature stable" ceramics and fall into EIA Class II materials. X7R is the most popular of these intermediate dielectric constant materials. Its temperature variation of capacitance is within  $\pm 15\%$  from  $-55^{\circ}$ C to  $+125^{\circ}$ C. This capacitance change is non-linear.

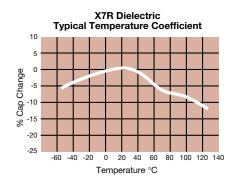
Capacitance for X7R varies under the influence of electrical operating conditions such as voltage and frequency.

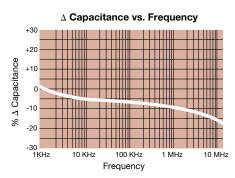
X7R dielectric chip usage covers the broad spectrum of industrial applications where known changes in capacitance due to applied voltages are acceptable.

## PART NUMBER (see page 2 for complete part number explanation)

0805	<u>5</u>	<u>C</u>	103	<u>M</u>	<u>A</u>	<u>T</u>	<u>2</u>	<u> </u>
	<b>Voltage</b> 4V = 4 6.3V = 6 10V = Z 16V = Y 25V = 3	<b>Dielectric</b> X7R = C	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros	Capacitance Tolerance $J = \pm 5\%$ $K = \pm 10\%$ $M = \pm 20\%$	Failure Rate A = Not Applicable	Terminations T = Plated Ni and Sn 7 = Gold Plated* Z = FLEXITERM <sup>TM**</sup>	<b>Packaging</b> 2 = 7" Reel 4 = 13" Reel 7 = Bulk Cass. 9 = Bulk	Special Code A = Std. Product
	50V = 5 100V = 1 200V = 2 500V = 7					*Optional termination  **See FLEXITERM <sup>TM</sup> X7R section	Contact Factory For Multiples	

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.





Insulation Resistance vs Temperature

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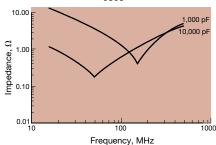
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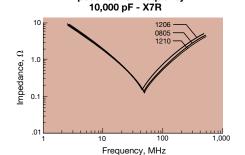
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Variation of Impedance with Cap Value Impedance vs. Frequency 1,000 pF vs. 10,000 pF - X7R 0805



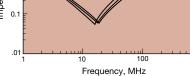


Variation of Impedance with Chip Size

Impedance vs. Frequency

Impedance vs. Frequency 100,000 pF - X7R

Variation of Impedance with Chip Size







# **Specifications and Test Methods**

Parame	ter/Test	X7R Specification Limits	Measuring	Conditions
Operating Tem		-55°C to +125°C	Temperature C	
Capac	itance	Within specified tolerance		-
		≤ 2.5% for ≥ 50V DC rating	Freq.: 1.0 k	
Discipation	on Factor	≤ 3.0% for 25V DC rating	Voltage: 1.0	
Dissipation	on Factor	≤ 3.5% for 16V DC rating	For Cap > 10 μF, (	0.5Vrms @ 120Hz
		≤ 5.0% for ≤ 10V DC rating		
		100,000MΩ or 1000MΩ - μF,	Charge device with	n rated voltage for
Insulation I	Resistance	whichever is less	120 ± 5 secs @ ro	
Dielectric	Strength	No breakdown or visual defects	Charge device with 300 1-5 seconds, w/charge limited to 50 Note: Charge device voltage for 50	0% of rated voltage for and discharge current 0 mA (max) with 150% of rated
	Appearance	No defects	Deflectio	
	Capacitance		Test Time: 3	
Resistance to	Variation	≤ ±12%	7	7 1mm/sec
Flexure	Dissipation		†	111111/360
Stresses	Factor	Meets Initial Values (As Above)		
C.1. 00000	Insulation			
	Resistance	≥ Initial Value x 0.3	90 r	mm —
		≥ 95% of each terminal should be covered	Dip device in eutectic	
Solder	rability	with fresh solder	for $5.0 \pm 0$ .	
	Appearance	No defects, <25% leaching of either end terminal	101 0.0 ± 0.	C 55001100
	Capacitance		-	
	Variation	≤ ±7.5%		
	Dissipation		Dip device in eutectic :	
Resistance to	Factor	Meets Initial Values (As Above)	seconds. Store at room	
Solder Heat	Insulation		hours before measurin	g electrical properties.
	Resistance	Meets Initial Values (As Above)		
	Dielectric			
	Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes
	Capacitance		·	
	Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes
Th	Dissipation		0. 0. 10500 00	00 0 1 1
Thermal	Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes
Shock	Insulation		0. 1.5	0
	Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric	M+-1-11-1-1-1-/ /A Al )	Repeat for 5 cycles ar	nd measure after
	Strength	Meets Initial Values (As Above)	24 ± 2 hours at room	
	Appearance	No visual defects		
	Capacitance	≤ ±12.5%	Charge device with 1.5	rated voltage (≤ 10V) in
	Variation	S ±12.070	test chamber set	at 125°C ± 2°C
	Dissipation	Initial Value v 0.0 (0 Al)	for 1000 hou	urs (+48, -0)
Load Life	Factor	≤ Initial Value x 2.0 (See Above)		
	Insulation	- Initial Value v 0.0 (Cas Alseva)	Remove from test ch	
	Resistance	≥ Initial Value x 0.3 (See Above)	at room temperatur	
	Dielectric	Mosto Initial Values (As Abova)	before me	easuring.
	Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects	Store in a test chamb	or not at 9590 · 990/
	Capacitance	≤ ±12.5%		
	Variation	≥ ±12.0/0	$85\% \pm 5\%$ relative hu	
Load	Dissipation	Initial Value v 0.0 (0 Al)	(+48, -0) with rated	u voitage applied.
Humidity	Factor	≤ Initial Value x 2.0 (See Above)	Domove from objects	bor and atabilize at
•	Insulation	lettel Melice or 0.0 (O. Al. )	Remove from cham	
	Resistance	≥ Initial Value x 0.3 (See Above)	room temperature	
	Dielectric	NA	24 ± 2 hours be	iore measuring.
	Strength	Meets Initial Values (As Above)		
	2			







										ш														[				
SIZI	E	02	201		0402	2				0603	}						080	5						12	206			
Solder	ina	Reflo	w Only	Re	eflow (	Only			Re	flow C	)nlv					Ref	flow/V	Vave						Reflo	ν/Wa\	/e		
Packag			Paper		All Pap					All Pap								ossec	1				P	aper/E				
(L) Length	MM (in.)	0.60	± 0.03 ± 0.001)		1.00 ± 0	0.10			1	$.60 \pm 0.063 \pm 0.000$	15					2	$.01 \pm 0$ $.079 \pm 0$	.20	<u>-                                      </u>					3.20	± 0.20 ± 0.00			
0.0.0.10.0.141-	MM		± 0.03		$0.50 \pm 0$					.81 ± 0.							$.25 \pm 0$								± 0.20			
(W) Width	(in.)		$\pm 0.001)$		.020 ± 0					$032 \pm 0.$							$0.49 \pm 0$								± 0.008			
(t) Terminal	MM		± 0.05		$0.25 \pm 0$					$.35 \pm 0.$							$.50 \pm 0$								± 0.25			
	(in.)		± 0.002)		.010 ± 0		0.0	10		$0.014 \pm 0.01$		1 400	1 000	0.0	40		$0.20 \pm 0$		1400	000	0.0	10	40		± 0.01		000	500
Cap	WVDC 100	10 A	16 A	16	25	50	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	500
(pF)	150	A	A																								i 1	
(pr)	220	A	A			С																						
	330	A	A			C					G	G	G		J	J	J	J	J	J								K
	470	Α	Α			С					G	G	G	l	J	J	J	J	J	J								K
	680	Α	Α			С					G	G	G		J	J	J	J	J	J								K
	1000	Α	А			С					G	G	G		J	J	J	J	J	J								K
	1500	Α				С					G	G			J	J	J	J	J	J		J	J	J	J	J	J	M
	2200	A				С	_				G	G		_	J	J	J	J	J	J	_	J	J	J	J	J	J	M
	3300 4700	A			C	С					G G	G G			J	J	J	J	J	J		J	J	J	J	J	J	M
	6800	A A		С	C						G	G			J	J	J	J	J	J		J	J	J	J	J	J	M P
Cap	0.010	A		C			_				G	G			J	J	J	J	J	J		J	J	J	J	J	J	P
(μF	0.015			C						G	G				Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ		J	Ĵ	Ĵ	Ĵ	Ĵ	M	
	0.022			С						G	G				J	J	J	J	J	N		J	J	J	J	J	М	ı
	0.033									G	G				J	J	J	J	N			J	J	J	J	J	М	
	0.047								G	G	G				J	J	J	J	N			J	J	J	J	J	М	
	0.068	_		_					G	G	G			_	J	J	J	J	N		<u> </u>	J	J	J	J	J	Р	
	0.10 0.15							G G	G	G	G				J J	J	J J	J	N			J	J J	J	J	M Q		
	0.13							G							J	J	N	l N				J	.1	J		Q	i 1	
	0.33							ч							N	N	N	N				J	J	M	Р	Q	$\vdash$	
	0.47														N	N	N	N				М	М	М	Р		i 1	
	0.68														N	N	N					М	М	Q	Q			
	1.0							J	J						N	N	N					М	М	Q	Q		i 1	
	1.5																					Р	Q	Q				
	2.2 3.3	<u> </u>			-		J							_			N				<u> </u>	Q	Q	Q			$\vdash$	
	4.7														Р	Р								Q			i 1	
	10													Р	'							Q	Q	Q				
	22																				Q						$\Box$	
	47																										i 1	
	100																										$\square$	
	WVDC	10	16	16	25	50	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	500
	SIZE	02	201		040	2				06	03						080	)5						1	206			
Letter	Α		С		E		G		J	K	7	М		N		Р		Q		Х		Υ		Z	1			
Max.	0.33		0.56		).71		.86		94	1.0		1.2		1.40		1.52		1.78		2.29		2.54	1	2.79				
Thickness	(0.013)		).022)		.028)		034)		037)	(0.0)		(0.05		(0.05		(0.060		(0.070		0.090)		0.100)		.110)				
	(0.0.0)	1 (0		1 '	PER	(3.		(0.0	.,	(0.0	. 0,	(0.00	-)	,5.50	-/	`	BOS	`	,   (	2.000)			,,					
				IA	LIT											LIVI												







# **Capacitance Range**

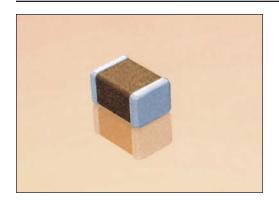
## **PREFERRED SIZES ARE SHADED**

SIZ	ZE				12	10					18	12			18	25		22	220		22	25	
Solde	ering			-	Reflow	/ Only					Reflov	v Only			Reflov	v Only		Reflo	w Only		Reflo	w Only	
Packa					per/En		ed				All Eml				All Emb				bossed			bossed	
(L) Length	MM (in.)				3.20 ± 0.126 ±						4.50 ± (0.177 ±				4.50 ± (0.177 ±			5.70 ± (0.225 ±			5.72 ± (0.225 ±		
(W) Width	MM				2.50 ±	0.20					3.20 ±	0.20			6.40 :	± 0.40		5.00 ±	± 0.40	$\neg \uparrow$	6.35 ±	0.25	
	(in.) MM				0.50 ±						(0.126 ±				0.252 =			0.197 ±			(0.250 ±		
(t) Terminal	(in.)			(0	0.020 ±	0.010)					(0.024 ±	0.014)			(0.024 =	± 0.014)		(0.025 ±	± 0.015)		(0.025 ±	0.015)	
0	WVDC	6.3	10	16	25	50	100	200	500	50	100	200	500		50	100	6.3	50	100	200	50	100	
Cap (pF)	100 150																		'		~ ~	-\n/	
	220																		L ~	كاسب		VV	
	330 470																			(		IJŢĭ	
	680																			_			
	1000																				a-t		
	1500 2200		J	J	J	J	J	J	M M												1		
	3300		J	J	J	J	J	J	М														
	4700 6800		J	J	J	J	J	J	M M														
Cap	0.010		J	J	J	J	J	J	M	K	K	K	K		M	М	Х	Х	Х	Х	М	Р	
(μF	0.015		J	J	J	J	J	J	Р	K	K	K	Р		М	М	X	X	X	Х	М	P	
	0.022	_	J	J	J	J	J	J	Q	K	K	K	P X		M	M M	X	X	X	X	M M	P P	
	0.047		Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ		K	K	K	Z		M	M	X	X	X	X	M	P	
	0.068	_	J	J	J	J	J	M		K	K	K			M	M M	X	X	X	X	<u>М</u> М	P P	
	0.10 0.15		J	J	J	J	J M	IVI		K K	K	K P			M M	M M	X	X	X	X	M M	P	
	0.22		J	J	J	J	Р			K	K	Р			М	М	Х	X	X		М	Р	
	0.33 0.47		J M	J M	J M	J M	Z			K K	M P				M M	M M	X	X	X		M M	P P	
	0.68		M	M	P	X	Z			M	Q				M	141	X	X	X		M	P	
	1.0		N	N	P	X	Z			M	X				M			X	Z Z		M	P	
	1.5 2.2		N Z	N Z	Z	Z Z				Z Z	Z Z				M			Χ			M M	X	
	3.3		Z	Z	Z	Z				Z													
	4.7 10		Z Z	Z 7	Z	Z				Z								Z					
	22		Z	Z																-			
	47																						
	100 WVDC	6.3	10	16	25	50	100	200	500	50	100	200	500		50	100	6.3	50	100	200	50	100	
SIZ					121							12			18				220		22		
I otto:	Δ		_		Е		C			. к	,	М		NI I	Р	Q	X		Υ		, ]		
Letter Max.	<b>A</b> 0.33		<b>C</b> 0.56		<u>=</u> ).71	(	<b>G</b> .86		<b>J</b> 94	1.0		1.27		<b>N</b> .40	1.52		2.2		2.54	2.7			
Thickness			0.022)		.028)		034)		037)	(0.0)		(0.050)		055)	(0.060		(0.090) (0.100) (0.110)						
				PA	PER										EM	BOSSED							

= Under Development







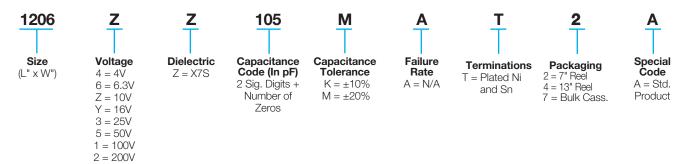
## **GENERAL DESCRIPTION**

X7S formulations are called "temperature stable" ceramics and fall into EIA Class II materials. Its temperature variation of capacitance is within  $\pm 22\%$  from -55°C to  $\pm 125$ °C. This capacitance change is non-linear.

Capacitance for X7S varies under the influence of electrical operating conditions such as voltage and frequency.

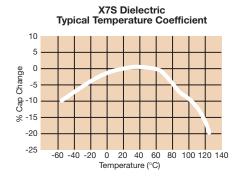
X7S dielectric chip usage covers the broad spectrum of industrial applications where known changes in capacitance due to applied voltages are acceptable.

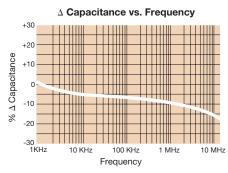
## PART NUMBER (see page 2 for complete part number explanation)

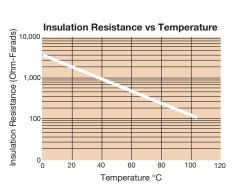


NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers.

#### TYPICAL ELECTRICAL CHARACTERISTICS

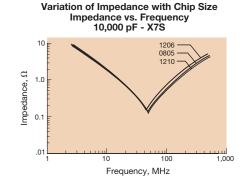


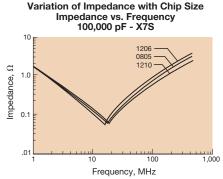




Impedance vs. Frequency 1,000 pF vs. 10,000 pF - X7S 0805 10.00 pF 1,000 pF 10,000 pF 10,000 pF 10,000 pF 1000 pF

Variation of Impedance with Cap Value









# **Specifications and Test Methods**

	ter/Test	X7S Specification Limits	Measuring	
	perature Range	-55°C to +125°C	Temperature C	Cycle Chamber
Capac	on Factor	Within specified tolerance ≤ 2.5% for ≥ 50V DC rating ≤ 3.0% for 25V DC rating ≤ 3.5% for 16V DC rating ≤ 5.0% for ≤ 10V DC rating	Freq.: 1.0 k Voltage: 1.0 For Cap > 10 μF, (	Vrms ± .2V
Insulation	Resistance	100,000MΩ or 1000MΩ - $\mu$ F, whichever is less	Charge device with 120 ± 5 secs @ ro	om temp/humidity
Dielectric	Strength	No breakdown or visual defects	Charge device with 300 1-5 seconds, w/charge limited to 50	and discharge current 0 mA (max)
	Appearance	No defects	Deflection	
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3	30 seconds 7 1mm/sec
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)	V	
	Insulation Resistance	≥ Initial Value x 0.3	90 r	
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for $5.0 \pm 0.0$	
	Appearance	No defects, <25% leaching of either end terminal		
	Capacitance Variation	≤ ±7.5%	Dip device in eutectic :	coldor at 260°C for 60
Resistance to	Dissipation Factor	Meets Initial Values (As Above)	seconds. Store at room	temperature for 24 $\pm$ 2
Solder Heat	Insulation Resistance	Meets Initial Values (As Above)	hours before measurin	g electrical properties.
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes
SHOCK	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles ar 24 ± 2 hours at room	
	Appearance	No visual defects		
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 test chamber set	at 125°C ± 2°C
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	for 1000 hou	,
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test ch at room temperatu	re for 24 ± 2 hours
	Dielectric Strength	Meets Initial Values (As Above)	before me	easuring.
	Appearance	No visual defects	Store in a test chamb	er set at 85°C + 2°C/
	Capacitance Variation	≤ ±12.5%	85% ± 5% relative hul (+48, -0) with rated	midity for 1000 hours
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	Remove from cham	
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	room temperature	and humidity for
	Dielectric Strength	Meets Initial Values (As Above)	24 ± 2 hours be	iore measuring.



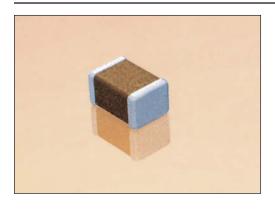




					<b>E</b>		ш				I			
SIZE	<b>.</b>	0402	2		0603		0805	12	206	121	10			
Solderi	ing	Reflow C	nly	Re	flow Only	y Re	flow/Wave	Reflov	v/Wave	Reflow	Only			
Packag		All Pap	er	Α	ll Paper		er/Embossed	Paper/E	mbossed	Paper/Em	nbossed			
L) Length	MM	1.00 ± 0.			60 ± 0.15		1.01 ± 0.20		± 0.20	3.20 ±				
	(in.) MM	$(0.040 \pm 0.0000)$			$63 \pm 0.006$ $81 \pm 0.15$		079 ± 0.008) .25 ± 0.20		± 0.008) ± 0.20	(0.126 ± 2.50 ±				
(W) Width	(in.)	$(0.020 \pm 0.$	004)		$32 \pm 0.006$	6) (0.0	0.008)	(0.063	± 0.008)	(0.098 ±	0.008)			
t) Terminal	MM	0.25 ± 0.			$35 \pm 0.15$		1.50 ± 0.25		± 0.25	0.50 ±				
.,	(in.) WVDC	(0.010 ± 0.	006)	6.3	14 ± 0.006		020 ± 0.010) 4	6.3	± 0.010)	(0.020 ±				
Cap	100	0.0		0.5	20		4	0.5	10	0.0				
(pF)	150													
	220							<b>.</b> .		$\sim$	<b>-</b>			
	330 470								_َ_َ		T			
	680							(		\	1			
	1000							t						
	1500								4 t	-				
	2200 3300					_		╀	1 -					
	4700								1	ı				
	6800													
Cap	0.010													
(μF	0.015 0.022													
	0.022	С				_								
	0.047	Č												
	0.068	C												
	0.10 0.15	С												
	0.13				G									
	0.33			G				İ						
	0.47			G										
	0.68			G G		-		-						
	1.5			u			N	Q						
	2.2						N	Q						
	3.3						N	Q						
	4.7 10						N	Q	Q					
	22									Z				
	47													
	100							<b>—</b>	10					
	WVDC	6.3	,	6.3	25		4	6.3	10	6.3				
	SIZE	0402			0603		0805	12	206	121	10			
Letter	Α	С	E		G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.7		0.86	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.7
Thickness	(0.013)	(0.022)	(0.02	, ,	0.034)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.11
			PAPE	ER						EMBC	DSSED			



## **General Specifications**

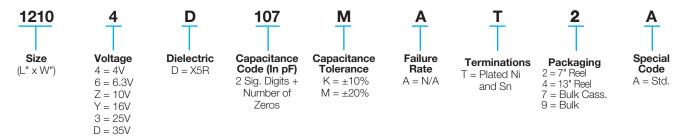


5 = 50V

## **GENERAL DESCRIPTION**

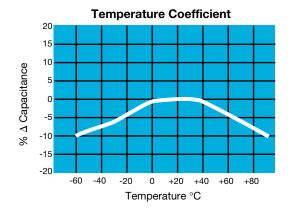
- General Purpose Dielectric for Ceramic Capacitors
- EIA Class II Dielectric
- Temperature variation of capacitance is within ±15% from -55°C to +85°C
- Well suited for decoupling and filtering applications
- Available in High Capacitance values (up to 100μF)

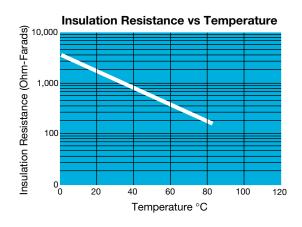
## PART NUMBER (see page 2 for complete part number explanation)



NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.

#### TYPICAL ELECTRICAL CHARACTERISTICS







# **Specifications and Test Methods**

Parame		X5R Specification Limits	Measuring	Conditions
Operating Temp	perature Range	-55°C to +85°C	Temperature C	Cycle Chamber
Capac	itance	Within specified tolerance		
		≤ 2.5% for ≥ 50V DC rating	Freq.: 1.0 k	
Dissipation	on Factor	≤ 3.0% for 25V DC rating	Voltage: 1.0	
Diooipatio		≤ 3.5% for 16V DC rating	For Cap $> 10 \mu F$ ,	0.5Vrms @ 120Hz
		≤ 5.0% for ≤ 10V DC rating		
Insulation I	Resistance	100,000MΩ or 500MΩ - μF,	Charge device wit	
		whichever is less	120 ± 5 secs @ ro Charge device with 30	
Dielectric	Strength	No breakdown or visual defects	1-5 seconds, w/charge limited to 5	and discharge current 0 mA (max)
	Appearance	No defects	Deflection	
	Capacitance	≤ ±12%	Test Time:	30 seconds
Resistance to	Variation		\	1mm/sec
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)		
	Insulation Resistance	≥ Initial Value x 0.3	90 1	mm —
Solder	rability	≥ 95% of each terminal should be covered	Dip device in eutection	
Coluci		with fresh solder	for $5.0 \pm 0.0$	5 seconds
	Appearance Capacitance	No defects, <25% leaching of either end terminal		
	Variation	≤ ±7.5%		
	Dissipation		Dip device in eutectic	
Resistance to	Factor	Meets Initial Values (As Above)	seconds. Store at room	
Solder Heat	Insulation		hours before measurin	g electrical properties.
	Resistance	Meets Initial Values (As Above)		
	Dielectric	Meets Initial Values (As Above)		
	Strength	, , ,		
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes
	Capacitance	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes
	Variation		· ·	
Thermal	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +85°C ± 2°	30 ± 3 minutes
Shock	Insulation			
	Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric	M	Repeat for 5 cycles ar	nd measure after
	Strength	Meets Initial Values (As Above)	24 ± 2 hours at room	temperature
	Appearance	No visual defects	Charge device with	1.5X rated voltage in
	Capacitance	≤ ±12.5%	test chamber set at 85°	
	Variation		(+48, -0). Note: Contact	
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	CV devices that are teste	ed at 1.5X rated voltage.
Load Life	Insulation			
	Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test ch	
	Dielectric	A4	at room temperatu	
	Strength	Meets Initial Values (As Above)	before m	easuring.
	Appearance	No visual defects	Store in a test chamb	er set at 85°C + 2°C/
	Capacitance	≤ ±12.5%	85% ± 5% relative hu	
	Variation		(+48, -0) with rate	
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)		
riamidity	Insulation		Remove from cham	
	Resistance	≥ Initial Value x 0.3 (See Above)	room temperature	
	Dielectric	Marka Initial Val. (A. Al. )	$24 \pm 2$ hours be	fore measuring.
	Strength	Meets Initial Values (As Above)		







## PREFERRED SIZES ARE SHADED

																					<b>E</b>	11																		
SIZ	E		02	201				04	02					C	0603	3					08	05					120	6					12	10				18	12	_
Solder	rina	R	eflo	w Oı	nlv	T	R	eflo	v Or	ılv				Refl	ow (	Only	,		$\vdash$	Ref	flow	/Wa	ave		T	Ref	flow/	Nav	e			Re	flow	/Wav	re		R	eflov	/ On	V
Packag		_		Pape		t		All P							Par				F				ssec	<u> </u>	F		r/Em				F			nbos			-	Emb		_
(L) Length	MM (in.)			± 0.0 ± 0.0				1.00 :						1.6 (0.06	0 ± 0		:)		Г		.01 ±						.20 ± 1		5/	T				0.20				1.50 ±		
000 \0/6dtb	MM			± 0.0		⊢		0.50 :				$\vdash$			$1 \pm 0$		"		$\vdash$		.25 ±			_	$\vdash$		.60 ± 1		)	+				0.20	٥)			3.20 ±		
(W) Width	(in.)			± 0.0		┖		.020 :						(0.03			6)		┖		)49 ±				_		63 ±		3)					0.00	B)			126 ±		
(t) Terminal	MM (in.)			± 0.0 ± 0.0				0.25 : .010 :						0.3 0.01)	5 ± 0 4 ± 0		6)				.50 ±						.50 ± 1		0)					0.25	O)			).61 ± 024 ±		
	WVDC			16		4					50	4			16			50	6.3					50	6.3					0	4 6.3					50		10		
Cap	100				А																																			
(pF)	150 220				A						С																													
	330	H			A	Н					С	$\vdash$							$\vdash$						$\vdash$	-	+	+	+						_					—
	470				A						С																				اس	_	$\overline{}$		$\subseteq$	-W-	>			
	680	L			Α						С	L													Ш			$\perp$	$\perp$	4	•	$\leq$	_	\	_	١)	T			
	1000			Α	Α						С																					_	. ]		_		_			
	1500 2200		Α	A							С																						با							
	3300	$\vdash$	A	A		$\vdash$	$\vdash$	$\vdash$	$\vdash$	$\vdash$	С	Н						$\vdash$	$\vdash$			_			$\vdash$	$\dashv$	+	+	+				"1	:					$\dashv$	—
	4700		A							С								G												Τ		1				I	I			
	6800		А							С								G																						
Cap	0.010		Α							С								G																						
(µF)	0.015 0.022	Α							С	С						G	G	G						Ν																
	0.022	A			-	-			С							G	G	G						N				+	+	+		+	+							_
	0.033	Α							С							G	G	G						N																
	0.068								С							G		G						Ν																
	0.10	Α						С	С							G		G				Ζ		Ν																
	0.15															G						N	N																	
	0.22	⊢	$\vdash$	$\vdash$	$\vdash$	⊢	С	-	$\vdash$	$\vdash$		⊢			G	G G		$\vdash$	$\vdash$			N	N	_	$\vdash$	$\dashv$	+	+	C	٧	+	+	+	+	+	+	┢		$\dashv$	—
	0.33					С	С								G	G						N						Q	Q							X				
	0.68														G							N																		
	1.0	Г				С	С	С					G	G	G	J					N	N		P*				Q	Q	Т				Х	Х	Х				_
	1.5																			N	N	N.I.						_						7	\ \/					7
	2.2	H	$\vdash$	$\vdash$	+	С		1	-	-		G	G	J	J			-	NI	N	N	Ν			$\vdash$		-	Q	+	+	+	+	+	Z	X		$\vdash$	$\vdash$		Ζ
	3.3 4.7											G	G						N	N N	N	N*						Q Q					Z	Z						
	10											K							N	N	N				Q			Q				Z								
	22																		N						Q	Q	Q			T	Z		: Z	Z*						
	47					1					1	l													Q						Z						1			
	100 WVDC	6.3	3 10	16	25	4	6.3	10	16	25	50	4	6.3	10	16	25	35	50	6.3	10	16	25	35	50	6.3	10	16 2	25 :	35 5	0	Z Z <sup>4</sup>		) 16	3 25	35	50	6.3	10	25	50
SIZ		J		201	1_0	Ė	, 5.0		02	1-0	,50	Ė			0603		, 50	150	1		080				1		120		- 10	1	10.0		12		, 50	, 55	1.5	18		
Letter	Α			E		C			J			K			М			N		Q			Х			Υ		7												
Max.	0.33			.71		0.0			0.94			1.02			.27	,		40		1.7			2.29			2.54	,	2.												
Thickness	(0.013)		(U.	028)		(0.0)	04)	(	0.03	11)	1 ((	0.040	J)	(U.	050	)	(U.(	055)		(0.07)	U)	1 (	(0.09)	(U)	1 (0	.100	)	(0.1)	10)	1										

= Under Development

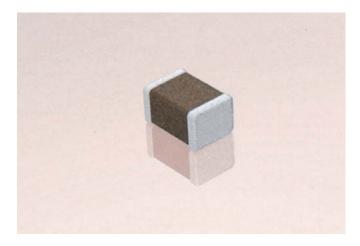
\*Optional Specifications - Contact factory

NOTE: Contact factory for non-specified capacitance values

# **Y5V Dielectric**



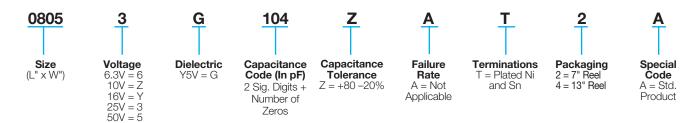


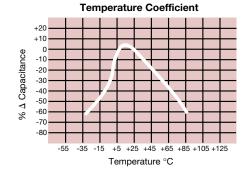


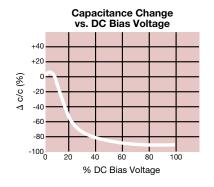
Y5V formulations are for general-purpose use in a limited temperature range. They have a wide temperature characteristic of +22% -82% capacitance change over the operating temperature range of -30°C to +85°C.

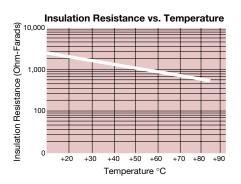
These characteristics make Y5V ideal for decoupling applications within limited temperature range.

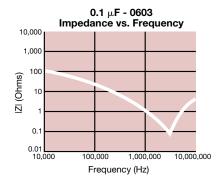
## PART NUMBER (see page 2 for complete part number explanation)

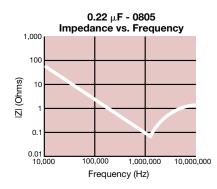


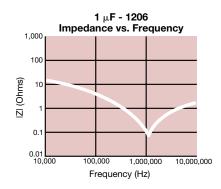














# **Y5V Dielectric**



# **Specifications and Test Methods**

Parame	ter/Test	Y5V Specification Limits	Measuring	
	perature Range	-30°C to +85°C	Temperature C	Cycle Chamber
	itance on Factor	Within specified tolerance ≤ 5.0% for ≥ 50V DC rating ≤ 7.0% for 25V DC rating ≤ 9.0% for 16V DC rating ≤ 12.5% for ≤ 10V DC rating	Freq.: 1.0 l Voltage: 1.0 For Cap > 10 μF,	Vrms ± .2V
Insulation	Resistance	100,000MΩ or 500MΩ - $\mu$ F, whichever is less	Charge device wit 120 ± 5 secs @ ro	
Dielectric	Strength	No breakdown or visual defects	Charge device with 30	0% of rated voltage for and discharge current
	Appearance	No defects	Deflection	
	Capacitance	≤ ±30%	Test Time:	30 seconds
Resistance to Flexure	Variation Dissipation			1mm/sec
Stresses	Factor Insulation	Meets Initial Values (As Above)		
	Resistance	≥ Initial Value x 0.1	90 1	mm —
Solde	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutection for 5.0 ± 0.0	
	Appearance	No defects, <25% leaching of either end terminal	101 010 = 01	
	Capacitance	≤ ±20%		
	Variation	\$ 12070	Din device in eutectic	solder at 260°C for 60
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	seconds. Store at room hours before measuring	temperature for $24 \pm 2$
Joidel Heat	Insulation Resistance	Meets Initial Values (As Above)	Tiodia bolore medadili	g cicetileal properties.
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects	Step 1: -30°C ± 2°	30 ± 3 minutes
	Capacitance Variation	≤ ±20%	Step 2: Room Temp	≤ 3 minutes
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +85°C ± 2°	30 ± 3 minutes
SHOCK	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles ar 24 ±2 hours at room	
	Appearance	No visual defects	Oleganor alanda a vi 91 d	udaa wakaal uu libu uu libu
	Capacitance Variation	≤ ±30%	Charge device with t	et at 85°C ± 2°C
Load Life	Dissipation Factor	≤ Initial Value x 1.5 (See Above)	for 1000 hou	
	Insulation Resistance	≥ Initial Value x 0.1 (See Above)	Remove from test chat room temperatu	re for 24 ± 2 hours
	Dielectric Strength	Meets Initial Values (As Above)	before m	easuring.
	Appearance	No visual defects	Store in a test chamb	er set at 85°C ± 2°C/
	Capacitance Variation	≤ ±30%	85% ± 5% relative hu (+48, -0) with rate	midity for 1000 hours
Load Humidity	Dissipation Factor	≤ Initial Value x 1.5 (See above)	(+48, -0) with rate  Remove from cham	
	Insulation Resistance	≥ Initial Value x 0.1 (See Above)	room temperature  24 ± 2 hours be	e and humidity for
	Dielectric Strength	Meets Initial Values (As Above)	Z4 ± Z HOUIS DE	nore measuility.



# **Y5V Dielectric**



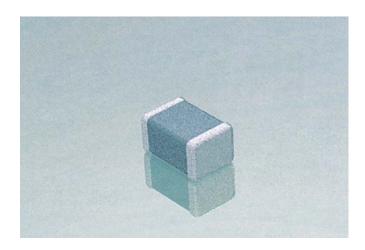


									<b>-</b>			ш	1				1					
SIZE	E	02	201		0402			06	603			080	)5			12	06			1:	210	
Solder	ing	Reflo	w Only		Reflow On	y		Reflov	w Only			Reflow/	Wave			Reflow	/Wave			Reflo	ow Only	
Packag	ging	All F	aper		All Paper			All P	aper		Р	aper/Em	bossed		F	aper/Er	nbossec	1		Paper/6	Embosse	ed
(L) Length	MM (in.)		± 0.03 ± 0.001)		1.00 ± 0.10 (0.040 ± 0.00			1.60 =	± 0.15 ± 0.006)			2.01 ± (0.079 ±				3.20 ± (0.126 ±					0.20 6 ± 0.008	3)
(W) Width	MM (in.)	(0.011	± 0.03 ± 0.001)		0.50 ± 0.10 (0.020 ± 0.00	04)		(0.032 -				1.25 ± (0.049 ±	0.008)			1.60 ± (0.063 ±	0.008)			(0.098	0.20 ± 0.20 ± 0.008	3)
(t) Terminal	MM (in.)	(0.006	± 0.05 ± 0.002)		$0.25 \pm 0.15$ $(0.010 \pm 0.00)$	06)		0.35 = (0.014 =	± 0.006)			0.50 ± (0.020 ±	0.010)			0.50 ± (0.020 ±	0.010)			(0.020	± 0.25 ) ± 0.010	,
	WVDC	6.3	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50
Cap (pF)	820 1000 2200		A A																· ~		T ✓W:	•
Cap (µF)	4700 0.010 0.022	A A	A A	С	C	C				G G											$\mathcal{I}$	) T
	0.047 0.10 0.22	А		CC				G	G G	G			J K	K N				ı i	Ì	1	ı	ı
	0.47 1.0 2.2						G	G G			N	K N N	N N			М	М	М				N
	4.7 10.0 22.0 47.0										N				Q Q	M Q			X	Q	N Q	
	WVDC	6.3	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50
SIZE	E	02	201		0402			06	603			30	305			12	206			12	210	
Letter	Α		C         E         G         J         K         M         N         P           0.56         0.71         0.86         0.94         1.02         1.27         1.40         1.52				Q	X		Y		70										
Max.	0.33													78	2.29		2.54	2.				
Thickness	(===) (===)			(0.037)	(0.040	) (0	.050)	(0.05	00)	(0.060)	1.	070)	(0.09	U) (	(0.100)	(0.1	10)					
				PAPER								EMB	OSSE	D								



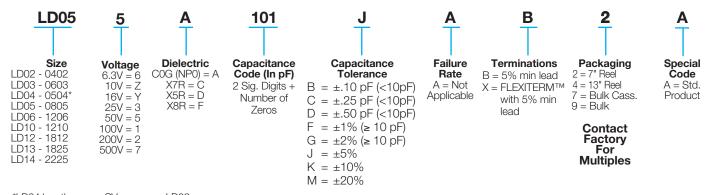


## **General Specifications**



AVX Corporation will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the AVX Catalog Part Number. This fulfills AVX's commitment to providing a full range of products to our customers. AVX has provided in the following pages a full range of values that we are currently offering in this special "B" termination. Please contact the factory if you require additional information on our MLCC Tin/Lead Termination "B" products.

## PART NUMBER (see page 2 for complete part number explanation)



<sup>\*</sup>LD04 has the same CV ranges as LD03.

NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specific capacitance values.

See FLEXITERM™ section for CV options

NP0	Refer to page 4 for Electrical Graphs
X7R	Refer to page 14 for Electrical Graphs
X7S	Refer to page 18 for Electrical Graphs
X5R	Refer to page 21 for Electrical Graphs
Y5V	Refer to page 24 for Electrical Graphs





# **Capacitance Range (X8R Dielectric)**

	SIZ	Έ			LD03				LD	05			L	.D06	
		WVDC	;	25V	/	50V		2	25V	50V		25V		50	)V
271	С	ap 270		G		G					T				
331	(p			G		G			J	J					
471		470		G		G			J	J					
681		680		G		G			J	J					
102		1000		G		G			J	J		J			J
152		1500		G		G			J	J		J			J
182		1800		G		G			J	J		J			J
222		2200		G		G			J	J		J			J
272		2700		G		G			J	J		J			J
332		3300		G		G			J	J		J			J
392		3900		G		G			J	J		J			J
472		4700		G		G			J	J		J			J
562		5600		G		G			J	J		J			
682		6800		G		G			J	J		J			
822		8200		G		G			J	J		J			
103		ap 0.01		G		G			J	J		J			
123	(µ	F) 0.012		G		G			J	J		J			
153		0.015		G		G			J	J		J			J
183		0.018		G		G			J	J		J			
223		0.022		G		G			J	J		J			
273		0.027		G		G			J	J		J			J
333		0.033		G		G			J	J		J			
393		0.039		G		G			J	J		J			
473		0.047		G		G			J	J		J			
563		0.056		G					N	N		М		N	
683		0.068		G					N	N		М		N	
823		0.082							N	N		М		N	
104		0.1							N	N		М		N	
124		0.12							N	N		М		N	Λ
154		0.15							N	N		М		N	
184		0.18							N			М		N	
224		0.22 0.27							N			M		N	
274											$\rightarrow$	М		N	
334		0.33									$\longrightarrow$	М		N	/I
394		0.39 0.47										M			
474 684												М			
824		0.68 0.82													
105		0.82		-				<u> </u>			-			-	
105		WVDC	<b>.</b>	25V	,	50V		-	25V	50V	-	25V		50	)//
	SIZE			250	LD03					)05	-	201	1.5	006	, v
Letter	Α	С	Е	G	J	K		М	N	P	Q	Х		Υ	Z
Max.	0.33	0.56	0.71	0.86	0.94	1.02		1.27	1.40	1.52	1.78			2.54	2.79
Thickness				(0.034)	(0.037)	(0.040)	(0	).050)	(0.055)	(0.060)	(0.070	0.09	90)	(0.100)	(0.110)
			PAPER							EMBO	SSED				





# **Capacitance Range (NP0 Dielectric)**

			-			•	· · · · · · · · · · · · · · · · · · ·				ш								
SIZI	Ε		LD02			LD	003				LD05					LD0	6		
Solder			eflow Or				w Only				flow/Wa					Reflow/V			
Packag (L) Length	ging MM		All Pape 1.00 ± 0.1				<b>Paper</b> ± 0.15				er/Embos 2.01 ± 0.20				Pa	3.20 ± 0			
	(in.) MM		$0.40 \pm 0.0$				± 0.006) ± 0.15				079 ± 0.00					$\frac{(0.126 \pm 0)}{1.60 \pm 0}$			
(W) Width	(in.)	(0.	$020 \pm 0.0$	04)		(0.032	± 0.006)			(0.	$0.000 \pm 0.000$	08)				$(0.063 \pm 0.000)$	.008)		
(t) Terminal	MM (in.)	(0.	0.25 ± 0.1 010 ± 0.0	06)		(0.014	± 0.15 ± 0.006)			(0.	0.50 ± 0.25 020 ± 0.01	0)				$0.50 \pm 0$ $(0.020 \pm 0)$	.010)		
Cap	WVDC 0.5	16 C	25 C	50 C	6.3 G	25 G	50 G	100 G	16 J	25 J	50 J	100 J	200 J	16 J	25 J	50 J	100 J	200 J	500 J
(pF)	1.0	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	1.2 1.5	C C	C C	C	G G	G G	G G	G G	J	J	J	J J	J J	J J	J J	J	J J	J	J
	1.8 2.2	00	C	C	G G	G G	G G	G G	J	J	J	ے ک	J	J	J	J	J	J	J
	2.7	С	С	С	G	G	G	G	J	Ĵ	Ĵ	J	J	J	J	J	J	J	J
	3.3 3.9	C	C	C	G G	G G	G G	G G	J	J	J	J J	J	J J	J J	J	J	J J	J
	4.7	C	C	C	G	G	G	G G	J	J	J	J	J	J	J	J	J	J	J
	5.6 6.8	С	С	С	G	G	G	G	J	J	J	J	J J	J	J	J	J	J J	J
	8.2 10	C	C	C	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J
	12	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	15 18	C	C	C	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J
	22 27	C C	C C	C	G G	G G	G G	G G	J J	J J	J	J J	J J	J J	J J	J J	J J	J J	J J
	33	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	39 47	C	C	C	G G	G G	G G	G G	J J	J	J	J J	J J	J J	J J	J	J J	J J	J
	56	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	68 82	C	C C	C C	G G	G G	G G	G G	J	J	J	J J	J J	J	J	J	J J	フラ	J
	100 120	C	C	C C	G G	G G	G G	G G	J	J	J	J	J	J J	J J	J	J	J	J
	150	С	С	С	G	G	G	G	J	Ĵ	Ĵ	J	J	J	J	J	J	J	J
	180 220	CC	C	C	G G	G G	G G	G G	J J	J	J	J J	J J	J J	J J	J	J	J J	J M
	270				G G	G G	G G	G G	J J	J	J	J	M M	J J	J J	J	J	J	M M
	330 390				G	G	G	G	J	J	J	J	М	J	J	J	J	J	М
-	470 560				G G	G G	G G		J	J	J	J	M M	J	J	J	J	J	M
	680				G	G	G		J	J	J	J		J	J	J	J	J	Р
	820 1000				G G	G G	G G		J	J	J	J		J	J	J	J	M Q	
	1200 1500								J J	J	J			J J	J J	J J	J M	QQ	
	1800								J	J	J			J	J	М	М	Q	
	2200 2700								J	J	M M			J	J	M M	P P		
	3300 3900													J J	J J	M M	P P		
	4700			>		<b>€</b> W_								J	J	М	P		
	5600 6800		~											J M	J M	М			
Con	8200		(		<u> </u>	.للر	ŢT							М	М				
Cap (µF)	0.010 0.012			\	سرار									М	М				
	0.015 0.018		-		t														
	0.022																		
	0.027																		
	0.039 0.047																		
	0.068																		
	0.082 0.1																		
	WVDC	16	25	50	6.3	25	50	100	16	25	50	100	200	16	25	50	100	200	500
	SIZE		LD02			LE	003				LD05					LD			
Letter Max.	<b>A</b> 0.33	0.8		<b>E</b> 0.71	<b>G</b>	3	<b>J</b> 0.94	<b>K</b>		<b>M</b> .27	<b>N</b>	<b>P</b>		<b>Q</b> 1.78	<b>X</b> 2.29		<b>Y</b> .54	<b>Z</b>	2
Thickness	(0.013)	(0.0	)22)	(0.028)	(0.03		0.94	(0.040		050)	(0.055)	(0.06		0.070)	(0.090		100)	(0.11	
			F	PAPER								EN	MBOSS	ED					



# **Capacitance Range (NP0 Dielectric)**

PNEF	Enni		SIZ		INL	SH	ADL	-0									
															1		
SIZ				LD10	h.			D	LD12 eflow Or	sh.			LD13			LD14	h.
Solde Packa				leflow On er/Embos					Emboss				Reflow Only All Embossed	<u> </u>		Reflow Onl	,
(L) Length	MM (in.)			3.20 ± 0.20 126 ± 0.00					4.50 ± 0.3 177 ± 0.0	0			4.50 ± 0.30 (0.177 ± 0.012)			5.72 ± 0.25 (0.225 ± 0.01	
(W) Width	MM (in.)		- 2	$\frac{120 \pm 0.00}{2.50 \pm 0.20}$ $\frac{120 \pm 0.00}{0.00}$				3	$3.20 \pm 0.2$ $126 \pm 0.0$	0			$6.40 \pm 0.40$ (0.252 ± 0.016)			6.35 ± 0.25 (0.250 ± 0.01	
(t) Terminal	MM (in.)		(	0.50 ± 0.00 0.50 ± 0.25 020 ± 0.01				(	0.61 ± 0.3 024 ± 0.0	6			0.61 ± 0.36 (0.024 ± 0.014)			0.64 ± 0.39 (0.025 ± 0.01	
	WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200
Cap (pF)	0.5 1.0																
( 51.)	1.2																
	1.5 1.8																
	2.2 2.7														_l^	<b>&gt;</b>	€W_
	3.3															$\leq$	) <u>T</u>
	3.9 4.7																
	5.6 6.8															- T	
	8.2 10															1	
	12					J											
	15 18					J											
	22 27					J J											
-	33					J											
	39 47					J J											
	56 68					J											
	82					J											
	100 120					J J											
	150 180					J											
	220					J											
	270 330					J											
	390 470					M M											
	560 680	J J	J	J	J J	M M											
	820	J	J	J	J	М	1.6	16	16								
	1000 1200	J J	J	J	J M	М	K K	K K	K K	K K	M M	M M	M M	M M	M M	M M	P P
	1500 1800	J J	J	J	M M		K K	K	K K	K	M M	M M	M M	M M	M M	M M	P P
	2200	J	J	J	Q		K	K	K	K	Р	M	M	М	М	M	Р
	2700 3300	J	J	J	Q		K K	K	K	P P	Q	M M	M M	M M	M M	M M	P P
	3900 4700	J J	J	M M			K K	K K	K K	P P	Q Q	M M	M M	M M	M M	M M	P P
	5600 6800						K	K	М	P X	X	M M	M M	M M	M M	M M	P P
	8200						K K	М	M M			M	М	IVI	M	M	Р
Cap (µF)	0.010 0.012						K K	M M	М			M M	M M		M M	M M	P P
-	0.015 0.018						M M	M M				M P	M M		M M	M M	Y
	0.022						M	M				P	IVI	1	M	Y	Y
	0.027 0.033													-	Р	Y	Y
	0.039 0.047																
	0.068																
	0.082 0.1						L										
SIZI	WVDC	25	50	100 <b>LD10</b>	200	500	25	50	100 <b>LD12</b>	200	500	50	100 <b>LD13</b>	200	50	100 <b>LD14</b>	200
Letter	A			E	G		J	K		M	N	P	Q	Х	I Y Z		
Max.	0.33	0.	56	0.71	0.86		0.94	1.02	1	.27	1.40	1.52	1.78	2.29 2	.54 2.7	'9	
Thickness	(0.013)	(0.0		(0.028) PAPER	(0.03	4) ((	).037)	(0.040	)	050)	(0.055)	(0.060) EMBO		(0.090) (0	.100) (0.1	10)	



# **Capacitance Range (X7R Dielectric)**

								ш																		
SIZI	Ε		LD02	2				LD03	3						LD05	;						LE	006			
Solder	ina	Re	flow C	Only			Re	flow C	)nlv					Ref	low/W	ave						Refloy	v/Wav	'e		
Packag		_	II Pap					II Pap						Pane	/Emb	nssed							mbos			
(L) Length	MM (in.)	1.	.00 ± 0.	.10			1.	.60 ± 0.	15					2.	01 ± 0.2 79 ± 0.0	20						3.20	± 0.20 ± 0.008			
	(III.) MM		$.50 \pm 0.$					$.81 \pm 0.$							$79 \pm 0.0$ $25 \pm 0.0$				_				± 0.000 ± 0.20	9)		
(W) Width	(in.)		$120 \pm 0.0$					.01 ± 0. 132 ± 0.							49 ± 0.0								± 0.20 ± 0.008	3)		
	MM		$.25 \pm 0.$					$.35 \pm 0.$							$50 \pm 0.5$								± 0.25	1		
(t) Terminal	(in.)		$10 \pm 0$					$14 \pm 0.0$							$20 \pm 0.0$								± 0.010	))		
	WVDC	16	25	50	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	500
Cap	100																									
(pF)	150																		l							
	220			С															l							
	330			С					G	G	G		J	J	J	J	J	J								K
	470			С	l				G	G	G		J	J	J	J	J	J	l							K
	680			С					G	G	G	L	J	J	J	J	J	J								K
	1000			С					G	G	G		J	J	J	J	J	J								K
	1500			С					G	G			J	J	J	J	J	J	l	J	J	J	J	J	J	М
	2200			С					G	G			J	J	J	J	J	J		J	J	J	J	J	J	М
	3300		С	С					G	G			J	J	J	J	J	J		J	J	J	J	J	J	М
	4700		С		l				G	G			J	J	J	J	J	J	l	J	J	J	J	J	J	М
	6800	С	С						G	G			J	J	J	J	J	J		J	J	J	J	J	J	Р
Cap	0.010	С							G	G			J	J	J	J	J	J		J	J	J	J	J	J	Р
μF	0.015	С						G	G				J	J	J	J	J	J		J	J	J	J	J	М	
	0.022	С						G	G				J	J	J	J	J	N		J	J	J	J	J	М	
	0.033						_	G	G				J	J	J	J	N		l	J	J	J	J	J	М	
	0.047				l		G	G	G				J	J	J	J	N		l	J	J	J	J	J	M	
	0.068				<u> </u>	_	G	G	G			_	J	J	J	J	N		<u> </u>	J	J	J	J	J	P	
	0.10					G	G	G	G				J	J	J	J	N		l	J	J	J	J	M	Р	
	0.15				l	G							J	J	J	N			l	J	J	J	J	Q		
	0.22					G						_	N	J	N N	N N			$\vdash$	J	J	J	J	Q		
	0.33												N	N	N	N	N		l	M	M	M	P	Q		
	0.47												N	N	N	IN	N		l	M	M	Q	Q			
	1.0					J	J					$\vdash$	N	N	N		_	-	$\vdash$	M	M	Q	Q	Q		_
	1.5				l	U	0						14	14	IN				l	P	Q	Q	4	Q		
	2.2				J										N				l	Q	Q	Q				
	3.3														- 14					Q	Q	Q				_
	4.7				l								Р	Р					l	Q	Q	Q				
	10				l							Р							l	Q	Q	~				
	22				$\vdash$														Q							
	47																									
	100																		l							
	WVDC	16	25	50	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	500
	SIZE		LD0	2				LD03	3						LD05							LD	06			
1 -44 -			^		_		0				V							^		V		V		-		
Letter	Α		<u>C</u>		E		G		J		K	N		N	_	P	_	Q		X		Υ		<b>Z</b>		
Max.	0.33		0.56		0.71		0.86		.94		.02	1.2		1.4		1.5		1.78		2.29	,	2.54		2.79		
Thickness	(0.013)	((	).022)	,	.028)	(0	.034)	(0.	037)	(0.	040)	(0.0)	150)	(0.05	5)	(0.06	,	(0.070	J)	(0.090	J)	(0.100	)) (	(0.110)		
				P/	APER											ΕN	/BOS	SED								





# **Capacitance Range (X7R Dielectric)**

SIZE LD10 Soldering Reflow Only			LD	12					
* '						LD	13	LI	D14
5 (5)			Reflov	v Only		Reflov	v Only	Reflo	ow Only
Packaging Paper/Embossed			All Emb	ossed		All Emb	oossed	All En	nbossed
(L) Length MM (in.) 3.20 ± 0.20 (0.126 ± 0.008)			4.50 ± (0.177 ±			4.50 ± (0.177 ±			± 0.25 ± 0.010)
MM 2 50 ± 0 20			3.20 ±			6.40			± 0.010) ± 0.25
(vv) Width (in.) $(0.098 \pm 0.008)$			(0.126 ±	0.008)		(0.252 ±	0.016)	(0.250	± 0.010)
(t) Terminal MM (in.) 0.50 ± 0.25 (0.020 ± 0.010)			0.61 ± (0.024 ±			0.61 ± (0.024 ±			± 0.39 ± 0.015)
	00   500	50	100	200	500	50	100	50	100
Cap 100	.00	- 00	100	200	000				100
(pF) 150							1-	<b>&gt;</b>	<b>√</b> W_
220							- < <u>L</u>	<	<b>√</b>
470							( ~		$\coprod$
680							_	<u> </u>	
1000								4 t	
	J M J						ı		1
	J M								<del> </del>
	J M								
	J M	17	17	17	17		.,	.,	5
	J M J P	K K	K K	K	K	M	M	M M	P
	j   Q	K	K	K	P	P M N		M	P
	J	K	K	K			М	М	Р
	J	K	K	K	Ζ	M	M	M	P
	M M	K	K	K		M M	M M	M M	P
0.15 J J J M		K	K	P		M	M	M	P
0.22 J J J P		K	K	Р		M	М	М	P
0.33		K K	M P			M M	M M	M M	P
0.68 M M P X Z		M	Q			M	141	M	P
1.0 N N P X Z		М	X			М		М	Р
1.5 N N Z Z		Z	Z			М		M	X
2.2 Z Z Z Z Z Z 3.3 Z Z Z Z		Z	Z		-+			М	<del>                                     </del>
4.7 Z Z Z Z Z		Z							
10 Z Z Z									
22 Z Z 47									
100									
	00 500	50	100	200	500	50	100	50	100
SIZE LD10	·		LD	12		LD	13	L	D14
Letter A C E G	J	K		M		N P	Q	Х	ΥZ
Max. 0.33 0.56 0.71 0.86	0.94	1.0		1.27		40 1.52	1.78	2.29	2.54 2.79
	(0.037)	(0.04		(0.050)		055) (0.060		(0.090)	(0.100) (0.110)
PAPER				. ,	,	EM	BOSSED	, ,	







## **Capacitance Range (X5R Dielectric)**

## **PREFERRED SIZES ARE SHADED**

											<b>—</b>							11					Ш	_													
SIZE	Ε			LD	002					L	D0	3					LD	05					LD	06					L	_D1	0				LD	12	_
Solderi	ing	Г	R	eflo	nO w	nly				Refle	ow (	Only				Re	flow	/Wa	ve		Г	Re	eflow	/Wa	ve			F	Refle	ow/\	Nave	<del></del>		Г			_
Packag				All F							Pap				F		er/En					Pape				i		Pa		/Eml		ed					_
(L) Length	MM (in.)			1.00					(	1.60 (0.060)	0 ± 0 3 ± 0		)				2.01 ± 079 ±						3.20 <del>-</del> 126 -					(		20 ± 0 26 ± 0		3)					
(W) Width	MM (in.)			0.50					-	0.8	1 ± 0		١				.25 ±						1.60 = 063 =					-		00 ± 0		1					_
(T) Max Thickn	MM		(0)	0.	.60	104)					0.90		<u> </u>			(0.	1.3	30	,0,			(0.	1.	50	50)					1.70	)	')		Н			—
<del></del>	(in.)			0.25	024) ± 0.1	5					0.035 $5 \pm 0$					(	(0.0) 0.50 ±		5		H	C	(0.0		5					0.06				H			—
(t) Terminal	(in.)	Ļ	(0	.010	± 0.0	006)	1 50	Ļ		(0.014	4 ± 0	.006)		l =0	0.0	(0.	020 ±	0.01	0)	50	0.0	(0.	020 -	± 0.0	10)	50	ļ.,		0.02	20 ± 0	0.010	,		0.0	Lol	05.1	
Cap	WVDC 100	4	6.3	10	16	25	50	4	6.3	10	16	25	35	50	6.3	10	16	25	35	50	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50	6.3	10	25	50
(pF)	150																																				
	220		_	_		_	С	L							L						L						<u> </u>	└ '		1	1		ı				
	330 470						C																							_L^		$\geq$	$\leq$	<u> </u>	W-	_	
	680						C																					Ĺ `	<		$\le$	_		$\supset$	)	T	
	1000						С																							<u></u>	_	) ]				_	
	1500 2200						C																									م مبدا	-				
	3300						С																					١.									
	4700 6800					C								G																							
Cap	0.010					С		$\vdash$						G							H																—
(μF)	0.015					С						G	G	G																							
	0.022	L		-	С	С		┢				G	G	G	_					N	L										-			L		_	
	0.033 0.047				С							G G	G	G						N N																	
	0.068				С							G		G						Ν																	
	0.10 0.15			C	С							G G		G				N N	N	Ν																	
	0.15		С	C							G	G						N	N							Q											
	0.33										G	G						N																			_
	0.47 0.68	С	С								G G							N		N				Q	Q								Χ				
	1.0	С	С	С				H	G	G	G	J			$\vdash$		N	N		P*	$\vdash$			Q	Q			$\vdash$			Х	Х	X		$\vdash \vdash$	+	_
	1.5								_							N	N							_													-
	3.3	С				$\vdash$		G	G	J	J		$\vdash$		N	N	N	N		$\vdash$	$\vdash$	Q	Q	Q			$\vdash$			_	Z	X		$\vdash$	$\vdash \vdash$	+	Z
	4.7							G	G						N	N	N	N*				Q	Q	Q						Z	Z						
	10							К							N	Ν	N				Q	Q	Q	Q					Z					L	$\square$	_	
	22 47														N						QQ	Q	Q					Z Z	Z	Z	Z						
	100							L																			Z	Z*								$\perp$	
SIZE	WVDC	4	6.3	_		25	50	4	6.3	10	_	25	35	50	6.3	10	16	25 OF	35	50	6.3	10	16	25	35	50	4	6.3	10	_		35	50	6.3		_	50
SIZE		<u> </u>		LL	002						D0	3					LD	UO					LD	טטי					L	_D1	U			<u> </u>	LD	12	—
Letter	Е			G		J			K			М			N			2		Х			Υ			Z											
Max. Thickness	0.71 (0.028)			86 034)		0.0			1.02 0.04			1.27			1.40 .055	۱ ا	(0.0			2.2			2.5			2.79											
THICKHESS	(0.028)		,	PER		(0.0)	07)	(	0.04	U)	(0	.000	7)	(U	.000	/	(0.0 //BO			(U.U	.090) (0.100) (0.1		J. 1 I	U)													

Letter	E	G	J	K	M	N	Q	Х	Υ	Z
Max.	0.71	0.86	0.94	1.02	1.27	1.40	1.78	2.29	2.54	2.79
Thickness	(0.028)	(0.034)	(0.037)	(0.040)	(0.050)	(0.055)	(0.070)	(0.090)	(0.100)	(0.110)
		PAPER				Е	MBOSSE	D		

= Under Development

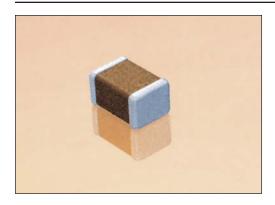
\*Optional Specifications - Contact factory

NOTE: Contact factory for non-specified capacitance values

# **MLCC Low Profile**



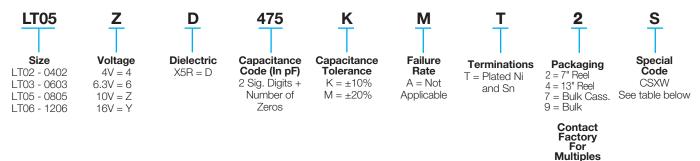
## **General Specifications**



## **GENERAL DESCRIPTION**

AVX introduces the LT series comprising a range of low profile products in our X5R dielectric. X5R is a Class II dielectric with temperature varation of capacitance within  $\pm 15\%$  from  $-55^{\circ}$ C to  $+85^{\circ}$ C. Offerings include 0402, 0603, 0805, and 1206 packages in compact, low profile designs. The LT series is ideal for decoupling and filtering applications where height clearance is limited.

## PART NUMBER (see page 2 for complete part number explanation)



## **CAPACITANCE RANGE (X5R DIELECTRIC)**

5	SIZE	LT02		LT03			LT05		LT06
	WVDC	4	4	6.3	16	6.3	10	16	16
Cap	0.33								
(µF)	0.47								
	0.68								
	1.0	С			S				
	1.5								
	2.2			S					
	3.3								
	4.7		S				S	X	
	10					X	X		W
	22								
	47								
	100								
	WVDC	4	4	6.3	16	6.3	10	16	16
S	SIZE	LT02		LT03			LT05		LT06

## **Special Code Table**

Letter	С	S	Х	W
Max.	0.356	0.56	0.95	1.02
Thickness	(0.014)	(0.022)	(0.038)	(0.040)
		DAE	DED	





## **Automotive MLCC**

## **Automotive**



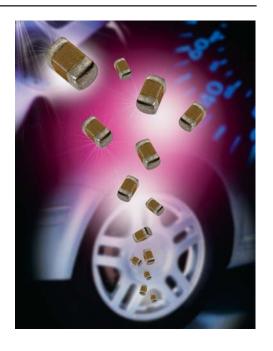
#### GENERAL DESCRIPTION

AVX Corporation has supported the Automotive Industry requirements for Multilayer Ceramic Capacitors consistently for more than 10 years. Products have been developed and tested specifically for automotive applications and all manufacturing facilities are QS9000 and VDA 6.4 approved.

As part of our sustained investment in capacity and state of the art technology, we are now transitioning from the established Pd/Ag electrode system to a Base Metal Electrode system (BME).

AVX is using AECQ200 as the qualification vehicle for this transition. A detailed qualification package is available on request and contains results on a range of part numbers including:

- X7R dielectric components containing BME electrode and copper terminations with a Ni/Sn plated overcoat.
- X7R dielectric components, BME electrode with epoxy finish for conductive glue mounting.
- X7R dielectric components BME electrode and soft terminations with a Ni/Sn plated overcoat.
- NPO dielectric components containing Pd/Ag electrode and silver termination with a Ni/Sn plated overcoat.

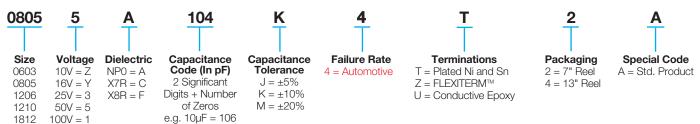


## **HOW TO ORDER**

100V = 1

200V = 2500V = 7

1812



NOTE: Contact factory for non-specified capacitance values.

## COMMERCIAL VS AUTOMOTIVE MLCC PROCESS COMPARISON

	Commercial	Automotive
Administrative	Standard Part Numbers. No restriction on who purchases these parts.	Specific Automotive Part Number. Used to control supply of product to Automotive customers.
Design	Minimum ceramic thickness of 0.020"	Minimum Ceramic thickness of 0.029" (0.74mm) on all X7R product.
Dicing	Side & End Margins = 0.003" min	Side & End Margins = 0.004" min Cover Layers = 0.005" min
Lot Qualification (Destructive Physical Analysis - DPA)	As per EIA RS469	Increased sample plan – stricter criteria.
Visual/Cosmetic Quality	Standard process and inspection	100% inspection
Application Robustness	Standard sampling for accelerated wave solder on X7R dielectrics	Increased sampling for accelerated wave solder on X7R and NP0 followed by lot by lot reliability testing.

All Tests have Accept/Reject Criteria 0/1



### **Automotive MLCC**

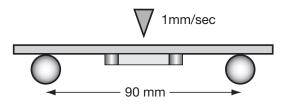
### **NP0/X7R Dielectric**



### **FLEXITERM™ FEATURES**

a) Bend Test

The capacitor is soldered to the PC Board as shown:



Typical bend test results are shown below:

Style	Conventional Term	Soft Term
0603	>2mm	>5
0805	>2mm	>5
1206	>2mm	>5

b) Temperature Cycle testing "Soft Termination" has the ability to withstand at least 1000 cycles between -55°C and +125°C

### **ELECTRODE AND TERMINATION OPTIONS**

### **NPO DIELECTRIC**

NP0 Ag/Pd Electrode Nickel Barrier Termination PCB Application

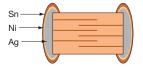


Figure 1 Termination Code T

### X7R DIELECTRIC

# X7R Dielectric PCB Application

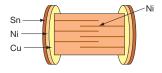


Figure 2 Termination Code T

### X7R Nickel Electrode Soft Termination PCB Application

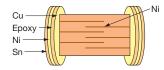


Figure 3 Termination Code Z

### Conductive Epoxy Termination Hybrid Application

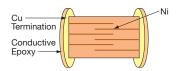


Figure 4 Termination Code U



# **Automotive MLCC - NP0**



### **Capacitance Range**

		04	02		0603			0805				1206				12	210		18	312
		25V	50V	25V	50V	100V	25V	50V	100V	25V	50V	100V	200V	500V	25V	50V	100V	200V	50V	100V
100	10pF	С	С	G	G	G	J	J	J	J	J	J	J	J						
120	12	С	С	G	G	G	J	J	J	J	J	J	J	J						
150	15	С	С	G	G	G	J	J	J	J	J	J	J	J						
180	18	С	С	G	G	G	J	J	J	J	J	J								
220	22	С	С	G	G	G	J	J	J	J	J	J								
270	27	С	С	G	G	G	J	J	J	J	J	J								
330	33	С	С	G	G	G	J	J	J	J	J	J								
390	39	С	С	G	G	G	J	J	J	J	J	J								
470	47	С	С	G	G	G	J	J	J	J	J	J								
510	51	С	С	G	G	G	J	J	J	J	J	J								
560	56	С	С	G	G	G	J	J	J	J	J	J								
680	68	С	С	G	G	G	J	J	J	J	J	J								
820	82	С	С	G	G	G	J	J	J	J	J	J								
101	100	С	С	G	G	G	J	J	J	J	J	J								
121	120			G	G	G	J	J	J	J	J	J								
151	150			G	G	G	J	J	J	J	J	J								
181	180			G	G	G	J	J	J	J	J	J								
221	220			G	G	G	J	J	J	J	J	J								
271	270			G	G	G	٦	J	J	J	J	J								
331	330			G	G	G	J	J	J	J	J	J								
391	390			G	G		J	J	J	J	J	J								
471	470			G	G		J	J	J	J	J	J								
561	560						J	J	J	J	J	J								
681	680						J	J	J	J	J	J								
821	820						J	J	J	J	J	J								
102	1000						J	J	J	J	J	J			J	J	J	J		
122	1200									J	J	J			J	J	М	М		
152	1500									J	М	М			J	J	М	М		
182	1800									J	М	М			J	J	М	М		
222	2200									J	M	М			J	J	М	М		
272	2700									J	М	Q			J	J	М			
332	3300									J	М	Q			J	J	Р		K	K
392	3900														J	J	Р		K	K
472	4700														J	J	Р		K	K
103	10nF																			
		25V	50V	25V	50V	100V	25V	50V	100V	25V	50V	100V	200V	500V	25V	50V	100V	200V	50V	100V
		04	02	0603 080								1206				12	210		18	12

Letter	Α	С	E	G	J	K	M	N	P	Q	X	Υ	Z
Max.	0.33	0.56	0.71	0.86	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.034)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBC	SSED			

# **Automotive MLCC - X7R**



## Capacitance Range

					0603	}				0805	5				12	206				12	210		18	12	2220
			16V	25V	50V	100V	200V	16V	25V	50V	100V	200V	16V	25V	50V	100V	200V	500V	16V	25V	50V	100V	50V	100V	50V
102	Cap	1	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	Κ	K	
182	(nF)	1.8	G	G	G	G		J	J	J	J	J	J	J	J	J	J		K	K	K	K	K	K	
222		2.2	G	G	G	G		J	J	J	J	J	J	J	J	J	J		K	K	K	K	K	K	
332		3.3	G	G	G	G		J	J	J	J	J	J	J	J	J	J		K	K	K	K	K	K	
472		4.7	G	G	G	G		J	J	J	J	J	J	J	J	J	J		K	K	K	K	K	K	
103		10	G	G	G	G		J	J	J	J	J	J	J	J	J			K	K	K	K	K	K	
123		12	G	G	G			J	J	J	M		J	J	J	J			K	K	K	K	K	K	
153		15	G	G	G			J	J	J	М		J	J	J	J			K	K	K	K	K	K	$\Box$
183		18	G	G	G			J	J	J	М		J	J	J	J			K	K	K	K	K	K	
223		22	G	G	G			J	J	J	М		J	J	J	J			K	K	K	K	K	K	
273		27	G	G	G			J	J	J	М		J	J	J	J			K	K	K	K	K	K	
333		33	G	G	G			J	J	J	M		J	J	J	J			K	K	K	K	K	K	-
473	ı	47	G	G	G			J	J	J	М		J	J	J	M			K	K	K	K	K	K	_
563		56 68	G	G	G			J	J	J	M		J	J	J	M			K	K	K	M	K	K	_
683 823		82	G	G	G	_		J	J	J	M		J	J	J	M			K	K	K	M	K	K	_
104		00	G	G	G		-	J	J	J	M		J	J	J	M	-		K	K	K	M	K	K	-
124		20	G	G	G	-	_	J	J	M	IVI		J	J	M	M	-		K		K	P	K	K	-
154		150	_		+		_	M	N	M		-	J	J	M	M	_		K	K	K	P	K	K	-
224		220						M	N	M	-		J	M	M	Q	-		M	M	M	P	M	M	-
334		330						N	N	M	_		J	M	P	Q	_		P	P	P	Q	X	X	-
474		170						N	N	M			M	M	P	- Q			P	P	P	Q	X	X	-
684		880						N	N				M	Q	Q				P	P	Q	X	X	X	
105	Cap	1						N	N				М	Q	Q				P	Q	Q	X	X	X	
155		1.5											Q	Q					P	ā	Z		X	X	
225		2.2											Q	Q					X	Z	Z		Z	Z	
335		3.3																	Х	Z	Z		Z		
475	١.	4.7																	Χ	Z	Z		Z		
106		10																							Z
			16V	25V	50V	100V	200V	16V	25V	50V	100V	200V	16V	25V	50V	100V	200V	500V	16V	25V	50V	100V	50V	100V	50V
					0603					0805					12	06				12	10		18	12	2220
	tter		Α		С		Е		G		J		K		М		N		Р		Q		Χ		Υ
	ax.		0.33		0.56		0.71		0.86		0.94		1.02		1.27		1.40		1.52		1.78		2.29		2.54
Thic	kness	(	0.013	)	(0.022)	) (	(0.028)	) (	0.034	) (	(0.037)	)	(0.040)	) ((	0.050)	((	0.055)	(C	.060)	(0	.070)	(0	.090)	(0	.100)
						В	APE	5								_			EMD	ossi	ED				

# **Automotive MLCC - X8R**



### **Capacitance Range**

	SIZ	E			0603				08	05			1206	
		WVDC	:	25V		50V		2	25V	50V		25V	5	OV
271	C	ap 270		G		G								
331	(p			G		G			J	J				
471		470		G		G			J	J				
681		680		G		G			J	J				
102		1000		G		G			J	J		J		J
152		1500		G		G			J	J		J		J
182		1800		G		G			J	J		J		J
222		2200		G		G			J	J		J		J
272		2700		G		G			J	J		J		J
332		3300		G		G			J	J		J		J
392		3900		G		G			J	J		J		J
472		4700		G		G			J	J		J		J
562		5600		G		G			J	J		J		J
682		6800		G		G			J	J		J		J
822		8200		G		G			J	J		J		J
103		ap 0.01		G		G			J	J		J		J
123	(μ			G		G			J	J		J		J
153		0.015		G		G			J	J		J		J
183		0.018		G		G			J	J		J		J
223		0.022		G		G			J	J		J		J
273		0.027		G		G			J	J		J		J
333		0.033		G		G			J	J		J		J
393		0.039		G		G			J	J		J		J
473		0.047		G		G			J	J		J		J
563		0.056		G					N	N		M		M
683		0.068		G					N	N		M		M
823		0.082		G					N	N		М		M
104		0.1		G					N	N		M		M
124		0.12		G					N	N		M		M
154		0.15							N	N		M		M
184		0.18		1					N			M		M
224		0.22							N			M		M
274		0.27							N			M		M
334		0.33							N			M		M
394		0.39		1					N			M		
474		0.47		1					N			M		
684		0.68		1								M		
824		0.82												
105		1		051		FOV.			) (T) (	501/		051/	-	0) /
		WVDC		25V		50V		- '2	25V	50V		25V		OV
	SIZE				0603	}			30	805			1206	
Letter	Α	С	Е	G	J	K		М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.86	0.94	1.02		1.27	1.40	1.52	1.78	3 2.29	2.54	<b>Z</b> 2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.034)	(0.037)	(0.040)		0.050)	(0.055)	(0.060)	(0.07		(0.100)	(0.110)
11110111033	(0.010)	(0.022)	(0.020)	(0.004)	(0.007)	(0.040)	10	0.000)	(0.000)	(0.000)	(0.07	(0.030)	(0.100)	(0.110)

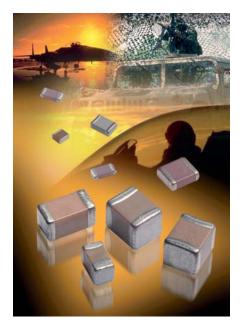


EMBOSSED

### **APS Series**

### **APS for COTS+ Applications**





#### **GENERAL DESCRIPTION**

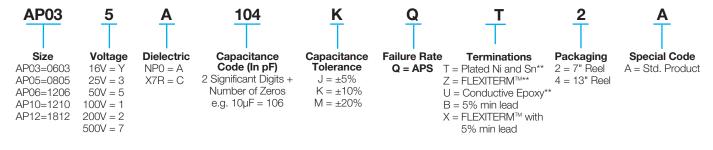
As part of our continuing support to high reliability customers, AVX has launched an Automotive Plus Series of parts (APS) qualified and manufactured in accordance with automotive AEC-Q200 standard. Each production batch is quality tested to an enhanced requirement and shipped with a certificate of conformance. On a quarterly basis a reliability package is issued to all APS customers.

A detailed qualification package is available on request and contains results on a range of part numbers including:

- X7R dielectric components containing BME electrode and copper terminations with a Ni/Sn plated overcoat.
- X7R dielectric components BME electrode and soft terminations with a Ni/Sn plated overcoat (FLEXITERM™).
- X7R for Hybrid applications.
- NP0 dielectric components containing Pd/Ag electrode and silver termination with a Ni/Sn plated overcoat.

We are also able to support customers who require an AEC-Q200 grade component finished with Tin/Lead.

### **HOW TO ORDER**



\*\*RoHS compliant

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.



# **NP0 Automotive Plus Series / APS**



### **Capacitance Range**

			0603			0805				1206				1	210		18	312
		25V	50V	100V	25V	50V	100V	25V	50V	100V	200V	500V	25V	50V	100V	200V	50V	100V
100	10pF	G	G	G	J	J	J	J	J	J	J	J						
120	12	G	G	G	J	J	J	J	J	J	J	J						
150	15	G	G	G	J	J	7	J	J	J	J	J						
180	18	G	G	G	J	J	J	J	J	J								
220	22	G	G	G	J	J	J	J	J	J								
270	27	G	G	G	J	J	J	J	J	J								
330	33	G	G	G	J	J	J	J	J	J								
390	39	G	G	G	J	J	J	J	J	J								
470	47	G	G	G	J	J	J	J	J	J								
510	51	G	G	G	J	J	J	J	J	J								
560	56	G	G	G	J	J	J	J	J	J								
680	68	G	G	G	J	J	J	J	J	J								
820	82	G	G	G	J	J	J	J	J	J								
101	100	G	G	G	J	J	J	J	J	J								
121	120	G	G	G	J	J	J	J	J	J								
151	150	G	G	G	J	J	J	J	J	J								
181	180	G	G	G	J	J	J	J	J	J								
221	220	G	G	G	J	J	J	J	J	J								
271	270	G	G	G	J	J	J	J	J	J								
331	330	G	G	G	J	J	J	J	J	J								
391	390 470	G G	G G	-	J	J	J	J	J	J			-					
471 561	560	G	G		J	J	J	J	J	J				-				
681	680				J	J	J	J	J	J				-				
821	820				J	J	J	J	J	J								
102	1000				J	J	J	J	J	J			J	J	J	J		
122	1200				J	J	U	J	J	J			J	J	M	M	<del>                                     </del>	
152	1500				+	<b>+</b>		J	M	M			J	J	M	M		
182	1800				1	1		J	M	M			J	J	M	M	<del>                                     </del>	
222	2200				1	<del>                                     </del>		J	M	M			J	J	M	M		<u> </u>
272	2700				<b>†</b>	1		J	M	Q			J	J	M		<b> </b>	
332	3300				1	<u> </u>		J	M	Q			J	J	P		K	K
392	3900				1	t							J	J	P		K	K
472	4700				1								J	J	P		K	K
103	10nF				1													
		25V	50V	100V	25V	50V	100V	25V	50V	100V	200V	500V	25V	50V	100V	200V	50V	100V
			0603			0805				1206	•			1	210		18	12
					-	•			V				'	•	V	V	' -	, ,
Let		A	C		E	G	J		K	M	N 1 10	P		Q	X	Y	Z	
Ma		0.33	0.5		0.71	0.86	0.94		.02	1.27	1.40	1.52		.78	2.29	2.54	2.7	
Thick	ness	(0.013)	(0.02		0.028)	(0.034)	(0.037	) (0.	040)	(0.050)	(0.055)	(0.06	/ \	.070)	(0.090)	(0.100)	(0.1	10)
				P	APER							EN	IBOSSE	D				

AEC-Q200 qualified TS 16949, ISO 9001 certified



# **X7R Automotive Plus Series / APS**



### **Capacitance Range**

					0603	}				0805	5				12	206				12	210		18	12	2220
			16V	25V	50V	100V	200V	16V	25V	50V	100V	200V	16V	25V	50V	100V	200V	500V	16V	25V	50V	100V	50V	100V	50V
102	Cap	1	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	K	K	
182	(nF)	1.8	G	G	G	G		J	J	J	J	J	J	J	J	J	J		K	K	K	K	K	K	
222		2.2	G	G	G	G		J	J	J	J	J	J	J	J	J	J		K	K	K	K	K	K	
332		3.3	G	G	G	G		J	J	J	J	J	J	J	J	J	J		K	K	K	K	K	K	
472		4.7	G	G	G	G		J	J	J	J	J	J	J	J	J	J		K	K	K	K	K	K	
103		10	G	G	G	G		J	J	J	J	J	J	J	J	J			K	K	K	K	K	K	
123		12	G	G	G			J	J	J	М		J	J	J	J			K	K	K	K	K	K	
153		15	G	G	G			J	J	J	М		J	J	J	J			K	K	K	K	K	K	
183		18	G	G	G			J	J	J	М		J	J	J	J			K	K	K	K	K	K	
223		22	G	G	G			J	J	J	М		J	J	J	J			K	K	K	K	K	K	$\Box$
273		27	G	G	G			J	J	J	М		J	J	J	J			K	K	K	K	K	K	
333		33	G	G	G			J	J	J	М		J	J	J	J			K	K	K	K	K	K	$\perp$
473		47	G	G	G			J	J	J	М		J	J	J	М			K	K	K	K	K	K	
563		56	G	G	G			J	J	J	М		J	J	J	М			K	K	K	M	K	K	
683		68	G	G	G			J	J	J	М		J	J	J	М			K	K	K	М	K	K	
823		82	G	G	G			J	J	J	М		J	J	J	М			K	K	K	M	K	K	$\perp$
104		100	G	G	G			J	J	М	М		J	J	J	М			K	K	K	М	K	K	$\square$
124		120	_					J	J	М			J	J	М	М			K	K	K	Р	K	K	$\perp$
154		150						М	N	М			J	J	М	M			K	K	K	Р	K	K	$\square$
224		220						М	N	М			J	M	M	Q			М	M	M	P	М	M	$\Box$
334		330						N	N	М			J	М	Р	Q			Р	Р	P	Q	X	X	$\square$
474 684		470 680	-					N	N	М			М	M	P				P	P		Q	X	X	$\vdash$
	Car		<b>!</b>		_			N	N	_			M	Q	Q	_					Q	X	X	X	
105	Cap	1	₩		_	_	-	N	N	_			M	Q	Q	<u> </u>	-	-	P	Q	Q	Х	X	X	_
155 225	(µF)	1.5	├					_		_			Q	Q					_	Q 7	Z 7		X 7	X 7	
			-					_			_		Q	Q		_			X						
335 475		3.3 4.7	1		-		-						<u> </u>		-		-	-	X	Z	Z		Z		$\vdash$
106		10			-	-	-	<u> </u>	-	_	-	-	⊢	-	-	-	-	-	Α.					-	Z
106		10	16V	25V	50V	100V	200V	16V	25V	50V	100V	2001/	16V	25V	50V	100V	200V	5001/	16V	25V	50V	100V	50V	100V	50V
			VOI			IUUV	12000	ΙΟV			ΙΟΟΛ	200V	100	20V			ZUUV	JUUV	IOV			ΠΟΟΛ			
					0603					0805					12	U6				12	10		18	12	2220
Le	tter		Α		С		Е		G		J		K		М		N		Р		Q		Х		Υ
М	ax.		0.33		0.56		0.71		0.86		0.94		1.02		1.27		1.40		1.52	-	1.78	1	2.29	7	2.54
Thic		s	(0.013	)	(0.022	)	(0.028)	) (	0.034	) (	0.037	) (	0.040	) (	0.050)		0.055)		.060)		.070)		).090)		.100)
			,,		,		APE											1 (-	,	OSSI		, (0	/	1 ,0	,
						F	APE	1												USSI	בט				

AEC-Q200 qualified TS 16949, ISO 9001 certified





### **General Specifications**



### **GENERAL DESCRIPTION**

With increased requirements from the automotive industry for additional component robustness, AVX recognized the need to produce a MLCC with enhanced mechanical strength. It was noted that many components may be subject to severe flexing and vibration when used in various under the hood automotive and other harsh environment applications.

To satisfy the requirement for enhanced mechanical strength, AVX had to find a way of ensuring electrical integrity is maintained whilst external forces are being applied to the component. It was found that the structure of the termination needed to be flexible and after much research and development, AVX launched FLEXITERM™. FLEXITERM™ is designed to enhance the mechanical flexure and temperature cycling performance of a standard ceramic capacitor with an X7R dielectric. The industry standard for flexure is 2mm minimum. Using FLEXITERM™, AVX provides up to 5mm of flexure without internal cracks. Beyond 5mm, the capacitor will generally fail "open".

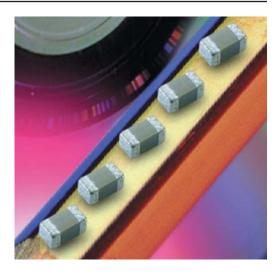
As well as for automotive applications FLEXITERM™ will provide Design Engineers with a satisfactory solution when designing PCB's which may be subject to high levels of board flexure.

### **PRODUCT ADVANTAGES**

- High mechanical performance able to withstand, 5mm bend test guaranteed.
- Increased temperature cycling performance, 3000 cycles and beyond.
- Flexible termination system.
- Reduction in circuit board flex failures.
- Base metal electrode system.

2 = 200V

• Automotive or commercial grade products available.



### **APPLICATIONS**

#### **High Flexure Stress Circuit Boards**

• e.g. Depanelization: Components near edges of board.

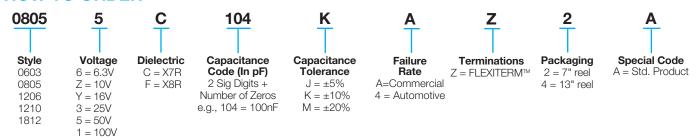
#### **Variable Temperature Applications**

- Soft termination offers improved reliability performance in applications where there is temperature variation.
- e.g. All kind of engine sensors: Direct connection to battery rail.

#### **Automotive Applications**

- Improved reliability.
- Excellent mechanical performance and thermo mechanical performance.

### **HOW TO ORDER**



NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers.



### **Specifications and Test Methods**



### **PERFORMANCE TESTING**

#### **AEC-Q200 Qualification:**

• Created by the Automotive Electronics Council

• Specification defining stress test qualification for passive components

#### Testing:

Key tests used to compare soft termination to

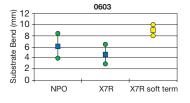
AEC-Q200 qualification:

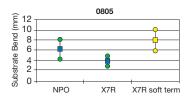
- Bend Test
- Temperature Cycle Test

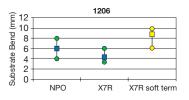


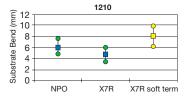
### **BOARD BEND TEST RESULTS**

AEC-Q200 Vrs AVX FLEXITERM™ Bend Test









### **TABLE SUMMARY**

Typical bend test results are shown below:

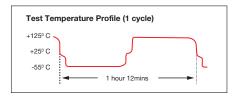
Style	Conventional Termination	FLEXITERM
0603	>2mm	>5mm
0805	>2mm	>5mm
1206	>2mm	>5mm

### TEMPERATURE CYCLE TEST PROCEDURE

### Test Procedure as per AEC-Q200:

The test is conducted to determine the resistance of the component when it is exposed to extremes of alternating high and low temperatures.

- Sample lot size quantity 77 pieces
- TC chamber cycle from -55°C to +125°C for 1000 cycles
- Interim electrical measurements at 250, 500, 1000 cycles
- Measure parameter capacitance dissipation factor. insulation resistance



### **BOARD BEND TEST PROCEDURE**

According to AEC-Q200

Test Procedure as per AEC-Q200: Sample size: 20 components Span: 90mm Minimum deflection spec: 2 mm

- Components soldered onto FR4 PCB (Figure 1)
- Board connected electrically to the test equipment (Figure 2)

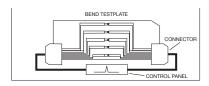


Fig 2 - Board Bend test

Fig 1 - PCB layout with electrical connections

equipment

विभिन्न

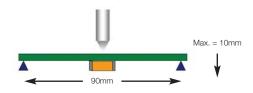
MOUNTING ASSEMBLY

CONTROL

### **AVX ENHANCED SOFT TERMINATION BEND TEST PROCEDURE**

#### **Bend Test**

The capacitor is soldered to the printed circuit board as shown and is bent up to 10mm at 1mm per second:



- The board is placed on 2 supports 90mm apart (capacitor side down)
- The row of capacitors is aligned with the load stressing knife



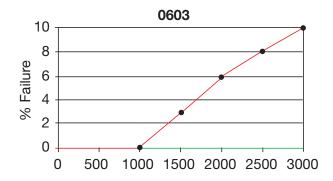
- The load is applied and the deflection where the part starts to crack is recorded (Note: Equipment detects the start of the crack using a highly sensitive current detection
- The maximum deflection capability is 10mm

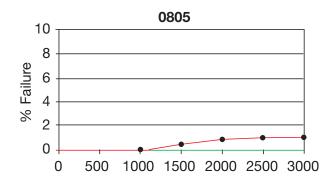


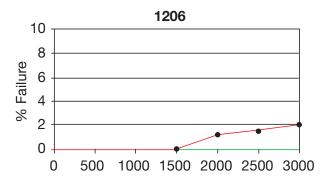
# **Specifications and Test Methods**

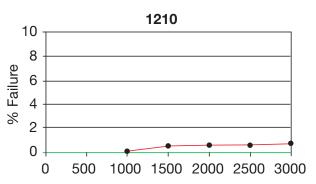


### **BEYOND 1000 CYCLES: TEMPERATURE CYCLE TEST RESULTS**









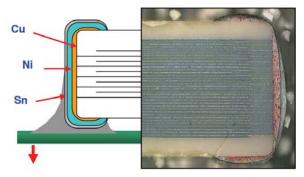
Soft Term - No Defects up to 3000 cycles

AEC-Q200 specification states 1000 cycles compared to AVX 3000 temperature cycles.

### FLEXITERM™ TEST SUMMARY

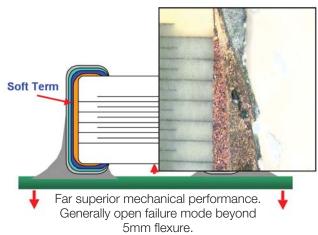
- Qualified to AEC-Q200 test/specification with the exception of using AVX 3000 temperature cycles (up to +150°C bend test guaranteed greater than 5mm).
- FLEXITERM™ provides improved performance compared to standard termination systems.
- Board bend test improvement by a factor of 2 to 4 times.
- Temperature Cycling:
  - 0% Failure up to 3000 cycles
    - No ESR change up to 3000 cycles

### WITHOUT SOFT TERMINATION



Major fear is of latent board flex failures.

### WITH SOFT TERMINATION







### X8R Dielectric Capacitance Range

WDC		SIZE			0603				08	05			1	206	
331		WVDC		25V		50V		2	25V	50V		25V		50	)V
471         470         G         G         G         J         J         J         G         G         J <td>271</td> <td>Cap 270</td> <td></td> <td>G</td> <td></td> <td>G</td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td>	271	Cap 270		G		G									
681	331	(pF) 330		G		G			J	J					
102	471			G		G			J	J					
152	681	680		G					J	J					
182	102	1000		G		G	$\equiv$		J	J		J			J
222	152	1500		G		G	$\equiv$		J	J		J			J
2772	182	1800		G		G			J	J		J			J
332   3300   G   G   G   J   J   J   J   J   J   J	222			G		G			J	J		J			J
392   3900   G   G   G   J   J   J   J   J   J   J									J	J		J			J
A72	332	3300		G		G			J	J		J			J
S62	392								J	J		J			J
682         6800         G         G         J <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td>J</td> <td>J</td> <td></td> <td>J</td> <td></td> <td></td> <td>J</td>									J	J		J			J
Record   R															
103									J						J
123															
153         0.015         G         G         J         N         N </td <td></td>															
183         0.018         G         G         J         N         N </td <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td>J</td> <td>J</td> <td></td> <td></td> <td></td> <td></td> <td>J</td>									J	J					J
223         0.022         G         G         J         N         N         N </td <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td>J</td> <td>J</td> <td></td> <td>J</td> <td></td> <td></td> <td>J</td>									J	J		J			J
273         0.027         G         G         J         N         N         N </td <td></td> <td>0.018</td> <td></td> <td>J</td>		0.018													J
333   0.033   G   G   J   J   J   J   J   J   J   J									J	J					J
393   0.039   G   G   J   J   J   J   J   J   J   J															J
473         0.047         G         G         J         J         J         J           563         0.056         G         N         N         N         M         <															
563         0.056         G         N         N         M         M           683         0.068         G         N         N         M         M         M           823         0.082         G         N         N         N         M         M         M           104         0.1         G         N         N         N         M															
683         0.068         G         N         N         M         M           823         0.082         G         N         N         M         M         M           104         0.1         G         N         N         M         M         M           124         0.12         G         N         N         M         M         M           154         0.15         N         N         N         M<						G									
823         0.082         G         N         N         M         M           104         0.1         G         N         N         M         M         M           124         0.12         G         N         N         N         M         M         M           154         0.15         N         N         N         M															
104															
124															
154															
184     0.18     N     M     M       224     0.22     N     M     M     M       274     0.27     N     M     M     M       334     0.33     N     M     M     M       394     0.39     N     M     M       474     0.47     N     M     M       684     0.68     M     M       824     0.82     M				G											
224         0.22         N         M         M           274         0.27         N         M         M         M           334         0.33         N         M         M         M           394         0.39         N         M         M         M           474         0.47         N         M         M         M           684         0.68         M         M         M         M           824         0.82         M										N					
274         0.27         N         M         M           334         0.33         N         M         M           394         0.39         N         M         M           474         0.47         N         M         M           684         0.68         M         M         M           824         0.82         M         M         M															
334         0.33         N         M         M           394         0.39         N         M         M           474         0.47         N         M         M           684         0.68         M         M           824         0.82         M         M		0.22										M			
394 0.39 N M M 6474 0.47 N M M 684 0.68 M M 6824 0.82															
474 0.47 N M 684 0.68 M M														l N	Л
684 0.68 M															
824 0.82									N						
												M			
		0.82													
105 1	105					5017		ļ				05):		L	
WVDC 25V 50V 25V 50V 25V 50V	<u> </u>		)	25V			_	2				25V			)V
SIZE 0603 0805 1206		SIZE			0603	<b>B</b>			80	305			12	06	
Letter A C E G J K M N P Q X Y															Z
Max. 0.33 0.56 0.71 0.86 0.94 1.02 1.27 1.40 1.52 1.78 2.29 2.54	Max.	0.33 0.56	0.71	0.86	0.94	1.02		1.27	1.40	1.52	1.78	3 2.29	9	2.54	2.79
Thickness (0.013) (0.022) (0.028) (0.034) (0.037) (0.040) (0.050) (0.055) (0.060) (0.070) (0.090) (0.100)	Thickness		(0.028)		(0.037)	(0.040)	(C	0.050)	(0.055)	(0.060)	(0.07	0.09	90)	(0.100)	(0.110)
PAPER EMBOSSED		(2.2)	, ,	, , , , ,	(/	()	,,,,	/	(/	, ,	,	, (		/	()

= AEC-Q200 Qualified = Under development (Contact factory for advanced samples)





### X7R Dielectric Capacitance Range

			0603					08	05					1206				12	10			18	12	
	16V	25V	50V	100V	200V	10V	16V	25V	50V	100V	200V	16V	25V	50V	100V	200V	16V	25V	50V	100V	16V	25V	50V	100V
101																								
121																								
151 181	-	-				-					-													
221											<del>                                     </del>						_				_			_
271	J	J	J	J	J	J																		
331	J	J	J	J	J	J	J	J	J	J	J													
391	J	J	J	J	J	J	J	J	J	J	J													
471	J	J	J	J	J	J	J	J	J	J	J													
561 681	J	J	J	J	J	J	J	J J	J	J	J													
821	J	J	J	J	J	J	J	J	J	J	J													<del>                                     </del>
102	J	J	J	J	J	J	J	J	J	J	J	J	J	J	J	J								
122	J	J	J	J		J	J	J	J	J	J	J	J	J	J	J								
152	J	J	J	J		J	J	J	J	J	J	J	J	J	J	J								
182	J	J	J	J		J	J	J	J	J	J	J	J	J	J	J	_							—
222 272	J	J	J	J		J	J	J	J	J	J	J	J	J	J	J	<b>—</b>		_					<del></del>
332	J	J	J	J		J	J	J	J	J	J.	J	,l	J	J	J					_			<del>                                     </del>
392	J	J	J	J		J	J	J	J	J	J	J	J	J	J	J								$\vdash$
472	J	J	J	J		J	J	J	J	J	J	J	J	J	J	J								
562	J	J	J	J		J	J	J	J	J	J	J	J	J	J	J								
682	J	J	J	J		J	J	J	J	J	J	J	J	J	J	J								
822	J	J	J	J		J	J	J	J	J	J	J	J	J	J	J								
103 123	J	J	J	J		J	J	J	J	J M	J	J	J	J	J	J								-
153	J	J	J.			J	.l	J.J	J	M		.l	J	J	J									
183	J	J	J			J	J	J	J	M		J	J	J	J									
223	J	J	J			J	J	J	J	М		J	J	J	J					K				
273	J	J	J			J	J	J	J	М		J	J	J	J					K				
333	J	J	J			J	J	J	J	М		J	J	J	J					K				<u> </u>
393 473	J	J	J			J	J J	J	J	M M		J	J	J	M M					K K				
563	J	J	J			J	J	J	J	N		J	J	J	M		K	K	K	M	K	K	K	K
683	J	J	J			J	J	J	J	N		J	J	J	M		K	K	K	M	K	K	K	K
823	J	J	J			J	J	J	J	N		J	J	J	Р		K	K	K	М	K	K	K	K
104	J	J	J			J	J	J	J	N		J	J	J	Q		K	K	K	Р	K	K	K	K
124						J	J	J	N		-	J	J	Р	Q		K	K	K	Q	K	K	K	K
154 184	_					M M	M M	N N	N N		-	J	J M	P	Q Q		K M	K M	K M	Q Q	K K	K	K K	M
224		M*				M	M	N	N			J	M	P	Q		M	M	M	Q	M	M	M	X
274						N	N	N	N		<u> </u>	J	M	P	Q		P	P	P	Q	M	M	M	X
334						N	N	N	N			J	М	Р	Q		Р	Р	Р	Q	М	М	М	X
394						N	N	N	N			М	М	Р			Р	Р	Р	Q	Χ	Χ	Χ	Х
474						N	N	N	N			М	M	Р			Р	Р	Р	Q	Х	X	Х	X
564 684	_					N N	N N	N N				M M	Q Q	Q Q			P P	Q X	Q X	Q	X	X	X	Z
824	$\vdash$			_		N	N	N N				M	Q	Q			P	7	Z	Z	X	X	X	7
105						N	N	N			_	M	Q	Q			Р	Z	Z	Z	X	X	X	Z
155												Q	Q				P	Z	Z				Z	Z
185												Q	Q				Z	Z	Z				Z	Z
225												Q	Q				Z	Z	Z				Z	Z
335	-	-	-		-	<u> </u>							_	-	-	-	Z	Z	Z				Z	
475 106	-				_	<u> </u>						_					Z		Z		<u> </u>		Z	-
226												$\vdash$					$\vdash$				$\vdash$			$\vdash$
	16V	25V	50V	100V	200V	10V	16V	25V	50V	100V	200V	16V	25V	50V	100V	200V	16V	25V	50V	100V	16V	25V	50V	100V
			0603					08						1206				12				18		
	_					_											_						-	
Letter		Α	С		Е	0	1	J		K	M		N	P		Q		(	Υ		Z			

1.40 (0.055) 2.79 0.33 0.56 0.71 0.86 0.94 1.02 1.27 1.78 2.29 2.54 Max. 1.52 (0.060)PAPER **EMBOSSED** 

= Under Development

 $^*$ Optional Specifications – Contact factory

NOTE: Contact factory for non-specified capacitance values

### **Capacitor Array (IPC)**



# BENEFITS OF USING CAPACITOR ARRAYS

AVX capacitor arrays offer designers the opportunity to lower placement costs, increase assembly line output through lower component count per board and to reduce real estate requirements.

#### **Reduced Costs**

Placement costs are greatly reduced by effectively placing one device instead of four or two. This results in increased throughput and translates into savings on machine time. Inventory levels are lowered and further savings are made on solder materials, etc.

#### **Space Saving**

Space savings can be quite dramatic when compared to the use of discrete chip capacitors. As an example, the 0508 4-element array offers a space reduction of >40% vs. 4 x 0402 discrete capacitors and of >70% vs. 4 x 0603 discrete capacitors. (This calculation is dependent on the spacing of the discrete components.)

#### **Increased Throughput**

Assuming that there are 220 passive components placed in a mobile phone:

A reduction in the passive count to 200 (by replacing discrete components with arrays) results in an increase in throughput of approximately 9%.

A reduction of 40 placements increases throughput by 18%.

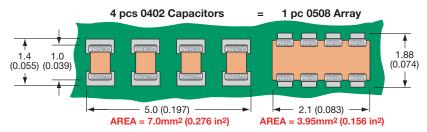
For high volume users of cap arrays using the very latest placement equipment capable of placing 10 components per second, the increase in throughput can be very significant and can have the overall effect of reducing the number of placement machines required to mount components:

If 120 million 2-element arrays or 40 million 4-element arrays were placed in a year, the requirement for placement equipment would be reduced by one machine.

During a 20Hr operational day a machine places 720K components. Over a working year of 167 days the machine can place approximately 120 million. If 2-element arrays are mounted instead of discrete components, then the number of placements is reduced by a factor of two and in the scenario where 120 million 2-element arrays are placed there is a saving of one pick and place machine.

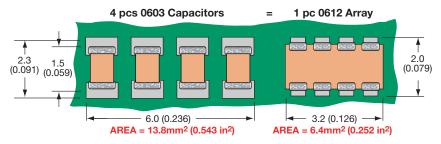
Smaller volume users can also benefit from replacing discrete components with arrays. The total number of placements is reduced thus creating spare capacity on placement machines. This in turn generates the opportunity to increase overall production output without further investment in new equipment.

### W2A (0508) Capacitor Arrays



The 0508 4-element capacitor array gives a PCB space saving of over 40% vs four 0402 discretes and over 70% vs four 0603 discrete capacitors.

#### W3A (0612) Capacitor Arrays

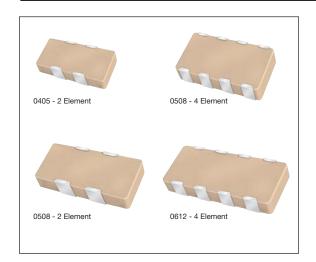


The 0612 4-element capacitor array gives a PCB space saving of over 50% vs four 0603 discretes and over 70% vs four 0805 discrete capacitors.









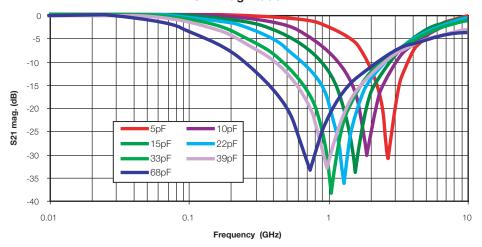
#### **GENERAL DESCRIPTION**

AVX is the market leader in the development and manufacture of capacitor arrays. The smallest array option available from AVX, the 0405 2-element device, has been an enormous success in the Telecommunications market. The array family of products also includes the 0612 4-element device as well as 0508 2-element and 4-element series, all of which have received widespread acceptance in the marketplace.

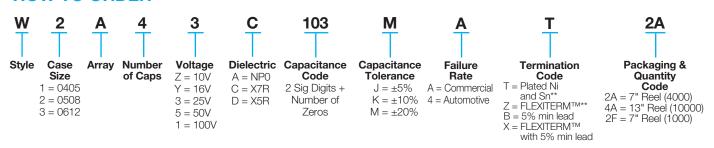
AVX capacitor arrays are available in X5R, X7R and NPO (COG) ceramic dielectrics to cover a broad range of capacitance values. Voltage ratings from 6.3 Volts up to 100 Volts are offered. AVX also now offers a range of automotive capacitor arrays qualified to AEC-Q200 (see separate table).

Key markets for capacitor arrays are Mobile and Cordless Phones, Digital Set Top Boxes, Computer Motherboards and Peripherals as well as Automotive applications, RF Modems, Networking Products, etc.

### AVX Capacitor Array - W2A41A\*\*\*K S21 Magnitude



### **HOW TO ORDER**



\*\*RoHS compliant

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.





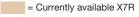
### Capacitance Range - NP0/C0G

S	SIZE		0405			05	08			050	08			06	612	
	ements		2			2				4					4	
	ldering	R	eflow Only	/		Reflow	Wave		1	Reflow	Wave			Reflov	v/Wave	,
Pac	ckaging	,	All Paper			All Pa	aper		Pa	per/En	nbosse	b	F	aper/E	mboss	ed
Length	MM (in.)		.00 ± 0.15 039 ± 0.00				± 0.15 ± 0.006	5)		1.30 ± .051 ±	0.15 0.006)			1.60 ± (0.063	± 0.150 ± 0.00	
Width	MM (in.)		.37 ± 0.15 054 ± 0.00				± 0.15 ± 0.006	5)		2.10 ± .083 ±	0.15 0.006)			3.20 (0.126	± 0.20 ± 0.00	
Max.	MM		0.66				94			0.9					.35	
Thicknes	ss (in.) WVDC	40	(0.026)		10	_	037)	400	40	(0.0		1 400	10		053)	100
1R0	Cap 1.0	16	25	50	16	25	50	100	16	25	50	100	16	25	50	100
1R2 1R5	(pF) 1.2 1.5															
1R8	1.8															
2R2 2R7	2.2 2.7															
3R3	3.3															$\vdash$
3R9	3.9															
4R7	4.7				<u> </u>	_							_			$\vdash \vdash$
5R6 6R8	5.6 6.8															
8R2	8.2															
100	10															
120	12															
150 180	15 18															
220	22															
270	27															
330 390	33 39															
470	39 47															
560	56															
680	68															
820	82															
101 121	100 120															
151	150															
181	180															
221 271	220 270															
331	330															
391	390															
471	470															
561 681	560 680															
821	820															
102	1000															
122	1200															
152 182	1500 1800				_	-			$\vdash$							$\vdash\vdash$
222	2200															
272	2700															
332	3300															]
392 472	3900 4700															
562	5600															$\vdash \vdash$
682	6800															
822	8200															



### Capacitance Range - X7R/X5R

S	IZE	Т		03	06				0405	5				05	08					05	08					06	12		
	ements	1			4				2					- 2	2						1					4	1		
So	ldering	$\perp$			v Only				eflow C				F		/Wave	)			F	Reflow	/Wave	9			F	Reflow	/Wave	)	
Pac	ckaging	4	All Paper All Paper 1.60 ± 0.15 1.00 ± 0.15										All P							nboss						nboss			
Length	MM				± 0.15 ± 0.00										± 0.15						± 0.15 ± 0.00						0.150		
	(in MN	_	_		± 0.00 ± 0.15		$\vdash$		$39 \pm 0$ $37 \pm 0$			_	_		± 0.00 ± 0.15			$\vdash$	_		± 0.00			$\vdash$			£ 0.00		
Width	(in				± 0.13				54 ± 0						± 0.13						± 0.13						£ 0.20		
Max.	MM	_	(=		50	-/		(0.00	0.66	,			- (-		94	-,			(=	0.9		-,			(=	1.0		-,	
Thicknes	ss (in	.)		(0.0					(0.026	5)				<u> </u>	)37)					(0.0						(0.0	53)		
	VDC	_	6	10	16	25	6	10	16	25	50	6	10	16	25	50	100	6	10	16	25	50	100	6	10	16	25	50	100
	ap 100																												
121 (µ 151	ıF) 120 150																												
181	180	$-\mathbf{\nu}$		+//																				$\vdash$					
221	220																												
271	270	-	44	44																									
331	330																												
391 471	390 470																												
561	560	$-\nu$																											
681	680	1																											
821	820	_																											
102 122	1000																												
152	1200 1500																												
182	1800	_																											
222	2200																												
272	2700																												
332 392	3300 3900																												
472	4700																												
562	5600																												
682	6800																						///						
822	8200	-																											
	ap 0.010 IF) 0.012																												
153	0.015																												
183	0.018																												
223 273	0.022																												
333	0.027	_																			///								$\vdash$
393	0.039																												
473	0.047																												
563	0.056																												
683 823	0.068 0.082																												
104	0.062	_																											$\vdash\vdash$
124	0.12						1///						1///											1///	///	1///			
154	0.15	_																											Ш
184	0.18 0.22																							///					
224 274	0.22																												
334	0.33	_																											H
474	0.47	1																											
564	0.56	_					_														_								$\vdash \vdash$
684 824	0.68 0.82																												
105	1.0																												
125	1.2	T										///																	
155	1.5																												
185	1.8					_	-		_									$\vdash$										_	$\vdash\vdash\vdash$
225 335	2.2 3.3											///												////					
475	4.7																												
106	10																												
226	22																												
476 107	47 100																												
101	100											<u> </u>							<u> </u>					<u> </u>					ш



= Currently available X5R

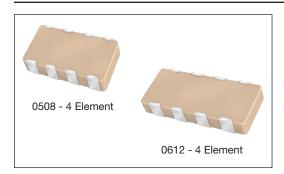
= Under development X7R, contact factory for advance samples

= Under development X5R, contact factory for advance samples



# **Automotive Capacitor Array (IPC)**



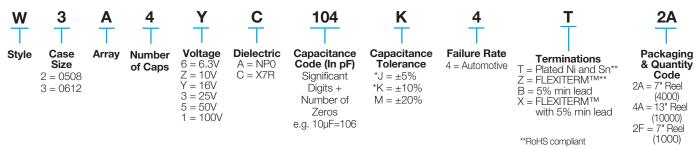


As the market leader in the development and manufacture of capacitor arrays AVX is pleased to offer a range of AEC-Q200 qualified arrays to compliment our product offering to the Automotive industry. Both the AVX 0612 and 0508 4-element capacitor array styles are qualified to the AEC-Q200 automotive specifications.

AEC-Q200 is the Automotive Industry qualification standard and a detailed qualification package is available on request.

All AVX automotive capacitor array production facilities are certified to ISO/TS 16949:2002.

### **HOW TO ORDER**



<sup>\*</sup>Contact factory for availability by part number for  $K = \pm 10\%$  and  $J = \pm 5\%$  tolerance.

ь і		100	
N	$\mathbf{P}$	/CO	ш

NP0/C0G										
S	IZE	0508		05	80			06	12	
	f Elements	2		4	1			4	ļ	
	VDC	100	16	25	50	100	16	25	50	100
1R0 1R2 1R5	Cap 1.0 (pF) 1.2 1.5									
1R8 2R2 2R7	1.8 2.2 2.7									
3R3 3R9 4R7	3.3 3.9 4.7									
5R6 6R8 8R2	5.6 6.8 8.2									
100 120 150	10 12 15									
180 220 270	18 22 27									
330 390 470	33 39 47									
560 680 820	56 68 82									
101 121 151	100 120 150									
181 221 271	180 220 270									
331 391 471	330 390 470									
561 681 821	560 680 820									
102 122 152	1000 1200 1500									
182 222 272	1800 2200 2700									
332 392 472	3300 3900 4700									
562 682 822	5600 6800 8200									

#### X7R

SI	ZE		05	80			0	508				06	12	
No. of	Elements			2				4				4	1	
	WVDC	16	25	50	100	16	25	50	100	10	16	25	50	100
101 121 151	Cap 100 (pF) 120 150													
181 221 271	180 220 270													
331 391 471	330 390 470													
561 681 821	560 680 820													
102 122 152	1000 1200 1500													
182 222 272	1800 2200 2700													
332 392 472	3300 3900 4700													
562 682 822	5600 6800 8200													
103 123 153	Cap 0.010 (µF) 0.012 0.015													
183 223 273	0.018 0.022 0.027													
333 393 473	0.033 0.039 0.047													
563 683 823	0.056 0.068 0.082													
104 124 154	0.10 0.12 0.15													
= >	K7R					•								<u> </u>







### **Multi-Value Capacitor Array (IPC)**



### **GENERAL DESCRIPTION**

A recent addition to the array product range is the Multi-Value Capacitor Array. These devices combine two different capacitance values in standard 'Cap Array' packages and are available with a maximum ratio between the two capacitance values of 100:1. The multi-value array is currently available in the 0405 and 0508 2-element styles and also in the 0612 4-element style.

Whereas to date AVX capacitor arrays have been suited to applications where multiple capacitors of the same value are used, the multi-value array introduces a new flexibility to the range. The multi-value array can replace discrete capacitors of different values and can be used for broadband decoupling applications. The 0508 x 2 element multi-value array would be particularly recommended in this application. Another application is filtering the 900/1800 or 1900MHz noise in mobile phones. The 0405 2-element, low capacitance value NPO, (COG) device would be suited to this application, in view of the space saving requirements of mobile phone manufacturers.

# ADVANTAGES OF THE MULTI-VALUE CAPACITOR ARRAYS

### **Enhanced Performance Due to Reduced Parasitic Inductance**

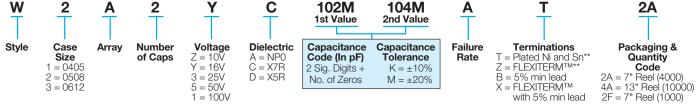
When connected in parallel, not only do discrete capacitors of different values give the desired self-resonance, but an additional unwanted parallel resonance also results. This parallel resonance is induced between each capacitor's self-resonant frequencies and produces a peak in impedance response. For decoupling and bypassing applications this peak will result in a frequency band of reduced decoupling and in filtering applications reduced attenuation.

The multi-value capacitor array, combining capacitors in one unit, virtually eliminates the problematic parallel resonance, by minimizing parasitic inductance between the capacitors, thus enhancing the broadband decoupling/filtering performance of the part.

#### Reduced ESR

An advantage of connecting two capacitors in parallel is a significant reduction in ESR. However, as stated above, using discrete components brings with it the unwanted side effect of parallel resonance. The multi-value cap array is an excellent alternative as not only does it perform the same function as parallel capacitors but also it reduces the uncertainty of the frequency response.

### **HOW TO ORDER (Multi-Value Capacitor Array - IPC)**



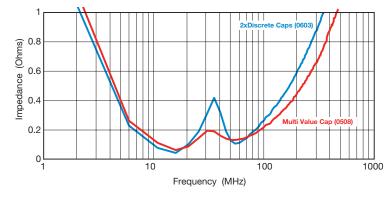
NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

\*\*RoHS compliant

	Cap (Min/Max) NP0 X5R/X7R				
0612 4-element	100/471	221/104			
0508 2-element	100/471	221/104			
0405 2-element	100/101	101/103			

- Max. ratio between the two cap values is 1:100.
- The voltage of the higher capacitance value dictates the voltage of the multi-value part.
- Only combinations of values within a specific dielectric range are possible.

### IMPEDANCE VS FREQUENCY

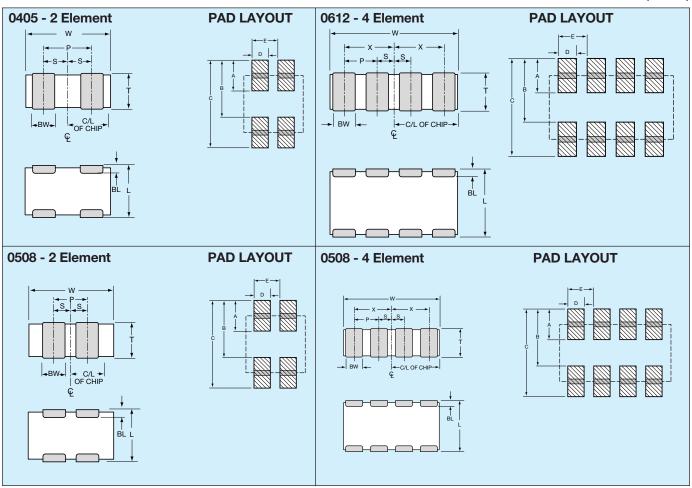






### PART & PAD LAYOUT DIMENSIONS

millimeters (inches)



### **PART DIMENSIONS**

### 0405 - 2 Element

L	W	Т	BW	BL	Р	S
1.00 ± 0.15		0.66 MAX	0.36 ± 0.10	0.20 ± 0.10	0.64 REF	0.32 ± 0.10
(0.039 ± 0.006)		(0.026 MAX)	(0.014 ± 0.004)	(0.008 ± 0.004)	(0.025 REF)	(0.013 ± 0.004)

#### 0508 - 2 Element

L	W	Т	BW	BL	Р	S
	2.10 ± 0.15 (0.083 ± 0.006)	0.94 MAX (0.037 MAX)	0.43 ± 0.10 (0.017 ± 0.004)		1.00 REF (0.039 REF)	0.50 ± 0.10 (0.020 ± 0.004)

#### 0508 - 4 Element

L	W	Т	BW	BL	Р	X	S
1.30 ± 0.15	2.10 ± 0.15	0.94 MAX	0.25 ± 0.06	0.20 ± 0.08	0.50 REF	0.75 ± 0.10	0.25 ± 0.10
(0.051 ± 0.006)	$(0.083 \pm 0.006)$	(0.037 MAX)	$(0.010 \pm 0.003)$	$(0.008 \pm 0.003)$	(0.020 REF)	$(0.030 \pm 0.004)$	$(0.010 \pm 0.004)$

### 0612 - 4 Element

L	W	Т	BW	BL	Р	Х	S
1.60 ± 0.20 (0.063 ± 0.008)	3.20 ± 0.20 (0.126 ± 0.008)		0.41 ± 0.10 (0.016 ± 0.004)			1.14 ± 0.10 (0.045 ± 0.004)	

### PAD LAYOUT DIMENSIONS

### 0405 - 2 Element

Α	В	С	D	E
0.46	0.74	1.20	0.30	0.64
(0.018)	(0.029)	(0.047)	(0.012)	(0.025)

#### 0508 - 2 Element

Α	В	C	D	Е
0.68	1.32	2.00	0.46	1.00
(0.027)	(0.052)	(0.079)	(0.018)	(0.039)

#### 0508 - 4 Element

Α	В	С	D	E
0.56	1.32	1.88	0.30	0.50
(0.022)	(0.052)	(0.074)	(0.012)	(0.020)

### 0612 - 4 Element

Α	В	С	D	Е
0.89	1.65	2.54	0.46	0.76
(0.035)	(0.065)	(0.100)	(0.018)	(0.030)



## **Low Inductance Capacitors**



### Introduction

As switching speeds increase and pulse rise times decrease the need to reduce inductance becomes a serious limitation for improved system performance. Even the decoupling capacitors, that act as a local energy source, can generate unacceptable voltage spikes: V = L (di/dt). Thus, in high speed circuits, where di/dt can be quite large, the size of the voltage spike can only be reduced by reducing L.

Figure 1 displays the evolution of ceramic capacitor toward lower inductance designs over the last few years. AVX has been at the forefront in the design and manufacture of these newer more effective capacitors.

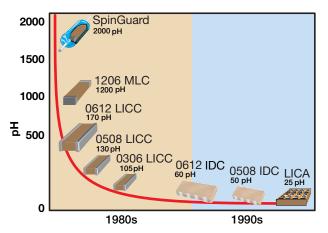


Figure 1. The evolution of Low Inductance Capacitors at AVX (values given for a 100 nF capacitor of each style)

### LOW INDUCTANCE CHIP CAPACITORS

The total inductance of a chip capacitor is determined both by its length to width ratio and by the mutual inductance coupling between its electrodes. Thus a 1210 chip size has lower inductance than a 1206 chip. This design improvement is the basis of AVX's low inductance chip capacitors, LI Caps, where the electrodes are terminated on the long side of the chip instead of the short side. The 1206 becomes an 0612 as demonstrated in Figure 2. In the same manner, an 0805 becomes an 0508 and 0603 becomes an 0306. This results in a reduction in inductance from around 1200 pH for conventional MLC chips to below 200 pH for Low Inductance Chip Capacitors. Standard designs and performance of these LI Caps are given on pages 55 and 56.

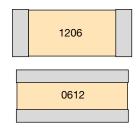
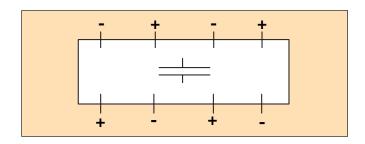


Figure 2. Change in aspect ratio: 1206 vs. 0612

#### INTERDIGITATED CAPACITORS

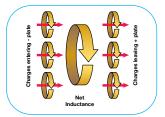
Multiple terminations of a capacitor will also help in reducing the parasitic inductance of the device. The IDC is such a device. By terminating one capacitor with 8 connections the ESL can be reduced even further. The measured inductance of the 0612 IDC is 60 pH, while the 0508 comes in around 50 pH. These FR4 mountable devices allow for even higher clock speeds in a digital decoupling scheme. Design and product offerings are shown on pages 59 and 60.



### **LOW INDUCTANCE CHIP ARRAYS (LICA®)**

Further reduction in inductance can be achieved by designing alternative current paths to minimize the mutual inductance factor of the electrodes (Figure 3). This is achieved by AVX's LICA® product which was the result of a joint development between AVX and IBM. As shown in Figure 4, the charging current flowing out of the positive plate returns in the opposite direction along adjacent negative plates. This minimizes the mutual inductance.

The very low inductance of the LICA capacitor stems from the short aspect ratio of the electrodes, the arrangement of the tabs so as to cancel inductance, and the vertical aspect of the electrodes to the mounting surface.



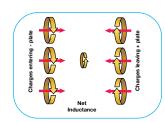


Figure 3. Net Inductance from design. In the standard Multilayer capacitor, the charge currents entering and leaving the capacitor create complementary flux fields, so the net inductance is greater. On the right, however, if the design permits the currents to be opposed, there is a net cancellation, and the inductance is much lower.



## **Low Inductance Capacitors**

### Introduction



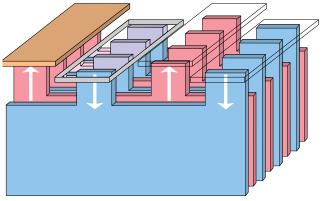


Figure 4. LICA's Electrode/Termination Construction.

The current path is minimized – this reduces self-inductance.

Current flowing out of the positive plate, returns in the opposite direction along the adjacent negative plate – this reduces the mutual inductance.

Also the effective current path length is minimized because the current does not have to travel the entire length of both electrodes to complete the circuit. This reduces the self inductance of the electrodes. The self inductance is also minimized by the fact that the charging current is supplied by both sets of terminals reducing the path length even further!

The inductance of this arrangement is less than 30 pH, causing the self-resonance to be above 100 MHz for the same popular 100 nF capacitance. Parts available in the LICA design are shown on pages 60 and 61.

Figure 5 compares the self resonant frequencies of various capacitor designs versus capacitance values. The approximate inductance of each style is also shown.

Active development continues on low inductance capacitors. C4 termination with low temperature solder is now available for plastic packages. Consult AVX for details.

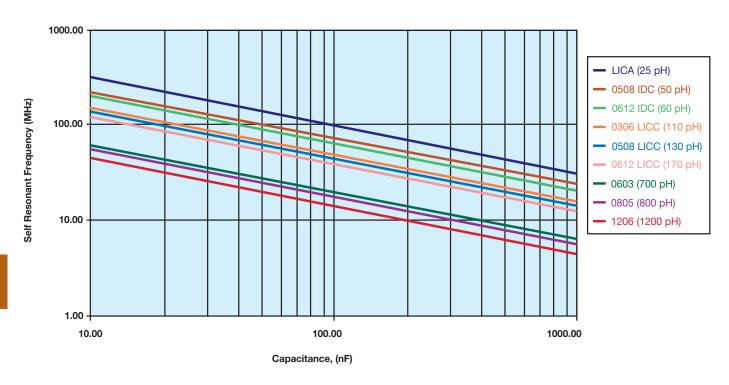


Figure 5. Self Resonant Frequency vs. Capacitance and Capacitor Design

# Low Inductance Capacitors (RoHS)

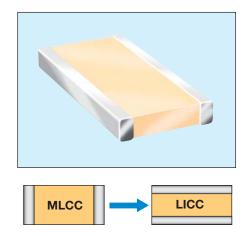


0612/0508/0306 LICC (Low Inductance Chip Capacitors)

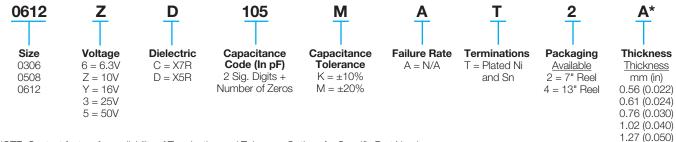
### **GENERAL DESCRIPTION**

The total inductance of a chip capacitor is determined both by its length to width ratio and by the mutual inductance coupling between its electrodes.

Thus a 1210 chip size has a lower inductance than a 1206 chip. This design improvement is the basis of AVX's Low Inductance Chip Capacitors (LICC), where the electrodes are terminated on the long side of the chip instead of the short side. The 1206 becomes an 0612, in the same manner, an 0805 becomes an 0508, an 0603 becomes an 0306. This results in a reduction in inductance from the 1nH range found in normal chip capacitors to less than 0.2nH for LICCs. Their low profile is also ideal for surface mounting (both on the PCB and on IC package) or inside cavity mounting on the IC itself.



### **HOW TO ORDER**



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

### PERFORMANCE CHARACTERISTICS

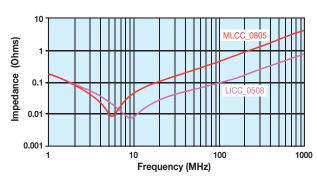
Capacitance Tolerances	$K = \pm 10\%$ ; $M = \pm 20\%$
Operation	$X7R = -55^{\circ}C \text{ to } +125^{\circ}C;$
Temperature Range	X5R = -55°C to $+85$ °C
Temperature Coefficient	±15% (0VDC)
Voltage Ratings	6.3, 10, 16, 25 VDC
Dissipation Factor	6.3V = 6.5% max; 10V = 5.0% max; 16V = 3.5% max; 25V = 3.0% max
Insulation Resistance (@+25°C, RVDC)	100,000M $\Omega$ min, or 1,000M $\Omega$ per μF min.,whichever is less

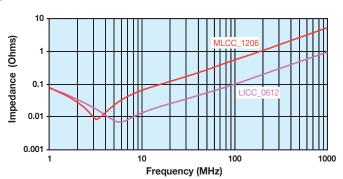
### **TYPICAL INDUCTANCE**

Package Style	Measured Inductance (pH)
1206 MLCC	1200
0612 LICC	170
0508 LICC	130
0306 LICC	105

\*Note: See Range Chart for Codes

### **TYPICAL IMPEDANCE CHARACTERISTICS**





# Low Inductance Capacitors (RoHS)



0612/0508/0306 LICC (Low Inductance Chip Capacitors)

SIZE		(	030	6		0508 0612									
Packaging			nbos			Embossed					En	nbos	sed		
Length MM (in.)		0.81 ± 0.15 (0.032 ± 0.006)					1.27 ± 0.25 (0.050 ± 0.010)				1.60 ± 0.25 (0.063 ± 0.010)				
Width MM (in.)			60 ± 0		)			00 ± 0					20 ± 0 26 ± 0		
WVDC	6.3		16	25	50	6.3		16	25	50	6.3	10		25	50
CAP 0.001															
(μF) 0.0022															
0.0047															
0.010															
0.015															
0.022															
0.047															
0.068															
0.10															
0.15															
0.22															
0.47															
0.68															
1.0															
1.5															
2.2															
3.3															
4.7															
10															

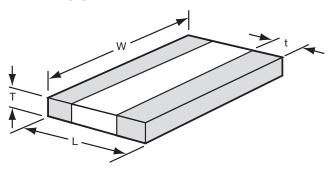
Solid = X7R = X5R



	mm (in.)				
0508					
Code	Thickness				
S	0.56 (0.022)				
٧	0.76 (0.030)				
Α	1.02 (0.040)				

	mm (in.)					
0612						
Code	Thickness					
S	0.56 (0.022)					
V	0.76 (0.030)					
W	1.02 (0.040)					
Α	1.27 (0.050)					

# PHYSICAL DIMENSIONS AND PAD LAYOUT



### PHYSICAL CHIP DIMENSIONS

mm (in)

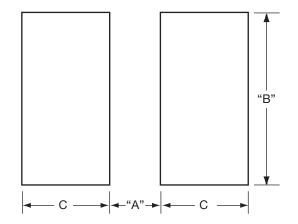
	L	W	t
0612	$1.60 \pm 0.25$	3.20 ± 0.25	0.13 min.
	(0.063 ± 0.010)	(0.126 ± 0.010)	(0.005 min.)
0508	1.27 ± 0.25	2.00 ± 0.25	0.13 min.
	(0.050 ± 0.010)	(0.080 ± 0.010)	(0.005 min.)
0306	0.81 ± 0.15	1.60 ± 0.15	0.13 min.
	(0.032 ± 0.006)	(0.063 ± 0.006)	(0.005 min.)

T - See Range Chart for Thickness and Codes

### PAD LAYOUT DIMENSIONS

mm (in)

	Α	В	С
0612	0.76 (0.030)	3.05 (0.120)	.635 (0.025)
0508	0.51 (0.020)	2.03 (0.080)	0.51 (0.020)
0306	0.31 (0.012)	1.52 (0.060)	0.51 (0.020)





# Low Inductance Capacitors (SnPb)

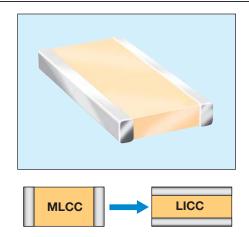


# 0612/0508/0306 X7R & X5R Dielectric – Tin Lead Termination "B"

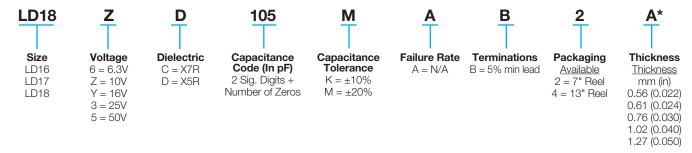
### **GENERAL DESCRIPTION**

The total inductance of a chip capacitor is determined both by its length to width ratio and by the mutual inductance coupling between its electrodes.

Thus a 1210 chip size has a lower inductance than a 1206 chip. This design improvement is the basis of AVX's Low Inductance Chip Capacitors (LICC), where the electrodes are terminated on the long side of the chip instead of the short side. The 1206 becomes an 0612, in the same manner, an 0805 becomes an 0508, an 0603 becomes an 0306. This results in a reduction in inductance from the 1nH range found in normal chip capacitors to less than 0.2nH for LICCs. Their low profile is also ideal for surface mounting (both on the PCB and on IC package) or inside cavity mounting on the IC itself.



### **HOW TO ORDER**



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.



# Low Inductance Capacitors (SnPb)



# 0612/0508/0306 X7R & X5R Dielectric – Tin Lead Termination "B"

### **PREFERRED SIZES ARE SHADED**

SIZ	ZE			LD16			LD17				LD18					
Solde	ering			Reflow Only	,				Reflow Only	У			R	eflow/Wave	<del></del>	
Packa	aging		All Paper						All Paper				Par	er/Emboss	ed	
(L) Length	MM (in.)		0.81 ± 0.15 (0.032 ± 0.006)					((	1.27 ± 0.25 0.050 ± 0.010				(C	1.60 ± 0.25 0.063 ± 0.010	)	
(W) Width	MM (in.)		(	1.60 ± 0.15 0.063 ± 0.006	,			(1	2.00 ± 0.25 0.080 ± 0.010	,				3.20 ± 0.25 ).126 ± 0.010	,	
	WVDC	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50
Cap (pF)	1000 2200 4700	A A A	A A A	A A A	A A A		S S S	S S S	S S S	S S S	V V V	S S S	S S S	S S S	S S S	V V
Cap (µF)	0.010 0.015 0.022	A A A	A A A	A A A	A A A		S S S	S S S	S S S	S S S	V V V	S S S	S S S	S S S	S S S	V W W
	0.047 0.068 0.10	A A A	A A A	A A ///K///			S S S	00 00 00	S S V	V A A	A A A	S S S	0 0 0	S S S	S V V	W W W
	0.15 0.22 0.47	A A	A A				S S V	S S V	V A (//Á///			S S S	\$ \$ \$	S > >	W	W
	0.68 1.0 1.5						A A // <i>A</i> ///	A A				V V W	V V W	W A		
	2.2 3.3 4.7											A ///﴿///	А			
	10															
SIZ	WVDC ZE	6.3	6.3 10 16 25 50 <b>0306</b>					10	16 <b>0508</b>	25	50	6.3	10	16 <b>0612</b>	25	50

	0306		0508		0612
Code	Thickness	Code	Thickness	Code	Thickness
Α	0.61 (0.024)	S	0.56 (0.022)	S	0.56 (0.022)
		V	0.76 (0.030)	V	0.76 (0.030)
		Α	1.02 (0.040)	W	1.02 (0.040)
				Α	1.27 (0.050)





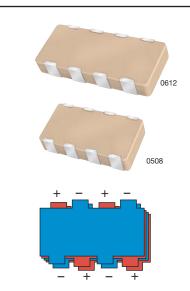


# IDC Low Inductance Capacitors (RoHS)

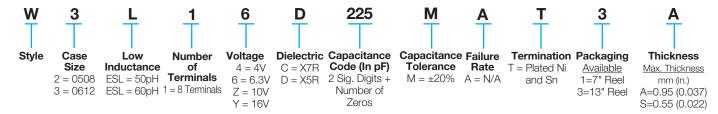
### 0612/0508 IDC (InterDigitated Capacitors)

### **GENERAL DESCRIPTION**

- Very low equivalent series inductance (ESL), surface mountable, high speed decoupling capacitor in 0612 and 0508 case size.
- Measured inductances of 60 pH (for 0612) and 50 pH (for 0508) are the lowest in the FR4 mountable device family. Now use 10T devices with inductances of 45 pH (for 0612) and 35 pH (for 0508).
- Opposing current flow creates opposing magnetic fields. This causes the fields to cancel, effectively reducing the equivalent series inductance.
- Perfect solution for decoupling high speed microprocessors by allowing the engineers to lower the power delivery inductance of the entire system through the use of eight vias.
- Overall reduction in decoupling components due to very low series inductance and high capacitance.



### **HOW TO ORDER**



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

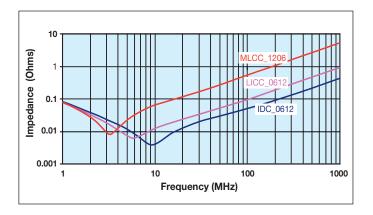
#### PERFORMANCE CHARACTERISTICS

Capacitance Tolerance	±20% Preferred
Operation	$X7R = -55^{\circ}C \text{ to } +125^{\circ}C;$
Temperature Range	X5R = -55°C to $+85$ °C
Temperature Coefficient	±15% (0VDC)
Voltage Ratings	4, 6.3, 10, 16 VDC
Dissipation Factor	4V, 6.3V = 6.5% max; 10V = 5.0% max; 16V = 3.5% max
Insulation Resistance (@+25°C, RVDC)	100,000M $\Omega$ min, or 1,000M $\Omega$ per μF min.,whichever is less

Dielectric Strength	No problems observed after 2.5 x RVDC for 5 seconds at 50mA max current
CTE (ppm/C)	12.0
Thermal Conductivity	4-5W/M K
Terminations Available	Plated Nickel and Solder
Max. Thickness	0.037" (0.95mm)

### TYPICAL ESL AND IMPEDANCE

Package Style	Measured Inductance (pH)
1206 MLCC	1200
0612 LICC	170
0612 IDC	60
0508 IDC	50



# IDC Low Inductance Capacitors (RoHS)

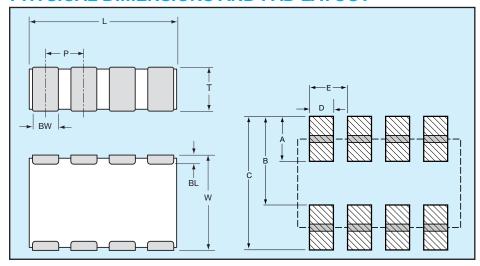
### 0612/0508 IDC (InterDigitated Capacitors)

SIZE			Thin	0508			0	508			Thin	0612			06	12	
Length	MM		2.03 ± 0.20 (0.080 ± 0.008)		$2.03 \pm 0.20$ $2.03 \pm 0.20$ $3.20 \pm 0.20$				3.20 ± 0.20								
	(in.)		`		5)	$(0.080 \pm 0.008)$				(0.126 ± 0.008)			(0.126 ± 0.008)				
Width	MM			± 0.20				± 0.20			1.60 ±					$\pm 0.20$	
VVIGIT	(in.)		(0.050 :		5)		(0.050)	± 0.00	8)	(		0.008	)	$(0.063 \pm 0.008)$			
Terminal	MM			± 0.05			0.50	$\pm 0.05$			0.80					$\pm 0.10$	
Pitch	(in.)		(0.020 :	± 0.002	2)		(0.020)	± 0.00	2)	(	0.031 ±	0.004	)		(0.031)	± 0.00	4)
Thickness	MM		0.55	MAX.			0.95	MAX.			0.55	MAX.			0.95	MAX.	
HIICKHESS	(in.)		(0.022)	) MAX.			(0.03)	7) MAX			(0.022)	) MAX.			(0.03)	7) MAX	
WVDC		4	6.3	10	16	4	6.3	10	16	4	6.3	10	16	4	6.3	10	16
CA	P (µF)																
and Thic	kness																
	0.047																
	0.047									_							
	0.068																
	0.000									_							
	0.10																
	01.10																
	0.22																
	0.33																
	0.47																
	0.00																
	0.68									_							
	1.0																
	1.0																
	1.5																
	2.2																
	3.3																

Consult factory for additional requirements



### PHYSICAL DIMENSIONS AND PAD LAYOUT



### PHYSICAL CHIP DIMENSIONS millimeters (inches)

### 0612

L	W	BW	BL	Р
$3.20 \pm 0.20$	1.60 ± 0.20	0.41 ± 0.10	0.18 +0.25	$0.80 \pm 0.10$
$(0.126 \pm 0.008)$	$(0.063 \pm 0.008)$	$(0.016 \pm 0.004)$	(0.007 +0.010)	$(0.031 \pm 0.004)$

### 0508

L	W	BW	BL	Р
2.03±0.20 (0.080±0.008)	1.27±0.20 (0.050±0.008)	0.254±0.10 (0.010±0.004)	0.18 <sup>+0.25</sup> <sub>-0.08</sub> (0.007 <sup>+0.010</sup> )	$0.50 \pm 0.05$ $(0.020 \pm 0.002)$

# PAD LAYOUT DIMENSIONS

### 0612

Α	В	С	D	Е
0.89	1.65	2.54	0.46	0.80
(0.035)	(0.065)	(0.100)	(0.018)	(0.031)

### 0508

Α	В	С	D	Е
0.64	1.27	1.91	0.28	0.50
(0.025)	(0.050)	(0.075)	(0.011)	(0.020)



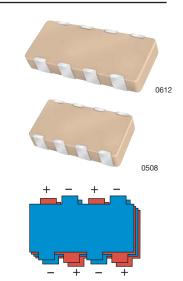
# IDC Low Inductance Capacitors (SnPb)

### 0612/0508 IDC with Sn/Pb Termination

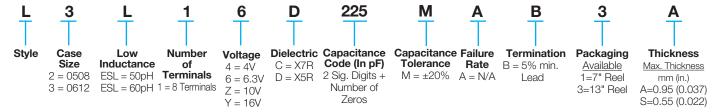
### **GENERAL DESCRIPTION**

AVX will support those customers who desire commercial and military type ceramic capacitors with a new series consisting of a termination with a 5% minimum lead content. This new series is AVX's "LD" series incorporating a "B" in the 12th position of the AVX Catalog Part Number. This fulfills AVX's commitment to providing a full range of products.

- Very low equivalent series inductance (ESL), surface mountable, high speed decoupling capacitor in 0612 and 0508 case size.
- Measured inductances of 60 pH (for 0612) and 50 pH (for 0508) are the lowest in the FR4 mountable device family. Now use 10T devices with inductances of 45 pH (for 0612) and 35 pH (for 0508).
- Opposing current flow creates opposing magnetic fields. This causes the fields to cancel, effectively reducing the equivalent series inductance.
- Perfect solution for decoupling high speed microprocessors by allowing the engineers to lower the power delivery inductance of the entire system through the use of eight vias.
- Overall reduction in decoupling components due to very low series inductance and high capacitance.



### **HOW TO ORDER**



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

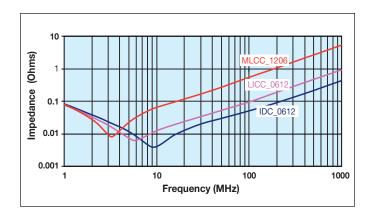
### PERFORMANCE CHARACTERISTICS

Capacitance Tolerance	±20% Preferred
Operation	$X7R = -55^{\circ}C \text{ to } +125^{\circ}C;$
Temperature Range	X5R = -55°C to $+85$ °C
Temperature Coefficient	±15% (0VDC)
Voltage Ratings	4, 6.3, 10, 16 VDC
Dissipation Factor	4V, 6.3V = 6.5% max; 10V = 5.0% max; 16V = 3.5% max
Insulation Resistance (@+25°C, RVDC)	100,000M $\Omega$ min, or 1,000M $\Omega$ per μF min.,whichever is less

Dielectric Strength	No problems observed after 2.5 x RVDC for 5 seconds at 50mA max current
CTE (ppm/C)	12.0
Thermal Conductivity	4-5W/M K
Terminations Available	Plated Nickel and 5% min. Lead
Max. Thickness	0.037" (0.95mm)

### TYPICAL ESL AND IMPEDANCE

Package Style	Measured Inductance (pH)
1206 MLCC	1200
0612 LICC	170
0612 IDC	60
0508 IDC	50



# IDC Low Inductance Capacitors (SnPb)

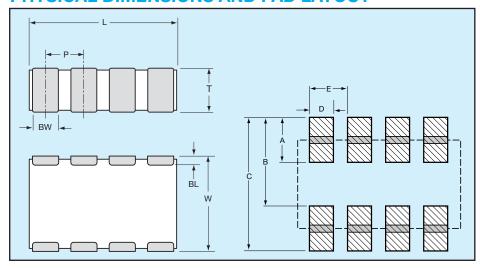
### 0612/0508 IDC with Sn/Pb Termination

SIZE			Thin	0508			0	508			Thin	0612			06	12	
Length	MM (in.)			± 0.20 ± 0.008	5)			± 0.20 ± 0.00		(	3.20 ± 0.126 ±		)			± 0.20 ± 0.00	
Width	MM (in.)	(	(0.050 :	± 0.20 ± 0.008	3)		(0.050	± 0.20 ± 0.00	8)	(	1.60 ± 0.063 ±	0.008	)			± 0.20 ± 0.00	
Terminal Pitch	MM (in.)	(	(0.020 :	± 0.05 ± 0.002	<u>'</u> )		(0.020	± 0.05 ± 0.00		(	0.80 ± 0.031 ±	0.004	)	0.80 ± 0.10 (0.031 ± 0.004)			
Thickness	MM (in.)		(0.022	MAX. ) MAX.			(0.03	MAX. 7) MAX			0.55	MAX.			(0.03	MAX. 7) MAX	
WVDC		4	6.3	10	16	4	6.3	10	16	4	6.3	10	16	4	6.3	10	16
CA and Thic	P (µF) kness																
	0.047																
	0.068																
	0.10																
	0.22																
	0.33																
	0.47																
	0.68																
	1.0																
	1.5																
	2.2																
	3.3																

Consult factory for additional requirements



### PHYSICAL DIMENSIONS AND PAD LAYOUT



### PHYSICAL CHIP DIMENSIONS millimeters (inches)

### 0612

L	W	BW	BL	Р
$3.20 \pm 0.20$	1.60 ± 0.20	0.41 ± 0.10	0.18 +0.25	$0.80 \pm 0.10$
$(0.126 \pm 0.008)$	$(0.063 \pm 0.008)$	$(0.016 \pm 0.004)$	(0.007 +0.010)	$(0.031 \pm 0.004)$

### 0508

	L	W	BW	BL	Р
1	2.03±0.20	1.27±0.20	0.254±0.10	0.18 <sup>+0.25</sup> <sub>-0.08</sub>	$0.50 \pm 0.05$
	.080±0.008)	(0.050±0.008)	(0.010±0.004)	(0.007 <sup>+0.010</sup> <sub>-0.003</sub> )	$(0.020 \pm 0.002)$

# PAD LAYOUT DIMENSIONS

### 0612

Α	В	С	D	Е
0.89	1.65	2.54	0.46	0.80
(0.035)	(0.065)	(0.100)	(0.018)	(0.031)

### 0508

Α	A B		D	E	
0.64	1.27	1.91	0.28	0.50	
(0.025)	(0.050)	(0.075)	(0.011)	(0.020)	



# **Low Inductance Capacitors**



### LICA® (Low Inductance Decoupling Capacitor Arrays)



LICA® arrays utilize up to four separate capacitor sections in one ceramic body (see Configurations and Capacitance Options). These designs exhibit a number of technical advancements:

Low Inductance features-

Low resistance platinum electrodes in a low aspect ratio pattern Double electrode pickup and perpendicular current paths C4 "flip-chip" technology for minimal interconnect inductance

### **HOW TO ORDER**

L	ICA	3	<u> </u>	102	M	3	<u>F</u> ⊤	C	4	<u>A</u>	A
	Style	Voltage	Dielectric	Cap/Section	Capacitance	Height	Termination	Reel Packaging	# of	Inspection	Code
	&	5V = 9	D = X5R	(EIA Code)	Tolerance	Code	F = C4 Solder	M = 7" Reel	Caps/Part	Code	Face
	Size	10V = Z	T = T55T	102 = 1000 pF	$M = \pm 20\%$	6 = 0.500mm	Balls-97Pb/3Sr	n R = 13" Reel	1 = one	A = Standard	A = Bar
		25V = 3	S = High K	103 = 10  nF	P = GMV	3 = 0.650mm	H = C4 Solder Balls	6 = 2"x2" Waffle Pack	2 = two	B = Established	B = No Bar
			T55T	104 = 100  nF		1 = 0.875mm	Low ESR	8 = 2"x2" Black Waffle	4 = four	Reliability	C = Dot, S55S
						5 = 1.100mm	P = Cr-Cu-Au	Pack		Testing	Dielectrics
						7 = 1.600mm	N = Cr-Ni-Au	7 = 2"x2" Waffle Pack			D = Triangle
							X = None	w/ termination			
٦	<b>TABLI</b>	≣1						facing up			
		al Para	meters 25°C		T55T Co	N	<b>Units</b> lanofarads	A = 2"x2" Black Waffle Pack w/ termination			
	Capa	citance, 5	55°C		1.4 x Co	N	lanofarads	facing up	N	OTE: Contact fac	ctory for

Typical Parameters	T55T	Units
Capacitance, 25°C	Co	Nanofarads
Capacitance, 55°C	1.4 x Co	Nanofarads
Capacitance, 85°C	0.7 x Co	Nanofarads
Dissipation Factor 25°	15	Percent
ESR	20	Megohms
DC Resistance	0.2	Ohms
IR (Minimum @25°)	2.0	Megaohms
Dielectric Breakdown, Min	500	Volts
Thermal Coefficient of Expansion	8.5	ppm/°C 25-100°
Inductance: (Design Dependent)	30	Pico-Henries
Frequency of Operation	DC to 5 Gigahertz	
Ambient Temp Range	-55° to 125°C	

### **TERMINATION OPTIONS**

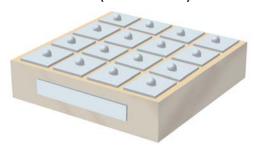
C = 4"x4" Waffle Pack

w/ clear lid

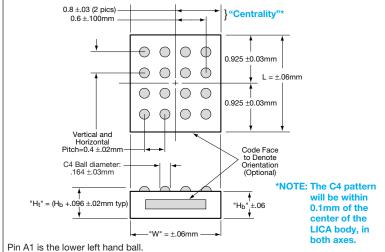
C4 SOLDER (97% Pb/3% Sn) BALLS

availability of Termination and Tolerance Options for Specific

Part Numbers.



### C4 AND PAD DIMENSIONS



Pin AT is the lower len	i nand ball.		
Code (Body Height)	Width (W)	Length (L)	Height Body (H <sub>b</sub> )
1	1.600mm	1.850mm	0.875mm
3	1.600mm	1.850mm	0.650mm
5	1.600mm	1.850mm	1.100mm
6	1.600mm	1.850mm	0.500mm
7	1.600mm	1.850mm	1.600mm





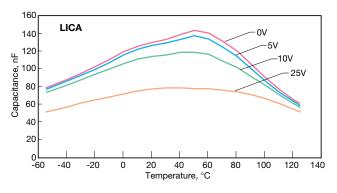
### TERMINATION OPTION P OR N

## **Low Inductance Capacitors**

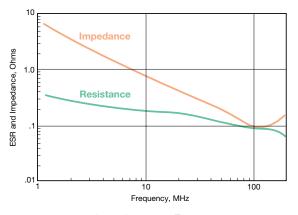


### LICA® (Low Inductance Decoupling Capacitor Arrays)

### LICA® TYPICAL PERFORMANCE CURVES



Effect of Bias Voltage and Temperature on a 130 nF LICA® (T55T)

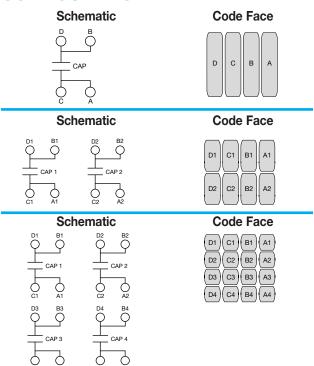


Impedance vs. Frequency

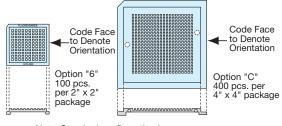
### **LICA VALID PART NUMBER LIST**

Part Number	Voltage	Thickness (mm)	Capacitors per Package
LICA3T193M3FC4AA	25	0.650	4
LICA3T153P3FC4AA	25	0.650	4
LICA3T134M1FC1AA	25	0.875	1
LICA3T104P1FC1AA	25	0.875	1
LICA3T333M1FC4AA	25	0.875	4
LICA3T263P3FC4AA	25	0.650	4
LICA3T244M5FC1AA	25	1.100	1
LICA3T194P5FC1AA	25	1.100	1
LICA3T394M7FC1AB	25	1.600	1
LICA3T314P7FC1AB	25	1.600	1
Extended Range			
LICAZT623M3FC4AB	10	0.650	4
LICA3T104M3FC1A	25	0.650	1
LICA3T803P3FC1A	25	0.650	1
LICA3T503M3FC2A	25	0.650	2
LICA3T403P3FC2A	25	0.650	2
LICA3S253M3FC4A	25	0.650	4
LICAZD753M3FC4AD	10	0.650	4
LICAZD504M3FC1AB	10	0.650	1
LICAZD604M7FC1AB	10	1.600	1
LICA3D193M3FC4AB	25	0.650	4

### **CONFIGURATION**



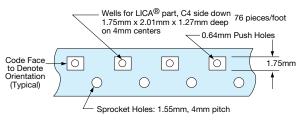
### WAFFLE PACK OPTIONS FOR LICA®



Note: Standard configuration is Termination side down

### LICA® PACKAGING SCHEME "M" AND "R"

8mm conductive plastic tape on reel: "M"=7" reel max. qty. 3,000, "R"=13" reel max. qty. 8,000

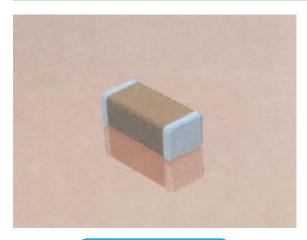




## **High Voltage MLC Chips**

### For 600V to 5000V Application





High value, low leakage and small size are difficult parameters to obtain in capacitors for high voltage systems. AVX special high voltage MLC chip capacitors meet these performance characteristics and are designed for applications such as snubbers in high frequency power converters, resonators in SMPS, and high voltage coupling/dc blocking. These high voltage chip designs exhibit low ESRs at high frequencies.

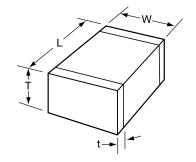
Larger physical sizes than normally encountered chips are used to make high voltage MLC chip products. Special precautions must be taken in applying these chips in surface mount assemblies. The temperature gradient during heating or cooling cycles should not exceed 4°C per second. The preheat temperature must be within 50°C of the peak temperature reached by the ceramic bodies through the soldering process. Chip sizes 1210 and larger should be reflow soldered only. Capacitors may require protective surface coating to prevent external arcing.

### **NEW 630V RANGE**

### **HOW TO ORDER**

1808	<b>A</b>	<b>A</b>	<u>271</u>	<u>K</u>	<b>A</b>	1	<b>1</b>	<b>A</b>
AVX	Voltage	Temperature	<b>Capacitance Code</b>	Capacitance	Test Level	Termination*	Packaging	Special
Style	600V/630V = C	Coefficient	(2 significant digits	Tolerance	A = Standard	1 = Pd/Ag	1 = 7" Reel	Code
0805	1000V = A	COG = A	+ no. of zeros)	$C0G:J = \pm 5\%$		T = Plated	3 = 13" Reel	A = Standard
1206	1500V = S	X7R = C	Examples:	$K = \pm 10\%$		Ni and Sn	9 = Bulk	
1210	2000V = G		10  pF = 100	$M = \pm 20\%$		(RoHS Compliant)		
1808	2500V = W		100  pF = 101	$X7R:K = \pm 10\%$				
1812	3000V = H		1,000 pF = 102	$M = \pm 20\%$				
1825	4000V = J		22,000  pF = 223	Z = +80%,				
2220	5000V = K		220,000 pF = 224	-20%				
2225			$1 \mu F = 105$					
3640			•					
*Note:	Terminations with 5	5% minimum lead	(Pb) is available, see page	es 69 and 70 for LD s	style.			

Notes: Capacitors with X7R dielectrics are not intended for applications across AC supply mains or AC line filtering with polarity reversal. Contact plant for recommendations. Contact factory for availability of Termination and Tolerance options for Specific Part Numbers.





### **DIMENSIONS**

#### millimeters (inches)

SIZE	0805	1206	1210*	1808*	1812*	1825*	2220*	2225*	3640*
(L) Length	2.01 ± 0.20	3.20 ± 0.20	3.20 ± 0.20	4.57 ± 0.25	4.50 ± 0.30	4.50 ± 0.30	5.70 ± 0.40	5.72 ± 0.25	9.14 ± 0.25
	(0.079 ± 0.008)	(0.126 ± 0.008)	(0.126 ± 0.008)	(0.180 ± 0.010)	(0.177 ± 0.012)	(0.177 ± 0.012)	(0.224 ± 0.016)	(0.225 ± 0.010)	(0.360 ± 0.010)
(W) Width	1.25 ± 0.20	1.60 ± 0.20	2.50 ± 0.20	2.03 ± 0.25	3.20 ± 0.20	6.40 ± 0.30	5.00 ± 0.40	6.35 ± 0.25	10.2 ± 0.25
	(0.049 ±0.008)	(0.063 ± 0.008)	(0.098 ± 0.008)	(0.080 ± 0.010)	(0.126 ± 0.008)	(0.252 ± 0.012)	(0.197 ± 0.016)	(0.250 ± 0.010)	(0.400 ± 0.010)
(T) Thickness	1.30	1.52	1.70	2.03	2.54	2.54	3.30	2.54	2.54
Max.	(0.051)	(0.060)	(0.067)	(0.080)	(0.100)	(0.100)	(0.130)	(0.100)	(0.100)
(t) terminal min. max.	0.50 ± 0.25	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.76 (0.030)
	(0.020 ± 0.010)	0.75 (0.030)	0.75 (0.030)	1.02 (0.040)	1.02 (0.040)	1.02 (0.040)	1.02 (0.040)	1.02 (0.040)	1.52 (0.060)

<sup>\*</sup>Reflow Soldering Only



# **High Voltage MLC Chips**



### For 600V to 5000V Applications

### **C0G Dielectric**

### **Performance Characteristics**

Capacitance Range	10 pF to 0.047 μF (25°C, 1.0 ±0.2 Vrms at 1kHz, for ≤ 1000 pF use 1 MHz)
Capacitance Tolerances	±5%, ±10%, ±20%
Dissipation Factor	0.1% max. (+25°C, 1.0 $\pm$ 0.2 Vrms, 1kHz, for $\leq$ 1000 pF use 1 MHz)
Operating Temperature Range	-55°C to +125°C
Temperature Characteristic	0 ±30 ppm/°C (0 VDC)
Voltage Ratings	600, 630, 1000, 1500, 2000, 2500, 3000, 4000 & 5000 VDC (+125°C)
Insulation Resistance (+25°C, at 500 VDC)	100K M $\Omega$ min. or 1000 M $\Omega$ - $\mu$ F min., whichever is less
Insulation Resistance (+125°C, at 500 VDC)	10K M $\Omega$ min. or 100 M $\Omega$ - $\mu$ F min., whichever is less
Dielectric Strength	Minimum 120% rated voltage for 5 seconds at 50 mA max. current

### HIGH VOLTAGE COG CAPACITANCE VALUES

VOLTAGE	0805	1206	1210	1808	1812	1825	2220	2225	3640
600/630 min.	10pF	10 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF	1000 pF
max.	330pF	1200 pF	2700 pF	3300 pF	5600 pF	0.012 µF	0.012 µF	0.018 µF	0.047 µF
1000 min.	10pF	10 pF	10 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF
max.	180pF	560 pF	1500 pF	2200 pF	3300 pF	8200 pF	0.010 µF	0.010 µF	0.022 µF
1500 min.		10 pF	10 pF	10 pF	10 pF	100 pF	100 pF	100 pF	100 pF
1300 max.	_	270 pF	680 pF	820 pF	1800 pF	4700 pF	4700 pF	5600 pF	0.010 µF
2000 min.	_	10 pF	10 pF	10 pF	10 pF	100 pF	100 pF	100 pF	100 pF
max.	_	120 pF	270 pF	330 pF	680 pF	1800 pF	2200 pF	2700 pF	6800 pF
2500 min.	_	_		10 pF	10 pF	10 pF	100 pF	100 pF	100 pF
2300 max.	_	_	_	180 pF	470 pF	1200 pF	1500 pF	1800 pF	3900 pF
3000 min.	_	_	_	10 pF	10 pF	10 pF	10 pF	10 pF	100 pF
max.	_	_	_	120 pF	330 pF	820 pF	1000 pF	1200 pF	2700 pF
4000 min.	_	_	_	10 pF	10 pF	10 pF	10 pF	10 pF	100 pF
max.	_	_	_	47 pF	150 pF	330 pF	470 pF	560 pF	1200 pF
5000 min.		_	_	_	_	_	_	_	10 pF
max.	_	_	_	_	_	_	_	_	820 pF

### **X7R Dielectric**

### **Performance Characteristics**

Capacitance Range	10 pF to 0.56 μF (25°C, 1.0 ±0.2 Vrms at 1kHz)
Capacitance Tolerances	±10%; ±20%; +80%, -20%
Dissipation Factor	2.5% max. (+25°C, 1.0 ±0.2 Vrms, 1kHz)
Operating Temperature Range	-55°C to +125°C
Temperature Characteristic	±15% (0 VDC)
Voltage Ratings	600, 630, 1000, 1500, 2000, 2500, 3000, 4000 & 5000 VDC (+125°C)
Insulation Resistance (+25°C, at 500 VDC)	100K M $\Omega$ min. or 1000 M $\Omega$ - $\mu$ F min., whichever is less
Insulation Resistance (+125°C, at 500 VDC)	10K M $\Omega$ min. or 100 M $\Omega$ - $\mu$ F min., whichever is less
Dielectric Strength	Minimum 120% rated voltage for 5 seconds at 50 mA max. current

### **HIGH VOLTAGE X7R MAXIMUM CAPACITANCE VALUES**

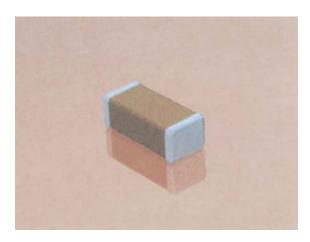
VOLTAGE	0805	1206	1210	1808	1812	1825	2220	2225	3640
600/630 min.	100pF	1000 pF	1000 pF	1000 pF	1000 pF	0.010 µF	0.010 μF	0.010 µF	0.010 µF
max.	6800pF	0.022 µF	0.056 µF	0.068 µF	0.120 µF	0.270 µF	0.270 µF	0.330 µF	0.560 µF
1000 min.	100pF	100 pF	1000 pF	1000 pF	1000 pF	1000 pF	1000 pF	1000 pF	0.010 µF
max.	1500pF	6800 pF	0.015 µF	0.018 µF	0.039 µF	0.100 µF	0.120 µF	0.150 µF	0.220 µF
1500 min.		100 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF	1000 pF
1300 max.	_	2700 pF	6800 pF	6800 pF	0.015 µF	0.056 µF	0.056 µF	0.068 µF	0.100 µF
2000 min.	_	10 pF	100 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF
max.	_	1500 pF	3900 pF	3300 pF	8200 pF	0.027 µF	0.027 µF	0.033 µF	0.027 µF
2500 min.	_	_		10 pF	10 pF	100 pF	100 pF	100 pF	1000 pF
max.	_	_	_	2200 pF	5600 pF	0.015 µF	0.018 µF	0.022 µF	0.022 µF
3000 min.	_			10 pF	10 pF	100 pF	100 pF	100 pF	1000 pF
max.	_	_	_	1800 pF	4700 pF	0.012 µF	0.012 µF	0.015 µF	0.018 µF
4000 min.				_	_	_		_	100 pF
max.	_		_	_		_			6800 pF
5000 min.	_	_	_	_	_	_	_	_	100 pF
max.	_	_	_	_	_	_	_	_	3300 pF



# High Voltage MLC Chips Tin/Lead Termination "B"



### For 600V to 5000V Application



AVX Corporation will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the AVX Catalog Part Number. This fulfills AVX's commitment to providing a full range of products to our customers. AVX has provided in the following pages, a full range of values that we are offering in this "B" termination.

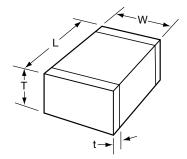
Larger physical sizes than normally encountered chips are used to make high voltage MLC chip product. Special precautions must be taken in applying these chips in surface mount assemblies. The temperature gradient during heating or cooling cycles should not exceed 4°C per second. The preheat temperature must be within 50°C of the peak temperature reached by the ceramic bodies through the soldering process. Chip sizes 1210 and larger should be reflow soldered only. Capacitors may require protective surface coating to prevent external arcing.

### **NEW 630V RANGE**

### **HOW TO ORDER**

LD08	<u>A</u>	<b>A</b>	<u>271</u>	<u>K</u>	<u>A</u>	<u>B</u>	1	A
AVX	Voltage	Temperature	Capacitance Code	Capacitance	Test	Termination	Packaging	Special Code
Style	600V/630V = C	Coefficient	(2 significant digits	Tolerance	Level	B = 5% Min Pb	1 = 7" Reel	A = Standard
LD05 - 0805	1000V = A	COG = A	+ no. of zeros)	COG: $J = \pm 5\%$	A = Standard		3 = 13" Reel	
LD06 - 1206	1500V = S	X7R = C	Examples:	$K = \pm 10\%$			9 = Bulk	
LD10 - 1210	2000V = G		10 pF = 100	$M = \pm 20\%$				
LD08 - 1808	2500V = W		100 pF = 101	X7R: $K = \pm 10\%$				
LD12 - 1812	3000V = H		1,000 pF = 102	$M = \pm 20\%$				
LD13 - 1825	4000V = J		22,000  pF = 223	Z = +80%, -20%				
LD20 - 2220	5000V = K		220,000 pF = 224					
LD14 - 2225			$1 \mu F = 105$					
LD40 - 3640								

Notes: Capacitors with X7R dielectrics are not intended for applications across AC supply mains or AC line filtering with polarity reversal. Contact plant for recommendations. Contact factory for availability of Termination and Tolerance options for Specific Part Numbers.



### **DIMENSIONS**

### millimeters (inches)

SIZE	LD05 (0805)	LD06 (1206)	LD10* (1210)	LD08* (1808)	LD12* (1812)	LD13* (1825)	LD20* (2220)	LD25* (2225)	LD40* (3640)
(L) Length	2.01 ± 0.20	3.20 ± 0.20	3.20 ± 0.20	4.57 ± 0.25	4.50 ± 0.30	4.50 ± 0.30	5.70 ± 0.40	5.72 ± 0.25	9.14 ± 0.25
	(0.079 ± 0.008)	(0.126 ± 0.008)	(0.126 ± 0.008)	(0.180 ± 0.010)	(0.177 ± 0.012)	(0.177 ± 0.012)	(0.224 ± 0.016)	(0.225 ± 0.010)	(0.360 ± 0.010)
(W) Width	1.25 ± 0.20	1.60 ± 0.20	2.50 ± 0.20	2.03 ± 0.25	3.20 ± 0.20	6.40 ± 0.30	5.00 ± 0.40	6.35 ± 0.25	10.2 ± 0.25
	(0.049 ±0.008)	(0.063 ± 0.008)	(0.098 ± 0.008)	(0.080 ± 0.010)	(0.126 ± 0.008)	(0.252 ± 0.012)	(0.197 ± 0.016)	(0.250 ± 0.010)	(0.400 ± 0.010)
(T) Thickness	1.30	1.52	1.70	2.03	2.54	2.54	3.30	2.54	2.54
Max.	(0.051)	(0.060)	(0.067)	(0.080)	(0.100)	(0.100)	(0.130)	(0.100)	(0.100)
(t) terminal min. max.	$0.50 \pm 0.25$	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.76 (0.030)
	(0.020 ± 0.010)	0.75 (0.030)	0.75 (0.030)	1.02 (0.040)	1.02 (0.040)	1.02 (0.040)	1.02 (0.040)	1.02 (0.040)	1.52 (0.060)

<sup>\*</sup> Reflow soldering only.



# High Voltage MLC Chips Tin/Lead Termination "B"



### For 600V to 5000V Application

### **COG Dielectric**

### **Performance Characteristics**

Capacitance Range	10 pF to 0.047 μF
-	(25°C, 1.0 ±0.2 Vrms at 1kHz, for ≤ 1000 pF use 1 MHz)
Capacitance Tolerances	±5%, ±10%, ±20%
Dissipation Factor	0.1% max. ( $\pm$ 25°C, 1.0 $\pm$ 0.2 Vrms, 1kHz, for $\leq$ 1000 pF use 1 MHz)
Operating Temperature Range	-55°C to +125°C
Temperature Characteristic	0 ±30 ppm/°C (0 VDC)
Voltage Ratings	600, 630, 1000, 1500, 2000, 2500, 3000, 4000 & 5000 VDC (+125°C)
Insulation Resistance (+25°C, at 500 VDC)	100K M $\Omega$ min. or 1000 M $\Omega$ - $\mu F$ min., whichever is less
Insulation Resistance (+125°C, at 500 VDC)	10K M $\Omega$ min. or 100 M $\Omega$ - $\mu F$ min., whichever is less
Dielectric Strength	Minimum 120% rated voltage for 5 seconds at 50 mA max. current

### **HIGH VOLTAGE COG CAPACITANCE VALUES**

VOLTA	GE	LD05 (0805)	LD06 (1206)	LD10 (1210)	LD08 (1808)	LD12 (1812)	LD25 (1825)	LD20 (2220)	LD25 (2225)	LD40 (3640)
600/630	min.	10pF	10 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF	1000 pF
max.	max.	330pF	1200 pF	2700 pF	3300 pF	5600 pF	0.012 µF	0.012 µF	0.018 µF	0.047 µF
1000	min.	10pF	10 pF	10 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF
1000	max.	180pF	560 pF	1500 pF	2200 pF	3300 pF	8200 pF	0.010 μF	0.010 µF	0.022 µF
1500	min.	_	10 pF	10 pF	10 pF	10 pF	100 pF	100 pF	100 pF	100 pF
1300	max.	_	270 pF	680 pF	820 pF	1800 pF	4700 pF	4700 pF	5600 pF	0.010 µF
2000	min.	_	10 pF	10 pF	10 pF	10 pF	100 pF	100 pF	100 pF	100 pF
2000	max.	_	120 pF	270 pF	330 pF	680 pF	1800 pF	2200 pF	2700 pF	6800 pF
2500	min.	_	_		10 pF	10 pF	10 pF	100 pF	100 pF	100 pF
2000	max.	_	_		180 pF	470 pF	1200 pF	1500 pF	1800 pF	3900 pF
3000	min.	_			10 pF	100 pF				
3000	max.	_			120 pF	330 pF	820 pF	1000 pF	1200 pF	2700 pF
4000	min.	_			10 pF	100 pF				
4000	max.	_			47 pF	150 pF	330 pF	470 pF	560 pF	1200 pF
5000	min.	_	_	_	_	_	_	_	_	10 pF
3000	max.	_	_	_	_	_	_	_	_	820 pF

### **X7R Dielectric**

### **Performance Characteristics**

Capacitance Range	10 pF to 0.56 μF (25°C, 1.0 ±0.2 Vrms at 1kHz)
Capacitance Tolerances	±10%; ±20%; +80%, -20%
Dissipation Factor	2.5% max. (+25°C, 1.0 ±0.2 Vrms, 1kHz)
Operating Temperature Range	-55°C to +125°C
Temperature Characteristic	±15% (0 VDC)
Voltage Ratings	600, 630, 1000, 1500, 2000, 2500, 3000, 4000 & 5000 VDC (+125°C)
Insulation Resistance (+25°C, at 500 VDC)	100K M $\Omega$ min. or 1000 M $\Omega$ - $\mu$ F min., whichever is less
Insulation Resistance (+125°C, at 500 VDC)	10K M $\Omega$ min. or 100 M $\Omega$ - $\mu$ F min., whichever is less
Dielectric Strength	Minimum 120% rated voltage for 5 seconds at 50 mA max. current

### HIGH VOLTAGE X7R MAXIMUM CAPACITANCE VALUES

VOLTAGE	LD05 (0805)	LD06 (1206)	LD10 (1210)	LD08 (1808)	LD12 (1812)	LD25 (1825)	LD20 (2220)	LD25 (2225)	LD40 (3640)
600/630 min.		1000 pF	1000 pF	1000 pF	1000 pF	0.010 µF	0.010 µF	0.010 µF	0.010 µF
max.		0.022 µF	0.056 µF	0.068 µF	0.120 µF	0.270 µF	0.270 µF	0.330 µF	0.560 µF
1000 min.		100 pF	1000 pF	1000 pF	1000 pF	1000 pF	1000 pF	1000 pF	0.010 µF
max.	. 1500pF	6800 pF	0.015 µF	0.018 µF	0.039 µF	0.100 μF	0.120 μF	0.150 μF	0.220 µF
1500 min.	_	100 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF	1000 pF
max.	. —	2700 pF	6800 pF	6800 pF	0.015 µF	0.056 µF	0.056 µF	0.068 µF	0.100 µF
2000 min.	_	10 pF	100 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF
max.	. —	1500 pF	3900 pF	3300 pF	8200 pF	0.027 µF	0.027 µF	0.033 µF	0.027 µF
2500 min.	_	_	_	10 pF	10 pF	100 pF	100 pF	100 pF	1000 pF
max.	. —	_	_	2200 pF	5600 pF	0.015 µF	0.018 µF	0.022 µF	0.022 µF
3000 min.	_	_	_	10 pF	10 pF	100 pF	100 pF	100 pF	1000 pF
max.	.   —	_	_	1800 pF	4700 pF	0.012 µF	0.012 µF	0.015 µF	0.018 µF
4000 min.	_	_	_	_	_		_	_	100 pF
max.		_	_	_			_	_	6800 pF
5000 min.	_	_	_	_	_	_	_	_	100 pF
max.		_	_	_	_	_	_	_	3300 pF



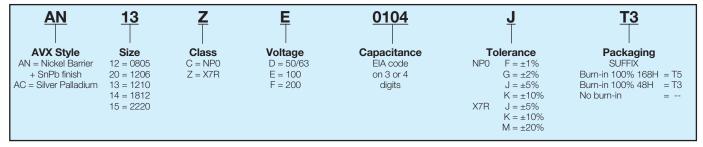
# **CECC Ceramic Chips**



### **FEATURES**

High Reliability CECC Ceramic Chips Capacitors for Military & Avionics applications

### **HOW TO ORDER**



### **QUALIFIED VS CECC 32101-801**

Class: NP0 + X7R (2C1/BX available on request)

Sizes: 0805, 1206, 1210, 1812, 2220 (0603 qualification pending)

Voltages: 50, 100, 200 (500V on request)

Terminations: Silver Palladium or Nickel barrier + tin lead finish

### **CAPACITANCE vs VOLTAGE TABLE**

Size		NP0*		X7R**				
	50V	100V	200V	50V	100V	200V		
0805	4.7 → 1500pF	4.7 → 1500pF	10 → 470pF	0.47 → 68nF	0.47 → 39nF	0.33 → 18nF		
1206	10 → 4700pF	10 → 4700pF	10 → 1500pF	1 → 180nF	1 → 100nF	0.1 → 39nF		
1210	10 → 8200pF	10 → 8200pF	22 → 2700pF	10 → 330nF	4.7 → 220nF	0.47 → 100nF		
1812	0.1 → 18nF	0.1 → 18nF	0.47 → 5.6nF	47 → 680nF	10 → 470nF	1 → 180nF		
2220	0.47 → 39nF	0.47 → 39nF	0.1 → 12nF	0.1 → 1.5µF	0.047 → 1µF	4.7 → 390nF		

<sup>\*</sup> NP0 Class (range available with tolerance: 1, 2, 5, 10%)

#### **Available Reliability Levels:**

Suffix: -- = qualified following CECC 32101-801 [no burn-in]

Suffix: T3 = according to CECC 32100-002 or 003; Established reliability level

(Equivalent to MIL-R) [100% burn-in: 48H @ 2 x Ur]

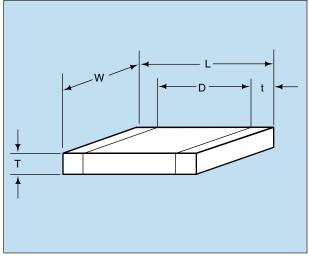
Suffix: T5 = according to CECC 32100-002 or 003; Established reliability level

(Equivalent to MIL-S) [100% burn-in: 168H @ 2 x Ur]

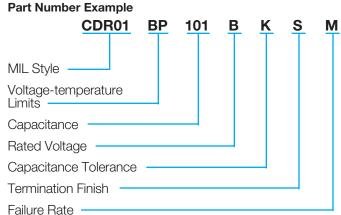
<sup>\*\*</sup> X7R Class (range available with tolerance: 5, 10, 20%)

# Part Number Example CDR01 thru CDR06





#### **MILITARY DESIGNATION PER MIL-PRF-55681**



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

MIL Style: CDR01, CDR02, CDR03, CDR04, CDR05, CDR06

#### **Voltage Temperature Limits:**

BP =  $0 \pm 30$  ppm/°C without voltage;  $0 \pm 30$  ppm/°C with rated voltage from -55°C to +125°C

BX =  $\pm 15\%$  without voltage; +15-25% with rated voltage from  $-55^{\circ}$ C to  $+125^{\circ}$ C

**Capacitance:** Two digit figures followed by multiplier (number of zeros to be added) e.g., 101 = 100 pF

Rated Voltage: A = 50V, B = 100V

Capacitance Tolerance:  $J \pm 5\%$ ,  $K \pm 10\%$ ,  $M \pm 20\%$ 

#### **Termination Finish:**

M = Palladium Silver N = Silver Nickel Gold S = Solder-coated

I Gold Metal/Solder Coated\*
ed W = Base Metallization/Barrier
Metal/Tinned (Tin or Tin/
Lead Alloy)

U = Base Metallization/Barrier

\*Solder shall have a melting point of 200°C or less.

Failure Rate Level: M = 1.0%, P = .1%, R = .01%, S = .001%

**Packaging:** Bulk is standard packaging. Tape and reel per RS481 is available upon request.

#### CROSS REFERENCE: AVX/MIL-PRF-55681/CDR01 THRU CDR06\*

Per	Per AVX Laurette (L) Military (L)	r AVX Lawrett (L) Mariette (AA) Thickness (T) D		Termination Band (t)					
MIL-PRF-55681	Style	Length (L)	Width (W)	Max.	Min.	Max.	Min.	Max.	Min.
CDR01	0805	.080 ± .015	$.050 \pm .015$	.055	.020	_	.030	_	.010
CDR02	1805	.180 ± .015	$.050 \pm .015$	.055	.020	_	_	.030	.010
CDR03	1808	.180 ± .015	$.080 \pm .018$	.080	.020	_	_	.030	.010
CDR04	1812	.180 ± .015	.125 ± .015	.080	.020	_	_	.030	.010
CDR05	1825	.180 +.020 015	.250 +.020 015	.080	.020	_	_	.030	.010
CDR06	2225	.225 ± .020	.250 ± .020	.080	.020	_	_	.030	.010

\*For CDR11, 12, 13, and 14 see AVX Microwave Chip Capacitor Catalog



# MIL-PRF-55681/Chips Military Part Number Identification CDR01 thru CDR06



### CDR01 thru CDR06 to MIL-PRF-55681

Military Type Designation	Type Capacitance Capacitance and voltage-		WVDC				
AVX Style 0805/CDR01							
CDR01BP100B CDR01BP150B CDR01BP180B CDR01BP220B CDR01BP270B CDR01BP330B CDR01BP390B CDR01BP470B CDR01BP470B	10 12 15 18 22 27 33 39 47	J,K J J,K J J,K J J,K	BP BP BP BP BP BP BP BP	100 100 100 100 100 100 100 100			
CDR01BP560B CDR01BP680B CDR01BP820B CDR01BP101B CDR01B121B CDR01B151B	56 68 82 100 120 150	J J,K J J,K J,K J,K	BP BP BP BP,BX BP,BX	100 100 100 100 100 100			
CDR01B181B	180	J,K	BP,BX	100			
CDR01BX221B	220	K,M	BX	100			
CDR01BX271B	270	K	BX	100			
CDR01BX331B	330	K,M	BX	100			
CDR01BX391B	390	K	BX	100			
CDR01BX471B	470	K,M	BX	100			
CDR01BX561B	560	K	BX	100			
CDR01BX681B	680	K,M	BX	100			
CDR01BX821B	820	K	BX	100			
CDR01BX102B	1000	K,M	BX	100			
CDR01BX122B	1200	K	BX	100			
CDR01BX152B	1500	K,M	BX	100			
CDR01BX182B	1800	K	BX	100			
CDR01BX222B	2200	K,M	BX	100			
CDR01BX272B	2700	K	BX	100			
CDR01BX332B	3300	K,M	BX	100			
CDR01BX392A	3900	K	BX	50			
CDR01BX472A	4700	K,M	BX	50			
AVX Style 18	805/CDR02						
CDR02BP221B	220	J,K	BP	100			
CDR02BP271B	270	J	BP	100			
CDR02BX392B	3900	K	BX	100			
CDR02BX472B	4700	K,M	BX	100			
CDR02BX562B	5600	K	BX	100			
CDR02BX682B	6800	K,M BX K BX K,M BX K BX K BX		100			
CDR02BX822B	8200			100			
CDR02BX103B	10,000			100			
CDR02BX123A	12,000			50			
CDR02BX153A	15,000			50			
CDR02BX183A	18,000	K	BX	50			
CDR02BX223A	22,000	K,M	BX	50			

·
Add appropriate failure rate
<ul> <li>Add appropriate termination finish</li> </ul>
Capacitance Tolerance

Military Type Capacitance Designation in pF		Capacitance tolerance	Rated temperature and voltage-temperature limits	WVDC		
AVX Style 1808/CDR03						
CDR03BP331B CDR03BP391B CDR03BP471B CDR03BP561B CDR03BP681B CDR03BP821B	330 390 470 560 680 820	J,K J J,K J J,K	BP BP BP BP BP	100 100 100 100 100		
CDR03BP102B CDR03BX123B CDR03BX153B CDR03BX183B	1000 12,000 15,000 18,000	J,K K K,M K	BP BX BX BX	100 100 100 100		
CDR03BX223B CDR03BX273B CDR03BX333B CDR03BX393A CDR03BX473A CDR03BX563A	223B 22,000 K,M BX 273B 27,000 K BX 333B 33,000 K,M BX 393A 39,000 K BX		100 100 100 50 50			
CDR03BX683A	56,000 68,000	K K,M	BX BX	50		
AVX Style 18	312/CDR04	I	T	ı		
CDR04BP122B CDR04BP152B CDR04BP182B CDR04BP222B CDR04BP272B	1200 1500 1800 2200 2700	J J,K J J,K J	BP BP BP BP BP	100 100 100 100 100		
CDR04BP332B CDR04BX393B CDR04BX473B CDR04BX563B CDR04BX823A	3300 39,000 47,000 56,000 82,000	J,K K K,M K K	BP BX BX BX BX	100 100 100 100 50		
CDR04BX104A CDR04BX124A CDR04BX154A CDR04BX184A	100,000 120,000 150,000 180,000	K,M K K,M K	BX BX BX BX	50 50 50 50		
AVX Style 18	325/CDR05					
CDR05BP392B CDR05BP472B CDR05BP562B CDR05BX683B CDR05BX823B	3900 4700 5600 68,000 82,000	J,K J,K J,K K,M	BP BP BP BX BX	100 100 100 100 100		
CDR05BX104B CDR05BX124B CDR05BX154B CDR05BX224A CDR05BX274A	100,000 120,000 150,000 220,000 270,000	K,M K K,M K,M	BX BX BX BX BX	100 100 100 50 50		
CDR05BX334A <b>AVX Style 2</b> 2	330,000 225/CDR06	K,M	BX	50		
CDR06BP682B CDR06BP822B CDR06BP103B CDR06BX394A CDR06BX474A	6800 8200 10,000 390,000 470,000	J,K J,K J,K K K,M	BP BP BP BX BX	100 100 100 50 50		

Add appropriate failure rate

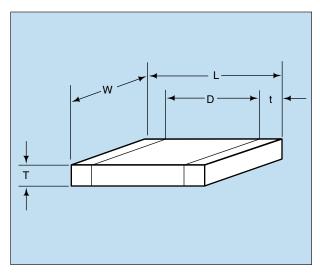
Add appropriate termination finish

- Capacitance Tolerance

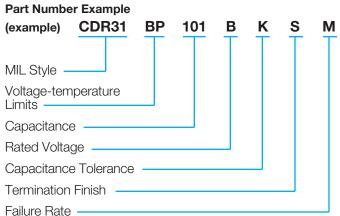


### **Part Number Example** CDR31 thru CDR35





#### MILITARY DESIGNATION PER MIL-PRF-55681



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

MIL Style: CDR31, CDR32, CDR33, CDR34, CDR35

#### **Voltage Temperature Limits:**

BP =  $0 \pm 30$  ppm/°C without voltage;  $0 \pm 30$  ppm/°C with rated voltage from -55°C to +125°C

BX =  $\pm 15\%$  without voltage; +15-25% with rated voltage from -55°C to +125°C

Capacitance: Two digit figures followed by multiplier (number of zeros to be added) e.g., 101 = 100 pF

Rated Voltage: A = 50V, B = 100V

Capacitance Tolerance:  $C \pm .25 pF$ ,  $D \pm .5 pF$ ,  $F \pm 1\%$ 

 $J \pm 5\%$ ,  $K \pm 10\%$ ,  $M \pm 20\%$ 

#### **Termination Finish:**

M = Palladium Silver N = Silver Nickel Gold

S = Solder-coated Y = 100% Tin

U = Base Metallization/Barrier Metal/Solder Coated\*

W = Base Metallization/Barrier Metal/Tinned (Tin or Tin/ Lead Alloy)

\*Solder shall have a melting point of 200°C or less.

**Failure Rate Level:** M = 1.0%, P = .1%, R = .01%, S = .001%

Packaging: Bulk is standard packaging. Tape and reel per RS481 is available upon request.

#### CROSS REFERENCE: AVX/MIL-PRF-55681/CDR31 THRU CDR35

Per MIL-PRF-55681	AVX	Length (L)	Width (W)	Thickness (T)	D	Terminatio	n Band (t)
(Metric Sizes)	Style	(mm)	(mm)	Max. (mm)	Min. (mm)	Max. (mm)	Min. (mm)
CDR31	0805	2.00	1.25	1.3	.50	.70	.30
CDR32	1206	3.20	1.60	1.3	_	.70	.30
CDR33	1210	3.20	2.50	1.5	_	.70	.30
CDR34	1812	4.50	3.20	1.5	_	.70	.30
CDR35	1825	4.50	6.40	1.5	_	.70	.30





## **Military Part Number Identification CDR31**

#### CDR31 to MIL-PRF-55681/7

Military Type Designation <u>1</u> /	Capacitance in pF	Capacitance tolerance	Rated temperature and voltage-temperature limits	WVDC
AVX Style 0	805/CDR31	(BP)		•
CDR31BP1R0B	1.0	B,C	BP	100
CDR31BP1R1B	1.1	B,C	BP	100
CDR31BP1R2B	1.2	B,C	BP	100
CDR31BP1R3B	1.3	B,C	BP	100
CDR31BP1R5B	1.5	B,C	BP	100
CDR31BP1R6B	1.6	B,C	BP	100
CDR31BP1R8B	1.8	B,C	BP	100
CDR31BP2R0B	2.0	B,C	BP	100
CDR31BP2R2B	2.2	B,C	BP	100
CDR31BP2R4B	2.4	B,C	BP	100
CDR31BP2R7B	2.7	B,C,D	BP	100
CDR31BP3R0B	3.0	B,C,D	BP	100
CDR31BP3R3B	3.3	B,C,D	BP	100
CDR31BP3R6B	3.6	B,C,D	BP	100
CDR31BP3R9B	3.9	B,C,D	BP	100
CDR31BP4R3B	4.3	B,C,D	BP	100
CDR31BP4R7B	4.7	B,C,D	BP	100
CDR31BP5R1B	5.1	B,C,D	BP	100
CDR31BP5R6B	5.6	B,C,D	BP	100
CDR31BP6R2B	6.2	B,C,D	BP	100
CDR31BP6R8B	6.8	B,C,D	BP	100
CDR31BP7R5B	7.5	B,C,D	BP	100
CDR31BP8R2B	8.2	B,C,D	BP	100
CDR31BP9R1B	9.1	B,C,D	BP	100
CDR31BP100B	10	F,J,K	BP	100
CDR31BP110B	11	F,J,K	BP	100
CDR31BP120B	12	F,J,K	BP	100
CDR31BP130B	13	F,J,K	BP	100
CDR31BP150B	15	F,J,K	BP	100
CDR31BP160B	16	F,J,K	BP	100
CDR31BP180B	18	F,J,K	BP	100
CDR31BP200B	20	F,J,K	BP	100
CDR31BP220B	22	F,J,K	BP	100
CDR31BP240B	24	F,J,K	BP	100
CDR31BP270B	27	F,J,K	BP	100
CDR31BP300B	30	F,J,K	BP	100
CDR31BP330B	33	F,J,K	BP	100
CDR31BP360B	36	F,J,K	BP	100
CDR31BP390B	39	F,J,K	BP	100
CDR31BP430B	43	F,J,K	BP	100
CDR31BP470B	47	F,J,K	BP	100
CDR31BP510B	51	F,J,K	BP	100
CDR31BP560B	56	F,J,K	BP	100
CDR31BP620B	62	F,J,K	BP	100
CDR31BP680B	68	F,J,K	BP	100
CDR31BP750B	75	F,J,K	BP	100
CDR31BP820B	82	F,J,K	BP	100
CDR31BP910B	91	F,J,K	BP	100

— Add appropriate failure rate

 — Add appropriate termination finish

 — Capacitance Tolerance

		Т		
Military Type Designation <u>1</u> /	Capacitance in pF	Capacitance tolerance	Rated temperature and voltage- temperature limits	WVDC
AVX Style 0	805/CDR31	(BP) cont	'd	
CDR31BP101B	100	F,J,K	BP	100
CDR31BP111B	110	F,J,K	BP	100
CDR31BP121B	120	F,J,K	BP	100
CDR31BP131B	130	F,J,K	BP	100
CDR31BP151B	150	F,J,K	BP	100
CDR31BP161B	160	F,J,K	BP	100
CDR31BP181B	180	F,J,K	BP	100
CDR31BP201B	200	F,J,K	BP	100
CDR31BP221B	220	F,J,K	BP	100
CDR31BP241B	240	F,J,K	BP	100
CDR31BP271B	270	F,J,K	BP	100
CDR31BP301B	300	F,J,K	BP	100
CDR31BP331B	330	F,J,K	BP	100
CDR31BP361B	360	F,J,K	BP	100
CDR31BP391B	390	F,J,K	BP	100
CDR31BP431B CDR31BP471B CDR31BP511A CDR31BP561A CDR31BP621A CDR31BP681A	430 470 510 560 620 680	F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP BP	100 100 50 50 50 50
AVX Style 0	805/CDR31	(BX)		
CDR31BX471B	470	K,M	BX	100
CDR31BX561B	560	K,M	BX	100
CDR31BX681B	680	K,M	BX	100
CDR31BX821B	820	K,M	BX	100
CDR31BX102B	1,000	K,M	BX	100
CDR31BX122B	1,200	K,M	BX	100
CDR31BX152B	1,500	K,M	BX	100
CDR31BX182B	1,800	K,M	BX	100
CDR31BX222B	2,200	K,M	BX	100
CDR31BX272B	2,700	K,M	BX	100
CDR31BX332B	3,300	K,M	BX	100
CDR31BX392B	3,900	K,M	BX	100
CDR31BX472B	4,700	K,M	BX	100
CDR31BX562A	5,600	K,M	BX	50
CDR31BX682A	6,800	K,M	BX	50
CDR31BX822A	8,200	K,M	BX	50
CDR31BX103A	10,000	K,M	BX	50
CDR31BX123A	12,000	K,M	BX	50
CDR31BX153A	15,000	K,M	BX	50
CDR31BX183A	18,000	K,M	BX	50

Add appropriate failure rate

- Add appropriate termination finish

- Capacitance Tolerance



<sup>1/</sup>The complete part number will include additional symbols to indicate capacitance tolerance, termination and failure rate level.



## **Military Part Number Identification CDR32**

#### CDR32 to MIL-PRF-55681/8

Military Type Designation <u>1</u> /	Capacitance in pF	Capacitance tolerance	Rated temperature and voltage-temperature limits	WVDC
AVX Style 1	206/CDR32	(BP)		
CDR32BP1R0B	1.0	B,C	BP	100
CDR32BP1R1B	1.1	B,C	BP	100
CDR32BP1R2B	1.2	B,C	BP	100
CDR32BP1R3B	1.3	B,C	BP	100
CDR32BP1R5B	1.5	B,C	BP	100
CDR32BP1R6B	1.6	B,C	BP	100
CDR32BP1R8B	1.8	B,C	BP	100
CDR32BP2R0B	2.0	B,C	BP	100
CDR32BP2R2B	2.2	B,C	BP	100
CDR32BP2R4B	2.4	B,C	BP	100
CDR32BP2R7B	2.7	B,C,D	BP	100
CDR32BP3R0B	3.0	B,C,D	BP	100
CDR32BP3R3B	3.3	B,C,D	BP	100
CDR32BP3R6B	3.6	B,C,D	BP	100
CDR32BP3R9B	3.9	B,C,D	BP	100
CDR32BP4R3B	4.3	B,C,D	BP	100
CDR32BP4R7B	4.7	B,C,D	BP	100
CDR32BP5R1B	5.1	B,C,D	BP	100
CDR32BP5R6B	5.6	B,C,D	BP	100
CDR32BP6R2B	6.2	B,C,D	BP	100
CDR32BP6R8B	6.8	B,C,D	BP	100
CDR32BP7R5B	7.5	B,C,D	BP	100
CDR32BP8R2B	8.2	B,C,D	BP	100
CDR32BP9R1B	9.1	B,C,D	BP	100
CDR32BP100B	10	F,J,K	BP	100
CDR32BP110B	11	F,J,K	BP	100
CDR32BP120B	12	F,J,K	BP	100
CDR32BP130B	13	F,J,K	BP	100
CDR32BP150B	15	F,J,K	BP	100
CDR32BP160B	16	F,J,K	BP	100
CDR32BP180B CDR32BP200B CDR32BP220B CDR32BP240B CDR32BP270B	18	F,J,K	BP	100
	20	F,J,K	BP	100
	22	F,J,K	BP	100
	24	F,J,K	BP	100
	27	F,J,K	BP	100
CDR32BP300B CDR32BP330B CDR32BP360B CDR32BP390B CDR32BP430B	30	F,J,K	BP	100
	33	F,J,K	BP	100
	36	F,J,K	BP	100
	39	F,J,K	BP	100
	43	F,J,K	BP	100
CDR32BP470B CDR32BP510B CDR32BP560B CDR32BP620B CDR32BP680B	47	F,J,K	BP	100
	51	F,J,K	BP	100
	56	F,J,K	BP	100
	62	F,J,K	BP	100
	68	F,J,K	BP	100
CDR32BP750B	75	F,J,K	BP	100
CDR32BP820B	82	F,J,K	BP	100
CDR32BP910B	91	F,J,K	BP	100

Add appropriate failure rate
 Add appropriate termination finish
 Capacitance Tolerance

Military Type Designation <u>1</u> /	Capacitance in pF	Capacitance tolerance	Rated temperature and voltage- temperature limits	WVDC			
AVX Style 1206/CDR32 (BP) cont'd							
CDR32BP101B CDR32BP111B CDR32BP121B CDR32BP131B CDR32BP151B CDR32BP161B	100 110 120 130 150	F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP BP	100 100 100 100 100			
CDR32BP181B CDR32BP201B CDR32BP221B CDR32BP2241B	180 200 220 240	F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP	100 100 100 100			
CDR32BP271B CDR32BP301B CDR32BP331B CDR32BP361B CDR32BP391B	270 300 330 360 390	F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP BP	100 100 100 100 100			
CDR32BP431B CDR32BP471B CDR32BP511B CDR32BP561B CDR32BP621B	430 470 510 560 620	F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP BP	100 100 100 100 100			
CDR32BP681B CDR32BP751B CDR32BP821B CDR32BP911B CDR32BP102B	680 750 820 910 1,000	F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP BP	100 100 100 100 100			
CDR32BP112A CDR32BP122A CDR32BP132A CDR32BP152A CDR32BP162A	1,100 1,200 1,300 1,500 1,600	F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP BP	50 50 50 50 50			
CDR32BP182A CDR32BP202A CDR32BP222A	1,800 2,000 2,200	F,J,K F,J,K F,J,K	BP BP BP	50 50 50			
AVX Style 1	206/CDR32	(BX)					
CDR32BX472B CDR32BX562B CDR32BX682B CDR32BX103B CDR32BX123B	4,700 5,600 6,800 8,200 10,000 12,000	K,M K,M K,M K,M K,M	BX BX BX BX BX	100 100 100 100 100			
CDR32BX153B CDR32BX183A CDR32BX223A CDR32BX273A CDR32BX333A CDR32BX393A	15,000 18,000 22,000 27,000 33,000 39,000	K,M K,M K,M K,M K,M	BX BX BX BX BX BX	100 50 50 50 50 50			
		l .					

Add appropriate failure rate

Add appropriate termination finish

Capacitance Tolerance



 $<sup>\</sup>underline{\mathbf{1}}/$  The complete part number will include additional symbols to indicate capacitance tolerance, termination and failure rate level.



### Military Part Number Identification CDR33/34/35

#### CDR33/34/35 to MIL-PRF-55681/9/10/11

Military Type Designation <u>1</u> /	Type Capacitance Capacitance and vo		Rated temperature and voltage- temperature limits	WVDC	
AVX Style 12	210/CDR33	(BP)			
CDR33BP102B CDR33BP112B CDR33BP132B CDR33BP152B CDR33BP162B CDR33BP182B CDR33BP202B CDR33BP202B CDR33BP242A	1,000 1,100 1,200 1,300 1,500 1,600 1,800 2,000 2,200 2,400	F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP BP BP BP BP BP	100 100 100 100 100 100 100 100 100 50	
CDR33BP272A CDR33BP302A CDR33BP332A	2,700 3,000 3,300	F,J,K F,J,K F,J,K	BP BP BP	50 50 50	
AVX Style 12	210/CDR33	(BX)			
CDR33BX153B CDR33BX223B CDR33BX223B CDR33BX273B CDR33BX473A CDR33BX563A CDR33BX683A CDR33BX823A CDR33BX104A	15,000 18,000 22,000 27,000 39,000 47,000 56,000 68,000 82,000 100,000	K,M K,M K,M K,M K,M K,M K,M K,M	BX BX BX BX BX BX BX BX BX BX	100 100 100 100 50 50 50 50 50 50	
AVX Style 18	812/CDR34	(BP)			
CDR34BP222B CDR34BP242B CDR34BP272B CDR34BP302B CDR34BP332B CDR34BP392B CDR34BP432B CDR34BP472B	2,200 2,400 2,700 3,000 3,300 3,600 3,900 4,300 4,700	F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP BP BP BP BP	100 100 100 100 100 100 100 100	
CDR34BP512A CDR34BP562A CDR34BP622A CDR34BP752A CDR34BP822A CDR34BP912A CDR34BP912A CDR34BP9103A	5,100 5,600 6,200 6,800 7,500 8,200 9,100 10,000	F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP BP BP BP	50 50 50 50 50 50 50 50	
Add appropriate failure rate  Add appropriate termination finish  Capacitance Tolerance					

Military Type Designation <u>1</u> /	Capacitance in pF	Capacitance tolerance	Rated temperature and voltage-temperature limits	WVDC
AVX Style 1	812/CDR34	(BX)		
CDR34BX273B CDR34BX333B CDR34BX473B CDR34BX563B CDR34BX104A CDR34BX124A CDR34BX154A CDR34BX184A	27,000 33,000 39,000 47,000 56,000 100,000 120,000 150,000 180,000	K,M K,M K,M K,M K,M K,M K,M K,M	BX BX BX BX BX BX BX BX BX	100 100 100 100 100 50 50 50
AVX Style 1	825/CDR35	(BP)		
CDR35BP472B CDR35BP562B CDR35BP622B CDR35BP682B CDR35BP752B CDR35BP912B CDR35BP113A CDR35BP13A CDR35BP153A CDR35BP163A CDR35BP183A CDR35BP183A CDR35BP183A CDR35BP183A CDR35BP183A CDR35BP183A CDR35BP183A CDR35BP183A CDR35BP183A	4,700 5,100 5,600 6,200 6,800 7,500 8,200 9,100 10,000 11,000 12,000 13,000 16,000 18,000 20,000 22,000	F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K F,J,K	BP BP BP BP BP BP BP BP BP BP BP BP BP B	100 100 100 100 100 100 100 100 50 50 50 50 50 50
AVX Style 18	825/CDR35	(BX)		
CDR35BX563B CDR35BX683B CDR35BX823B CDR35BX104B CDR35BX124B CDR35BX154B CDR35BX224A CDR35BX224A CDR35BX334A CDR35BX394A CDR35BX394A CDR35BX35BX474A	56,000 68,000 82,000 100,000 120,000 150,000 180,000 220,000 270,000 330,000 470,000	K,M K,M K,M K,M K,M K,M K,M K,M K,M K,M	BX BX BX BX BX BX BX BX BX BX BX BX	100 100 100 100 100 100 50 50 50 50 50

- Add appropriate failure rate

Add appropriate termination finish

- Capacitance Tolerance



 $<sup>\</sup>underline{\bf 1}/$  The complete part number will include additional symbols to indicate capacitance tolerance, termination and failure rate level.

## **Packaging of Chip Components**



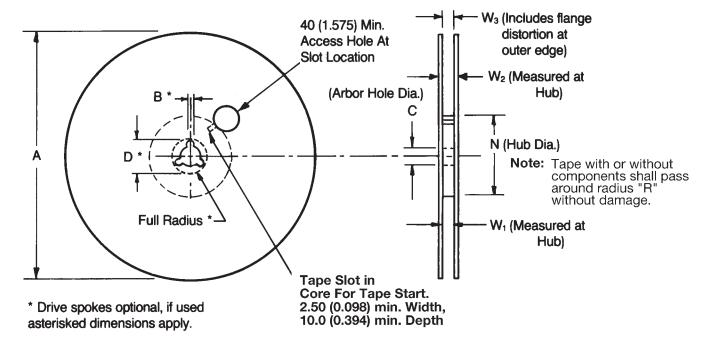
### **Automatic Insertion Packaging**

#### **TAPE & REEL QUANTITIES**

All tape and reel specifications are in compliance with RS481.

	8mm	121	mm
Paper or Embossed Carrier	0612, 0508, 0805, 1206, 1210		
Embossed Only		1808	1812, 1825 2220, 2225
Paper Only	0201, 0306, 0402, 0603		
Qty. per Reel/7" Reel	2,000, 3,000 or 4,000, 10,000, 15,000 Contact factory for exact quantity	3,000	500, 1,000 Contact factory for exact quantity
Qty. per Reel/13" Reel	5,000, 10,000, 50,000 Contact factory for exact quantity	10,000	4,000

#### **REEL DIMENSIONS**



Tape Size <sup>(1)</sup>	A Max.	B* Min.	С	D* Min.	N Min.	W <sub>1</sub>	W <sub>2</sub> Max.	W <sub>3</sub>
8mm	330	1.5	13.0 <sup>+0.50</sup>	20.2	50.0	8.40 ±1.5 (0.331 ±0.059)	14.4 (0.567)	7.90 Min. (0.311) 10.9 Max. (0.429)
12mm	(12.992)	(0.059)	(0.512 -0.008)	(0.795)	(1.969)	12.4 +2.0 (0.488 +0.079)	18.4 (0.724)	11.9 Min. (0.469) 15.4 Max. (0.607)

Metric dimensions will govern.

English measurements rounded and for reference only.

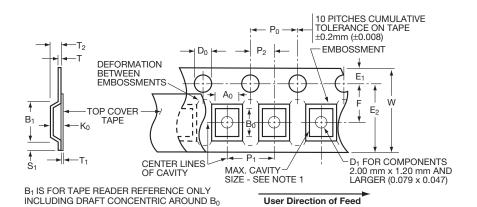
<sup>(1)</sup> For tape sizes 16mm and 24mm (used with chip size 3640) consult EIA RS-481 latest revision.

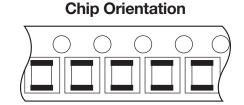


## **Embossed Carrier Configuration**



### 8 & 12mm Tape Only





### 8 & 12mm Embossed Tape Metric Dimensions Will Govern

#### **CONSTANT DIMENSIONS**

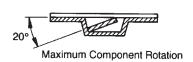
Tape Size	D <sub>0</sub>	E	Po	P <sub>2</sub>	S <sub>1</sub> Min.	T Max.	T <sub>1</sub>
8mm and 12mm	1.50 <sup>+0.10</sup> <sub>-0.0</sub> (0.059 <sup>+0.004</sup> )	1.75 ± 0.10 (0.069 ± 0.004)	$4.0 \pm 0.10 \\ (0.157 \pm 0.004)$	$2.0 \pm 0.05$ (0.079 ± 0.002)	0.60 (0.024)	0.60 (0.024)	0.10 (0.004) Max.

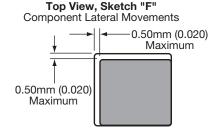
#### VARIABLE DIMENSIONS

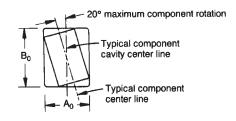
Tape Size	B₁ Max.	D₁ Min.	E <sub>2</sub> Min.	F	P <sub>1</sub> See Note 5	R Min. See Note 2	T <sub>2</sub>	W Max.	A <sub>0</sub> B <sub>0</sub> K <sub>0</sub>
8mm	4.35 (0.171)	1.00 (0.039)	6.25 (0.246)	$3.50 \pm 0.05 \\ (0.138 \pm 0.002)$	4.00 ± 0.10 (0.157 ± 0.004)	25.0 (0.984)	2.50 Max. (0.098)	8.30 (0.327)	See Note 1
12mm	8.20 (0.323)	1.50 (0.059)	10.25 (0.404)	5.50 ± 0.05 (0.217 ± 0.002)	4.00 ± 0.10 (0.157 ± 0.004)	30.0 (1.181)	6.50 Max. (0.256)	12.3 (0.484)	See Note 1
8mm 1/2 Pitch	4.35 (0.171)	1.00 (0.039)	6.25 (0.246)	$3.50 \pm 0.05$ (0.138 ± 0.002)	$2.00 \pm 0.10$ (0.079 ± 0.004)	25.0 (0.984)	2.50 Max. (0.098)	8.30 (0.327)	See Note 1
12mm Double Pitch	8.20 (0.323)	1.50 (0.059)	10.25 (0.404)	5.50 ± 0.05 (0.217 ± 0.002)	8.00 ± 0.10 (0.315 ± 0.004)	30.0 (1.181)	6.50 Max. (0.256)	12.3 (0.484)	See Note 1

#### NOTES

- 1. The cavity defined by  $A_0$ ,  $B_0$ , and  $K_0$  shall be configured to provide the following: Surround the component with sufficient clearance such that:
  - a) the component does not protrude beyond the sealing plane of the cover tape.
  - b) the component can be removed from the cavity in a vertical direction without mechanical restriction, after the cover tape has been removed.
  - c) rotation of the component is limited to 20° maximum (see Sketches D & E).
  - d) lateral movement of the component is restricted to 0.5mm maximum (see Sketch F).
- 2. Tape with or without components shall pass around radius "R" without damage.
- Bar code labeling (if required) shall be on the side of the reel opposite the round sprocket holes. Refer to EIA-556.
- 4. B<sub>1</sub> dimension is a reference dimension for tape feeder clearance only.
- 5. If  $P_{\scriptscriptstyle 1}=2.0\text{mm},$  the tape may not properly index in all tape feeders.





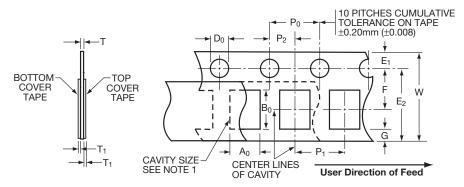




## **Paper Carrier Configuration**







# 8 & 12mm Paper Tape Metric Dimensions Will Govern

#### **CONSTANT DIMENSIONS**

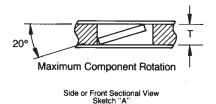
Tape Size	D <sub>0</sub>	E	P <sub>0</sub>	P <sub>2</sub>	T <sub>1</sub>	G. Min.	R Min.
8mm and 12mm	1.50 ±0.10 (0.059 ±0.004)	1.75 ± 0.10 (0.069 ± 0.004)	4.00 ± 0.10 (0.157 ± 0.004)	2.00 ± 0.05 (0.079 ± 0.002)	0.10 (0.004) Max.	0.75 (0.030) Min.	25.0 (0.984) See Note 2 Min.

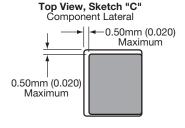
#### **VARIABLE DIMENSIONS**

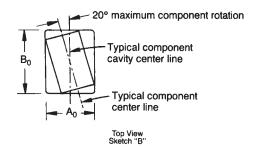
Tape Size	P <sub>1</sub> See Note 4	E <sub>2</sub> Min.	F	W	$A_0 B_0$	Т
8mm	4.00 ± 0.10 (0.157 ± 0.004)	6.25 (0.246)	$3.50 \pm 0.05$ $(0.138 \pm 0.002)$	8.00 <sup>+0.30</sup> (0.315 <sup>+0.012</sup> )	See Note 1	1.10mm
12mm	4.00 ± 0.010 (0.157 ± 0.004)	10.25 (0.404)	5.50 ± 0.05 (0.217 ± 0.002)	12.0 ± 0.30 (0.472 ± 0.012)		(0.043) Max. for Paper Base Tape and
8mm 1/2 Pitch	2.00 ± 0.05 (0.079 ± 0.002)	6.25 (0.246)	3.50 ± 0.05 (0.138 ± 0.002)	8.00 ±0.30 (0.315 ±0.012)		1.60mm (0.063) Max. for Non-Paper Base Compositions
12mm Double Pitch	8.00 ± 0.10 (0.315 ± 0.004)	10.25 (0.404)	5.50 ± 0.05 (0.217 ± 0.002)	12.0 ± 0.30 (0.472 ± 0.012)		Dase Compositions

#### NOTES

- 1. The cavity defined by  $A_0$ ,  $B_0$ , and T shall be configured to provide sufficient clearance surrounding the component so that:
  - a) the component does not protrude beyond either surface of the carrier tape; b) the component can be removed from the cavity in a vertical direction without
  - mechanical restriction after the top cover tape has been removed; c) rotation of the component is limited to 20° maximum (see Sketches A & B);
  - d) lateral movement of the component is restricted to 0.5mm maximum (see Sketch C).
- 2. Tape with or without components shall pass around radius "R" without damage.
- Bar code labeling (if required) shall be on the side of the reel opposite the sprocket holes. Refer to EIA-556.
- 4. If  $P_1 = 2.0$ mm, the tape may not properly index in all tape feeders.







### **Bar Code Labeling Standard**

AVX bar code labeling is available and follows latest version of EIA-556



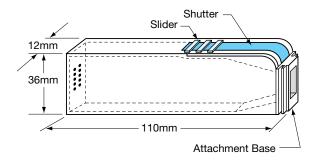
# **Bulk Case Packaging**



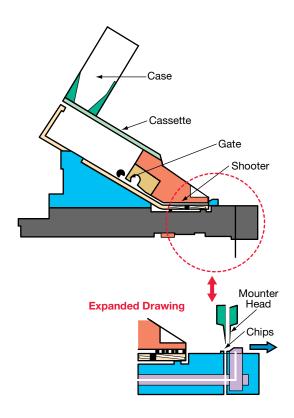
#### **BENEFITS**

- Easier handling
- Smaller packaging volume (1/20 of T/R packaging)
- Easier inventory control
- Flexibility
- Recyclable

#### **CASE DIMENSIONS**



### **BULK FEEDER**



### **CASE QUANTITIES**

Part Size	0402	0603	0805	1206
Qty. (pcs / cassette)	80,000	15,000	10,000 (T=.023") 8,000 (T=.031") 6,000 (T=.043")	5,000 (T=.023") 4,000 (T=.032") 3,000 (T=.044")



## **Basic Capacitor Formulas**



#### I. Capacitance (farads)

English: 
$$C = \frac{.224 \text{ K A}}{T_D}$$
Metric:  $C = \frac{.0884 \text{ K A}}{T_D}$ 

### II. Energy stored in capacitors (Joules, watt - sec)

#### III. Linear charge of a capacitor (Amperes)

$$I = C \frac{dV}{dt}$$

#### IV. Total Impedance of a capacitor (ohms)

$$Z = \sqrt{R_S^2 + (X_C - X_I)^2}$$

#### V. Capacitive Reactance (ohms)

$$x_C = \frac{1}{2 \pi fC}$$

#### VI. Inductive Reactance (ohms)

$$x_L=2\;\pi\;fL$$

#### VII. Phase Angles:

Ideal Capacitors: Current leads voltage 90° Ideal Inductors: Current lags voltage 90° Ideal Resistors: Current in phase with voltage

#### **VIII. Dissipation Factor (%)**

D.F.= tan 
$$\delta$$
 (loss angle) =  $\frac{\text{E.S.R.}}{X_{\text{C}}}$  = (2  $\pi$ fC) (E.S.R.)

#### IX. Power Factor (%)

P.F. = Sine  $\delta$  (loss angle) = Cos  $\phi$  (phase angle) P.F. = (when less than 10%) = DF

#### X. Quality Factor (dimensionless)

Q = Cotan 
$$\delta$$
 (loss angle) =  $\frac{1}{D.F.}$ 

#### XI. Equivalent Series Resistance (ohms)

E.S.R. = (D.F.) (Xc) = (D.F.) / (2 
$$\pi$$
 fC)

#### XII. Power Loss (watts)

Power Loss = 
$$(2 \pi fCV^2)$$
 (D.F.)

#### XIII. KVA (Kilowatts)

$$KVA = 2 \pi fCV^2 \times 10^{-3}$$

#### XIV. Temperature Characteristic (ppm/°C)

$$T.C. = \frac{Ct - C_{25}}{C_{25} (T_t - 25)} \times 10^6$$

#### XV. Cap Drift (%)

C.D. = 
$$\frac{C_1 - C_2}{C_1}$$
 x 100

XVI. Reliability of Ceramic Capacitors 
$$\overset{L_o}{\bar{L}_t} = \left(\frac{V_t}{V_o}\right) \overset{X}{X} \quad \left(\frac{T_t}{T_o}\right) \overset{Y}{X}$$

#### XVII. Capacitors in Series (current the same)

Any Number: 
$$\frac{1}{C_{T}} = \frac{1}{C_{1}} + \frac{1}{C_{2}} - \frac{1}{C_{N}}$$
  
Two:  $C_{T} = \frac{C_{1} C_{2}}{C_{1} + C_{2}}$ 

#### XVIII. Capacitors in Parallel (voltage the same)

$$C_T = C_1 + C_2 - - + C_N$$

#### XIX. Aging Rate

A.R. =  $\%\Delta$  C/decade of time

#### XX. Decibels

$$db = 20 \log \frac{V_1}{V_2}$$

#### **METRIC PREFIXES SYMBOLS**

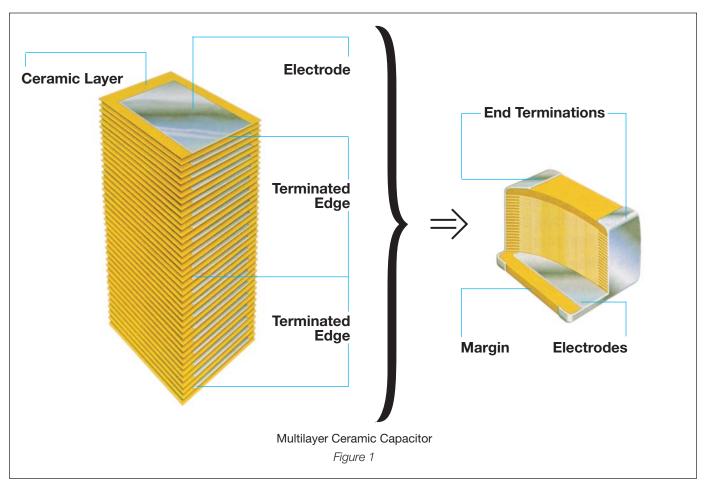
Pico	X 10 <sup>-12</sup>
Nano	X 10 <sup>-9</sup>
Micro	X 10 <sup>-6</sup>
Milli	X 10 <sup>-3</sup>
Deci	X 10 <sup>-1</sup>
Deca	X 10 <sup>+1</sup>
Kilo	X 10 <sup>+3</sup>
Mega	X 10 <sup>+6</sup>
Giga	X 10 <sup>+9</sup>
Tera	X 10 <sup>+12</sup>





**Basic Construction -** A multilayer ceramic (MLC) capacitor is a monolithic block of ceramic containing two sets of offset, interleaved planar electrodes that extend to two opposite surfaces of the ceramic dielectric. This simple

structure requires a considerable amount of sophistication, both in material and manufacture, to produce it in the quality and quantities needed in today's electronic equipment.



**Formulations -** Multilayer ceramic capacitors are available in both Class 1 and Class 2 formulations. Temperature compensating formulation are Class 1 and temperature stable and general application formulations are classified as Class 2.

Class 1 – Class 1 capacitors or temperature compensating capacitors are usually made from mixtures of titanates where barium titanate is normally not a major part of the mix. They have predictable temperature coefficients and in general, do not have an aging characteristic. Thus they are the most stable capacitor available. The most popular Class 1 multilayer ceramic capacitors are COG (NPO) temperature compensating capacitors (negative-positive 0 ppm/°C).

**Class 2 –** EIA Class 2 capacitors typically are based on the chemistry of barium titanate and provide a wide range of capacitance values and temperature stability. The most commonly used Class 2 dielectrics are X7R and Y5V. The X7R provides intermediate capacitance values which vary only ±15% over the temperature range of -55°C to 125°C. It finds applications where stability over a wide temperature range is required.

The Y5V provides the highest capacitance values and is used in applications where limited temperature changes are expected. The capacitance value for Y5V can vary from 22% to -82% over the -30°C to 85°C temperature range.

All Class 2 capacitors vary in capacitance value under the influence of temperature, operating voltage (both AC and DC), and frequency. For additional information on performance changes with operating conditions, consult AVX's software, SpiCap.





Table 1: EIA and MIL Temperature Stable and General Application Codes

EIA CODE Percent Capacity Change Over Temperature Range					
RS198	Temperature Range				
X7	-55°C to +125°C				
X6 X5	-55°C to +105°C -55°C to +85°C				
Y5 Z5	-30°C to +85°C +10°C to +85°C				
Code	Percent Capacity Change				
- Coue	Percent Capacity Change				
D	±3.3%				
E	±4.7%				
F	±7.5%				
Р	±10%				
R	±15%				
S	±22%				
T	+22%, -33%				
U	+22%, - 56%				
V	+22%, -82%				

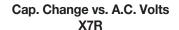
EXAMPLE – A capacitor is desired with the capacitance value at  $25^{\circ}$ C to increase no more than 7.5% or decrease no more than 7.5% from -30°C to +85°C. EIA Code will be Y5F.

MIL CODE							
Symbol	Temperati	Temperature Range					
A B C	-55°C to +85°C -55°C to +125°C -55°C to +150°C						
Symbol	Cap. Change Zero Volts	Cap. Change Rated Volts					
R S W X Y Z	+15%, -15% +22%, -22% +22%, -56% +15%, -15% +30%, -70% +20%, -20%	+15%, -40% +22%, -56% +22%, -66% +15%, -25% +30%, -80% +20%, -30%					

Temperature characteristic is specified by combining range and change symbols, for example BR or AW. Specification slash sheets indicate the characteristic applicable to a given style of capacitor.

In specifying capacitance change with temperature for Class 2 materials, EIA expresses the capacitance change over an operating temperature range by a 3 symbol code. The first symbol represents the cold temperature end of the temperature range, the second represents the upper limit of the operating temperature range and the third symbol represents the capacitance change allowed over the operating temperature range. Table 1 provides a detailed explanation of the EIA system.

**Effects of Voltage –** Variations in voltage have little effect on Class 1 dielectric but does affect the capacitance and dissipation factor of Class 2 dielectrics. The application of DC voltage reduces both the capacitance and dissipation factor while the application of an AC voltage within a reasonable range tends to increase both capacitance and dissipation factor readings. If a high enough AC voltage is applied, eventually it will reduce capacitance just as a DC voltage will. Figure 2 shows the effects of AC voltage.



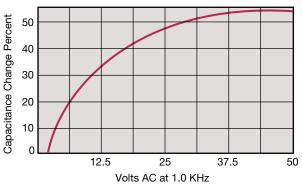
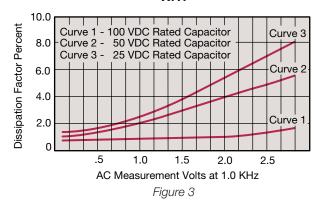


Figure 2

Capacitor specifications specify the AC voltage at which to measure (normally 0.5 or 1 VAC) and application of the wrong voltage can cause spurious readings. Figure 3 gives the voltage coefficient of dissipation factor for various AC voltages at 1 kilohertz. Applications of different frequencies will affect the percentage changes versus voltages.

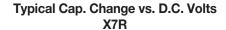
## D.F. vs. A.C. Measurement Volts X7R

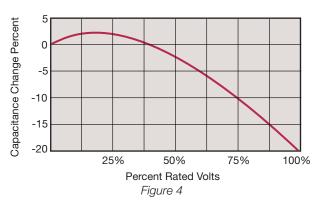


Typical effect of the application of DC voltage is shown in Figure 4. The voltage coefficient is more pronounced for higher K dielectrics. These figures are shown for room temperature conditions. The combination characteristic known as voltage temperature limits which shows the effects of rated voltage over the operating temperature range is shown in Figure 5 for the military BX characteristic.

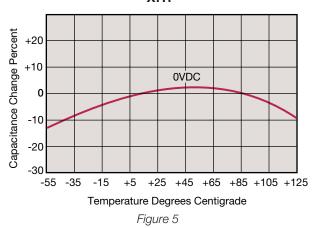








Typical Cap. Change vs. Temperature X7R



**Effects of Time -** Class 2 ceramic capacitors change capacitance and dissipation factor with time as well as temperature, voltage and frequency. This change with time is known as aging. Aging is caused by a gradual re-alignment of the crystalline structure of the ceramic and produces an exponential loss in capacitance and decrease in dissipation factor versus time. A typical curve of aging rate for semistable ceramics is shown in Figure 6.

If a Class 2 ceramic capacitor that has been sitting on the shelf for a period of time, is heated above its curie point, (125°C for 4 hours or 150°C for ½ hour will suffice) the part will de-age and return to its initial capacitance and dissipation factor readings. Because the capacitance changes rapidly, immediately after de-aging, the basic capacitance measurements are normally referred to a time period sometime after the de-aging process. Various manufacturers use different time bases but the most popular one is one day or twenty-four hours after "last heat." Change in the aging curve can be caused by the application of voltage and other stresses. The possible changes in capacitance due to de-aging by heating the unit explain why capacitance changes are allowed after test, such as temperature cycling, moisture resistance, etc., in MIL specs. The application of high voltages such as dielectric withstanding voltages also

tends to de-age capacitors and is why re-reading of capacitance after 12 or 24 hours is allowed in military specifications after dielectric strength tests have been performed.

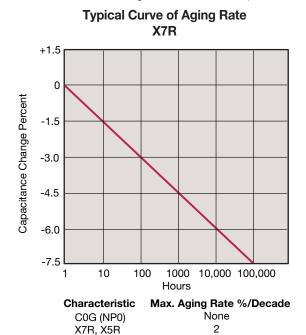


Figure 6

Y5V

**Effects of Frequency –** Frequency affects capacitance and impedance characteristics of capacitors. This effect is much more pronounced in high dielectric constant ceramic formulation than in low K formulations. AVX's SpiCap software generates impedance, ESR, series inductance, series resonant frequency and capacitance all as functions of frequency, temperature and DC bias for standard chip sizes and styles. It is available free from AVX and can be downloaded for free from AVX website: www.avx.com.







Effects of Mechanical Stress - High "K" dielectric ceramic capacitors exhibit some low level piezoelectric reactions under mechanical stress. As a general statement, the piezoelectric output is higher, the higher the dielectric constant of the ceramic. It is desirable to investigate this effect before using high "K" dielectrics as coupling capacitors in extremely low level applications.

Reliability - Historically ceramic capacitors have been one of the most reliable types of capacitors in use today. The approximate formula for the reliability of a ceramic capacitor is:

$$\frac{L_o}{L_t} = \left(\frac{V_t}{V_o}\right)^X \left(\frac{T_t}{T_o}\right)^Y$$

where

 $L_o$  = operating life

 $egin{aligned} oldsymbol{T_t} = \text{test temperature and} \\ oldsymbol{T_o} = \text{operating temperature} \end{aligned}$ **L**<sub>t</sub> = test life

**V**<sub>t</sub> = test voltage

 $V_o$  = operating voltage X,Y = see text

Historically for ceramic capacitors exponent X has been considered as 3. The exponent Y for temperature effects typically tends to run about 8.

A capacitor is a component which is capable of storing electrical energy. It consists of two conductive plates (electrodes) separated by insulating material which is called the dielectric. A typical formula for determining capacitance is:

$$C = \frac{.224 \text{ KA}}{t}$$

**C** = capacitance (picofarads)

**K** = dielectric constant (Vacuum = 1)

**A** = area in square inches

**t** = separation between the plates in inches (thickness of dielectric)

.224 = conversion constant

(.0884 for metric system in cm)

Capacitance - The standard unit of capacitance is the farad. A capacitor has a capacitance of 1 farad when 1 coulomb charges it to 1 volt. One farad is a very large unit and most capacitors have values in the micro (10-6), nano (10<sup>-9</sup>) or pico (10<sup>-12</sup>) farad level.

**Dielectric Constant –** In the formula for capacitance given above the dielectric constant of a vacuum is arbitrarily chosen as the number 1. Dielectric constants of other materials are then compared to the dielectric constant of a vacuum.

Dielectric Thickness - Capacitance is indirectly proportional to the separation between electrodes. Lower voltage requirements mean thinner dielectrics and greater capacitance per volume.

Area - Capacitance is directly proportional to the area of the electrodes. Since the other variables in the equation are usually set by the performance desired, area is the easiest parameter to modify to obtain a specific capacitance within a material group.

Energy Stored - The energy which can be stored in a capacitor is given by the formula:

$$E = \frac{1}{2}CV^2$$

**E** = energy in joules (watts-sec)

V = applied voltage

**C** = capacitance in farads

Potential Change - A capacitor is a reactive component which reacts against a change in potential across it. This is shown by the equation for the linear charge of a capacitor:

$$I_{ideal} = C \frac{dV}{dt}$$

where

I = Current

**C** = Capacitance

dV/dt = Slope of voltage transition across capacitor

Thus an infinite current would be required to instantly change the potential across a capacitor. The amount of current a capacitor can "sink" is determined by the above equation.

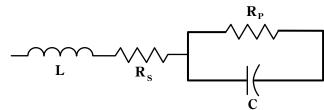
Equivalent Circuit - A capacitor, as a practical device, exhibits not only capacitance but also resistance and inductance. A simplified schematic for the equivalent circuit

**C** = Capacitance

**L** = Inductance

 $\mathbf{R}_{\mathbf{s}}$  = Series Resistance

 $\mathbf{R}_{\mathbf{p}}$  = Parallel Resistance



**Reactance** – Since the insulation resistance (R<sub>n</sub>) is normally very high, the total impedance of a capacitor is:

$$Z = \sqrt{R_s^2 + (X_c - X_L)^2}$$
 where

**Z** = Total Impedance

 $\mathbf{R_s}$  = Series Resistance  $\mathbf{X_c}$  = Capacitive Reactance =  $\frac{1}{2 \pi \text{ fC}}$ 

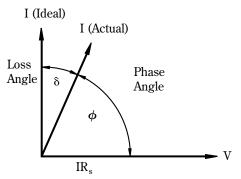
 $X_i$  = Inductive Reactance =  $2 \pi fL$ 

The variation of a capacitor's impedance with frequency determines its effectiveness in many applications.

Phase Angle - Power Factor and Dissipation Factor are often confused since they are both measures of the loss in a capacitor under AC application and are often almost identical in value. In a "perfect" capacitor the current in the capacitor will lead the voltage by 90°.





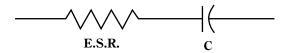


In practice the current leads the voltage by some other phase angle due to the series resistance  $R_{\rm s}$ . The complement of this angle is called the loss angle and:

Power Factor (P.F.) = Cos  $\phi$  or Sine  $\delta$  Dissipation Factor (D.F.) =  $\tan \delta$ 

for small values of  $\delta$  the tan and sine are essentially equal which has led to the common interchangeability of the two terms in the industry.

**Equivalent Series Resistance -** The term E.S.R. or Equivalent Series Resistance combines all losses both series and parallel in a capacitor at a given frequency so that the equivalent circuit is reduced to a simple R-C series connection.



**Dissipation Factor -** The DF/PF of a capacitor tells what percent of the apparent power input will turn to heat in the capacitor.

Dissipation Factor = 
$$\frac{\text{E.S.R.}}{\text{X}_c}$$
 = (2  $\pi$  fC) (E.S.R.)

The watts loss are:

Watts loss = 
$$(2 \pi fCV^2)$$
 (D.F.)

Very low values of dissipation factor are expressed as their reciprocal for convenience. These are called the "Q" or Quality factor of capacitors.

**Parasitic Inductance –** The parasitic inductance of capacitors is becoming more and more important in the decoupling of today's high speed digital systems. The relationship between the inductance and the ripple voltage induced on the DC voltage line can be seen from the simple inductance equation:

$$V = L \frac{di}{dt}$$

The  $\frac{dl}{dt}$  seen in current microprocessors can be as high as 0.3 A/ns, and up to 10A/ns. At 0.3 A/ns, 100pH of parasitic inductance can cause a voltage spike of 30mV. While this does not sound very drastic, with the Vcc for microprocessors decreasing at the current rate, this can be a fairly large percentage.

Another important, often overlooked, reason for knowing the parasitic inductance is the calculation of the resonant frequency. This can be important for high frequency, bypass capacitors, as the resonant point will give the most signal attenuation. The resonant frequency is calculated from the simple equation:

$$f_{\text{res}} = \frac{1}{2\pi\sqrt{LC}}$$

Insulation Resistance - Insulation Resistance is the resistance measured across the terminals of a capacitor and consists principally of the parallel resistance Rp shown in the equivalent circuit. As capacitance values and hence the area of dielectric increases, the I.R. decreases and hence the product (C x IR or RC) is often specified in ohm farads or more commonly megohm-microfarads. Leakage current is determined by dividing the rated voltage by IR (Ohm's Law).

**Dielectric Strength -** Dielectric Strength is an expression of the ability of a material to withstand an electrical stress. Although dielectric strength is ordinarily expressed in volts, it is actually dependent on the thickness of the dielectric and thus is also more generically a function of volts/mil.

**Dielectric Absorption -** A capacitor does not discharge instantaneously upon application of a short circuit, but drains gradually after the capacitance proper has been discharged. It is common practice to measure the dielectric absorption by determining the "reappearing voltage" which appears across a capacitor at some point in time after it has been fully discharged under short circuit conditions.

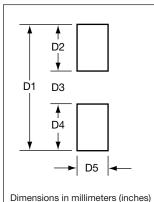
**Corona -** Corona is the ionization of air or other vapors which causes them to conduct current. It is especially prevalent in high voltage units but can occur with low voltages as well where high voltage gradients occur. The energy discharged degrades the performance of the capacitor and can in time cause catastrophic failures.



### **MLC Chip Capacitors**



#### **REFLOW SOLDERING**



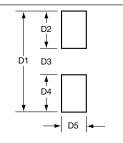
Case Size	D1	D2	D3	D4	D5
0201	0.85 (0.033)	0.30 (0.012)	0.25 (0.010)	0.30 (0.014)	0.35 (0.014)
0402	1.70 (0.067)	0.60 (0.024)	0.50 (0.020)	0.60 (0.024)	0.50 (0.020)
0603	2.30 (0.091)	0.80 (0.031)	0.70 (0.028)	0.80 (0.031)	0.75 (0.030)
0805	3.00 (0.118)	1.00 (0.039)	1.00 (0.039)	1.00 (0.039)	1.25 (0.049)
1206	4.00 (0.157)	1.00 (0.039)	2.00 (0.079)	1.00 (0.039)	1.60 (0.063)
1210	4.00 (0.157)	1.00 (0.039)	2.00 (0.079)	1.00 (0.039)	2.50 (0.098)
1808	5.60 (0.220)	1.00 (0.039)	3.60 (0.142)	1.00 (0.039)	2.00 (0.079)
1812	5.60 (0.220)	1.00 (0.039)	3.60 (0.142)	1.00 (0.039)	3.00 (0.118)
1825	5.60 (0.220)	1.00 (0.039)	3.60 (0.142)	1.00 (0.039)	6.35 (0.250)
2220	6.60 (0.260)	1.00 (0.039)	4.60 (0.181)	1.00 (0.039)	5.00 (0.197)
2225	6.60 (0.260)	1.00 (0.039)	4.60 (0.181)	1.00 (0.039)	6.35 (0.250)

#### **C**omponent Pad Design

Component pads should be designed to achieve good solder filets and minimize component movement during reflow soldering. Pad designs are given below for the most common sizes of multilayer ceramic capacitors for both wave and reflow soldering. The basis of these designs is:

- Pad width equal to component width. It is permissible to decrease this to as low as 85% of component width but it is not advisable to go below this.
- Pad overlap 0.5mm beneath component.
- Pad extension 0.5mm beyond components for reflow and 1.0mm for wave soldering.

#### **WAVE SOLDERING**

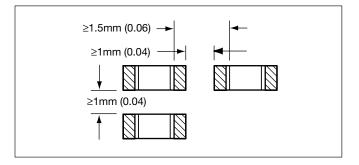


Case Size	D1	D2	D3	D4	D5
0603	3.10 (0.12)	1.20 (0.05)	0.70 (0.03)	1.20 (0.05)	0.75 (0.03)
0805	4.00 (0.15)	1.50 (0.06)	1.00 (0.04)	1.50 (0.06)	1.25 (0.05)
1206	5.00 (0.19)	1.50 (0.06)	2.00 (0.09)	1.50 (0.06)	1.60 (0.06)

Dimensions in millimeters (inches)

#### **Component Spacing**

For wave soldering components, must be spaced sufficiently far apart to avoid bridging or shadowing (inability of solder to penetrate properly into small spaces). This is less important for reflow soldering but sufficient space must be allowed to enable rework should it be required.



#### **Preheat & Soldering**

The rate of preheat should not exceed 4°C/second to prevent thermal shock. A better maximum figure is about 2°C/second.

For capacitors size 1206 and below, with a maximum thickness of 1.25mm, it is generally permissible to allow a temperature differential from preheat to soldering of 150°C. In all other cases this differential should not exceed 100°C.

For further specific application or process advice, please consult AVX.

#### Cleaning

Care should be taken to ensure that the capacitors are thoroughly cleaned of flux residues especially the space beneath the capacitor. Such residues may otherwise become conductive and effectively offer a low resistance bypass to the capacitor.

Ultrasonic cleaning is permissible, the recommended conditions being 8 Watts/litre at 20-45 kHz, with a process cycle of 2 minutes vapor rinse, 2 minutes immersion in the ultrasonic solvent bath and finally 2 minutes vapor rinse.

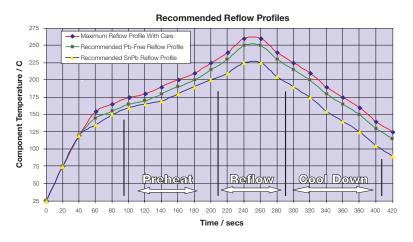


### **Recommended Soldering Profiles**



#### **REFLOW SOLDER PROFILES**

AVX RoHS compliant products utilize termination finishes (e.g.Sn or SnAg) that are compatible with all Pb-Free soldering systems and are fully reverse compatible with SnPb soldering systems. A recommended SnPb profile is shown for comparison; for Pb-Free soldering, IPC/JEDECJ-STD-020C may be referenced. The upper line in the chart shows the maximum envelope to which products are qualified (typically 3x reflow cycles at 260°C max). The center line gives the recommended profile for optimum wettability and soldering in Pb-Free Systems.



#### Preheat:

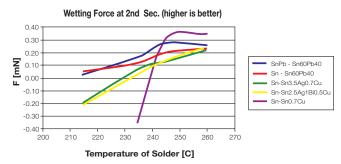
The pre-heat stabilizes the part and reduces the temperature differential prior to reflow. The initial ramp to 125°C may be rapid, but from that point (2-3)°C/sec is recommended to allow ceramic parts to heat uniformly and plastic encapsulated parts to stabilize through the glass transition temperature of the body (~ 180°C).

#### Reflow:

In the reflow phase, the maximum recommended time > 230°C is 40secs. Time at peak reflow is 10secs max.; optimum reflow is achieved at 250°C, (see wetting balance chart opposite) but products are qualified to 260°C max. Please reference individual product datasheets for maximum limits

#### **Cool Down:**

Cool down should not be forced and 6°C/sec is recommended. A slow cool down will result in a finer grain structure of the reflow solder in the solder fillet.



IMPORTANT NOTE: Typical Pb-Free reflow solders have a more dull and grainy appearance compared to traditional SnPb. Elevating the reflow temperature will not change this, but extending the cool down can help improve the visual appearance of the joint.

#### **WAVE SOLDER PROFILES**

For wave solder, there is no change in the recommended wave profile; all standard Pb-Free (SnCu/SnCuAg) systems operate at the same 260°C max recommended for SnPb systems.

#### **Preheat:**

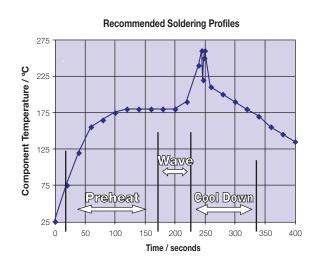
This is more important for wave solder; a higher temperature preheat will reduce the thermal shock to SMD parts that are immersed (please consult individual product data sheets for SMD parts that are suited to wave solder). SMD parts should ideally be heated from the bottom-Side prior to wave. PTH (Pin through hole) parts on the topside should not be separately heated.

#### Wave:

250°C - 260°C recommended for optimum solderability.

#### Cool Down:

As with reflow solder, cool down should not be forced and 6°C/sec is recommended. Any air knives at the end of the 2nd wave should be heated.





### **MLC Chip Capacitors**



#### **APPLICATION NOTES**

#### **Storage**

Good solderability is maintained for at least twelve months, provided the components are stored in their "as received" packaging at less than 40°C and 70% RH.

#### **Solderability**

Terminations to be well soldered after immersion in a 60/40 tin/lead solder bath at  $235 \pm 5$ °C for  $2 \pm 1$  seconds.

#### Leaching

Terminations will resist leaching for at least the immersion times and conditions shown below.

Termination Type	Solder	Solder	Immersion Time
	Tin/Lead/Silver	Temp. °C	Seconds
Nickel Barrier	60/40/0	$260 \pm 5$	30 ± 1

#### **Lead-Free Wave Soldering**

The recommended peak temperature for lead-free wave soldering is 250°C-260°C for 3-5 seconds. The other parameters of the profile remains the same as above.

The following should be noted by customers changing from lead based systems to the new lead free pastes.

- a) The visual standards used for evaluation of solder joints will need to be modified as lead free joints are not as bright as with tin-lead pastes and the fillet may not be as large.
- b) Lead-free solder pastes do not allow the same self alignment as lead containing systems. Standard mounting pads are acceptable, but machine set up may need to be modified.

#### General

Surface mounting chip multilayer ceramic capacitors are designed for soldering to printed circuit boards or other substrates. The construction of the components is such that they will withstand the time/temperature profiles used in both wave and reflow soldering methods.

#### Handling

Chip multilayer ceramic capacitors should be handled with care to avoid damage or contamination from perspiration and skin oils. The use of tweezers or vacuum pick ups is strongly recommended for individual components. Bulk handling should ensure that abrasion and mechanical shock

are minimized. Taped and reeled components provides the ideal medium for direct presentation to the placement machine. Any mechanical shock should be minimized during handling chip multilayer ceramic capacitors.

#### **Preheat**

It is important to avoid the possibility of thermal shock during soldering and carefully controlled preheat is therefore required. The rate of preheat should not exceed 4°C/second and a target figure 2°C/second is recommended. Although an 80°C to 120°C temperature differential is preferred, recent developments allow a temperature differential between the component surface and the soldering temperature of 150°C (Maximum) for capacitors of 1210 size and below with a maximum thickness of 1.25mm. The user is cautioned that the risk of thermal shock increases as chip size or temperature differential increases.

#### Soldering

Mildly activated rosin fluxes are preferred. The minimum amount of solder to give a good joint should be used. Excessive solder can lead to damage from the stresses caused by the difference in coefficients of expansion between solder, chip and substrate. AVX terminations are suitable for all wave and reflow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

#### Cooling

Natural cooling in air is preferred, as this minimizes stresses within the soldered joint. When forced air cooling is used, cooling rate should not exceed 4°C/second. Quenching is not recommended but if used, maximum temperature differentials should be observed according to the preheat conditions above.

#### Cleaning

Flux residues may be hygroscopic or acidic and must be removed. AVX MLC capacitors are acceptable for use with all of the solvents described in the specifications MIL-STD-202 and EIA-RS-198. Alcohol based solvents are acceptable and properly controlled water cleaning systems are also acceptable. Many other solvents have been proven successful, and most solvents that are acceptable to other components on circuit assemblies are equally acceptable for use with ceramic capacitors.



### **MLC Chip Capacitors**



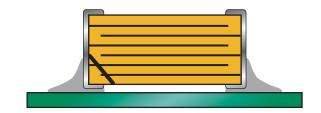
#### **POST SOLDER HANDLING**

Once SMP components are soldered to the board, any bending or flexure of the PCB applies stresses to the soldered joints of the components. For leaded devices, the stresses are absorbed by the compliancy of the metal leads and generally don't result in problems unless the stress is large enough to fracture the soldered connection.

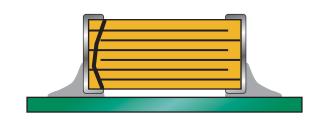
Ceramic capacitors are more susceptible to such stress because they don't have compliant leads and are brittle in nature. The most frequent failure mode is low DC resistance or short circuit. The second failure mode is significant loss of capacitance due to severing of contact between sets of the internal electrodes.

Cracks caused by mechanical flexure are very easily identified and generally take one of the following two general forms:

Mechanical cracks are often hidden underneath the termination and are difficult to see externally. However, if one end termination falls off during the removal process from PCB, this is one indication that the cause of failure was excessive mechanical stress due to board warping.



Type A: Angled crack between bottom of device to top of solder joint.



Type B: Fracture from top of device to bottom of device.

### **MLC Chip Capacitors**



# COMMON CAUSES OF MECHANICAL CRACKING

The most common source for mechanical stress is board depanelization equipment, such as manual breakapart, v-cutters and shear presses. Improperly aligned or dull cutters may cause torqueing of the PCB resulting in flex stresses being transmitted to components near the board edge. Another common source of flexural stress is contact during parametric testing when test points are probed. If the PCB is allowed to flex during the test cycle, nearby ceramic capacitors may be broken.

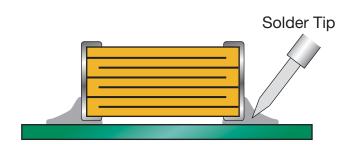
A third common source is board to board connections at vertical connectors where cables or other PCBs are connected to the PCB. If the board is not supported during the plug/unplug cycle, it may flex and cause damage to nearby components.

Special care should also be taken when handling large (>6" on a side) PCBs since they more easily flex or warp than smaller boards.

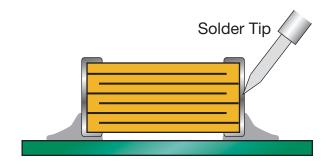
#### **REWORKING OF MLCs**

Thermal shock is common in MLCs that are manually attached or reworked with a soldering iron. AVX strongly recommends that any reworking of MLCs be done with hot air reflow rather than soldering irons. It is practically impossible to cause any thermal shock in ceramic capacitors when using hot air reflow.

However direct contact by the soldering iron tip often causes thermal cracks that may fail at a later date. If rework by soldering iron is absolutely necessary, it is recommended that the wattage of the iron be less than 30 watts and the tip temperature be <300°C. Rework should be performed by applying the solder iron tip to the pad and not directly contacting any part of the ceramic capacitor.



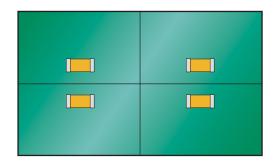
Preferred Method - No Direct Part Contact



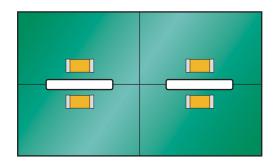
Poor Method - Direct Contact with Part

#### **PCB BOARD DESIGN**

To avoid many of the handling problems, AVX recommends that MLCs be located at least .2" away from nearest edge of board. However when this is not possible, AVX recommends that the panel be routed along the cut line, adjacent to where the MLC is located.



No Stress Relief for MLCs



Routed Cut Line Relieves Stress on MLC



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